

Device Package User Guide

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Revision History

The following table shows the revision history for this document.

Date	Version	Revision
01/31/04	1.0	Initial release
02/04/05	1.1	Added Pb-free packaging information.
05/31/06	2.0	Extensive updates and new material added.
05/18/07	3.0	<p>Updated “Material Data Declaration Sheet (MDDS)” in Chapter 1; revised link to “Xilinx Packaging Material Content Data for Standard and PB-Free Packages”.</p> <p>Revised “Part Marking” in Chapter 1; added “Ordering Information”, “Marking Template”, Table 1-1: “Example Part Numbers (FPGA, CPLD, and PROM)”, and Table 1-2: “Xilinx Device Marking Definition—Example”.</p> <p>Updated “Flip-Chip BGA Packages” in Chapter 1; added content to “Package Construction” to clarify Type I and Type II lid usage.</p> <p>Updated “Thermal Management & Thermal Characterization Methods & Conditions” in Chapter 3; removed “Junction-to-Board Measurement - ΨJB”, added link to new “Data Acquisition and Package Thermal Database”, added Figure 3-11, page 53, “Package Thermal Data Query for Device-Specific Data” (query tool replaces Table 3-1: “Summary of Thermal Resistance for Packages”, which was removed).</p> <p>Updated “Recommended PCB Design Rules for BGA, CSP, and CCGA Packages,” page 87; added missing (D) values for CP56 and CP132 packages and corrected SF363 package specification (D) value in Table 5-3, page 88. Added CS48 to Table 5-4, page 88.</p> <p>Updated Table 6-2, page 108 to include MSL ratings for Pb-free packages.</p> <p>Updated “Package Peak Reflow Temperature” in Chapter 7; correction to peak reflow temperature. Added post-wash bake details to “Post Reflow Washing” section.</p>
12/18/08	3.1	<p>Added link to Package Thermal Data Query Tool on xilinx.com. Updated remaining external links.</p> <p>Added Spartan®-3A DSP information to Table 1-1, page 13.</p> <p>Added these packages to Table 2-3, page 36: FG484 and FGG484.</p> <p>Added these packages to Table 5-3, page 88: SFG363, FF676, FGG484, FFG676, FT64 and FTG64.</p> <p>Removed these packages from Table 5-3, page 88: FF896, FFG896, FF1704, FFG1704, FF1696 and FFG1696.</p> <p>Added these packages to Table 5-4, page 88: CS484 and CSG484.</p>

Date	Version	Revision
03/17/09	3.2	<p>Revised “Small Form Factor Packages,” page 15 to include description of third template used for marking small form factor packages.</p> <p>Revised “Package Construction,” page 20 to describe flip-chip package vent hole locations.</p> <p>Added missing Pb-free packages to Table 1-3, page 27.</p> <p>Revised mass of FG676 and FGG676 packages in Table 1-3, page 27.</p> <p>Added CS484 and CSG484 information to Table 1-3, page 27 and Table 2-3, page 36.</p> <p>Added FF1136 and FFG1136 tray and box information to Table 2-3, page 36.</p> <p>Changed link from DS529 to UG331 in third paragraph of “Data Acquisition and Package Thermal Database,” page 52.</p> <p>Added CS484 electrical data to Table 4-1, page 75.</p> <p>Added note to Table 5-3, page 88, referring to UG195.</p> <p>Revised humidity value in third paragraph of “Dry Bake Recommendation and Dry Bag Policy,” page 107.</p> <p>Revised humidity value in first and fourth paragraph of “Expiration Date,” page 107.</p> <p>Updated links in Table A-1, page 121.</p>
04/23/09	3.3	<p>Added FG400, FGG400, FF323, FFG323, FF324, FFG324, FF665, FFG665, FF676, FFG676, FF1153, FFG1153, FF1156, FFG1156, FF1738, FFG1738, FF1760, and FFG1760 to Table 2-3, page 36.</p> <p>Revised the via land diameters for CF1140, CF1144, and CF1509 packages in Table 5-5, page 89.</p>
06/10/09	3.4	<p>Revised third paragraph of “Package Construction,” page 20 about EF flip-chip package epoxy protection.</p> <p>Revised second paragraph of “Post Reflow Washing,” page 117 excepting EF packages from cleaning solution/solvent recommendation.</p>
11/06/09	3.5	<p>Added link to MDDS documents under “Material Data Declaration Sheet (MDDS),” page 10. Added FF896, EF1152, EF1704, FF1704, EF668, and EF672 to Table 5-3, page 88. Added EF957 to Table 5-4, page 88.</p>
09/22/10	3.6	<p>Added CS225/CSG225 and CS324/CSG324 in Table 2-3, page 36. Added CF1752 to heading in CF1509 column, and changed “Solder (ball) land pitch” to “Solder (column) land pitch” in Table 5-5, page 89. Added VO48/VOG48 in Table 6-2, page 108.</p>
09/05/12	3.7	<p>Updated “Thermal Management,” page 39. Updated “Characterization Methods,” page 47 and added “Calibration of System Monitor,” page 47. Removed T_t and T_l from and added T_s to “Definition of Terms,” page 48. Updated “Junction-to-Case Measurement — qJC,” page 49, with JEDEC Standard JESD51-14. Updated document references in “Data Acquisition and Package Thermal Database,” page 52. Removed “Junction-to-Top Measurement — Ψ_{JT}” and “Support for Compact Thermal Models (CTM).” Updated note for T_A in “Thermal Data Usage Examples,” page 54. Updated “Additional Power Management Options,” page 57.</p>

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Package Information

Package Overview

Introduction to Xilinx Packaging

Electronic packages are interconnectable housings for semiconductor devices. The major functions of the electronic packages are to provide electrical interconnections between the IC and the board and to efficiently remove heat generated by the device.

Feature sizes are constantly shrinking, resulting in increased number of transistors being packed into the device. Today's submicron technology is also enabling large-scale functional integration and system-on-a-chip solutions. In order to keep pace with these new advancements in silicon technologies, semiconductor packages have also evolved to provide improved device functionality and performance.

Feature size at the device level is driving package feature sizes down to the design rules of the early transistors. To meet these demands, electronic packages must be flexible to address high pin counts, reduced pitch and form factor requirements. At the same time, packages must be reliable and cost effective.

Packaging Technology at Xilinx

Xilinx provides a wide range of leaded and array packaging solutions for our advanced silicon products. Xilinx® advanced packaging solutions include overmolded plastic ball grid arrays (PBGA), small form factor Chip Scale Packages, “Cavity-Down” BGAs, flip-chip BGAs, flip-chip ceramic column grid arrays (CCGA), as well as the newer lead frame packages such as Quad Flat No-Lead (QFN) packages to meet various pin counts and density requirements. Packages from Xilinx are designed, optimized, and characterized to support the long-term mechanical reliability requirements as well as to support the cutting-edge electrical and thermal performance requirements for our high-speed advanced FPGA products.

Pb-free Packaging Solutions from Xilinx

Xilinx also develops packaging solutions that are safer for the environment. Today, standard packages from Xilinx do not contain substances that are identified as harmful to the environment including cadmium, hexavalent chromium, mercury, PBB, and PBDE. Pb-free solutions take that one step further and also do not contain lead (Pb). This makes Pb-free solutions from Xilinx RoHS (Reduction of Hazardous Substances) compliant. Pb-free packages from Xilinx are also JEDEC J-STD-020 compliant, meaning that the packages are made to be more robust so they are capable of withstanding higher reflow temperatures. Xilinx is now ready to support the industry requirements for Pb-free packaging solutions.

Package Drawings

Package drawings are mechanical specifications that include exact dimensions for the placement of pins, height of the package, and related information.

Package drawings are available online at http://www.xilinx.com/support/documentation/package_specifications.htm.

Material Data Declaration Sheet (MDDS)

The MDDS template used by Xilinx is based on the Electronic Industries Alliance (EIA) September 19, Material Composition Declaration Guide dated September 19, 2003 for Level A and Level B materials of interest.

As per EIA, "Level A" List is composed of materials and substances subject to currently enacted legislation that:

- a. Prohibits their use and/or marketing
- b. Restricts their use and/or marketing
- c. Requires reporting or results in other regulatory effect.

As per EIA, "Level B" List is composed of materials and substances that the industry has determined relevant for disclosure because they meet one or more of the following criteria:

- a. Precious materials/substances that provide economic value for end-of-life management purposes
- b. Materials/substances that are of significant environmental, health, or safety interest
- c. Materials/substances that would trigger hazardous waste management requirements
- d. Materials/substances that could have a negative impact on end-of-life management.

See the EIA standard for more specific information.

MDDS documents are available online at http://www.xilinx.com/support/documentation/package_specifications.htm.

Information about Pb-Free and RoHS-compliant products is available at http://www.xilinx.com/system_resources/lead_free.

Package Samples

Xilinx offers two types of non-product-specific package samples that can help develop custom processes and perform board-level tests. These samples can be ordered with ordering codes as detailed below.

Mechanical Samples XCMECH-XXXXX (where XXXXX is the package code of interest)

This part type is used for mechanical evaluations, process setup, etc. Most packages are based on the JEDEC outline, and these parts are at times referred to as "dummy" parts since mechanical samples do not contain a die.

Example:

To order a FG676 package as a mechanical sample (without the die), the part number would be XCMECH-FG676.

Daisy Chain Samples XCDAISY-XXXXX (where XXXXX is the package code of interest)

Use this part type to perform board-based evaluations (such as vibrations and temperature cycles) to see how well the solder balls withstand these mechanical conditions. For Xilinx daisy chain parts (XCDAISY-XXXXX), a specific ball assignment chain is available. If you do not have a board already made, you can use our default chain. You can purchase these parts from Xilinx through standard sales outlets. Xilinx does not support unique chains because these parts do not have the volume to justify the development effort.

Example:

To order a FG676 package in a daisy-chained configuration, the part number would be XCDAISY-FG676.

Specifications and Definitions

Inches vs. Millimeters

The JEDEC standards for PLCC, CQFP, and PGA packages define package dimensions in inches. The lead spacing is specified as 25 mils, 50 mils, or 100 mils (0.025 in., 0.050 in. or 0.100 in.).

The JEDEC standards for PQFP, HQFP, TQFP, VQFP, CSP, and BGA packages define package dimensions in millimeters. The lead frame packages have lead spacings of 0.5 mm, 0.65 mm, or 0.8 mm. The CSP and BGA packages have ball pitches of 0.5 mm, 0.8 mm, 1.00 mm, or 1.27 mm.

Because of the potential for measurement discrepancies, this Data Book provides measurements in the controlling standard only, either inches or millimeters.

Pressure Handling Capacity

For mounted BGA packages, including flip chips, a direct compressive (non-varying) force applied normally to the lid or top of package with a tool head that coincides with the lid (or is slightly bigger) will not induce mechanical damage to the device including external balls, provided the force is not over 5.0 grams per external ball, and the device and board are supported to prevent any flexing or bowing.

These components are tested in sockets with loads in the 5 to 10 gm/ball range for short durations. Analysis using a 10g/ball (e.g., 10 kg for FF1148) showed little impact on short-term but some creep over time. 20 gm/ball and 45 gm/ball loads at 85°C over a six week period has shown the beginning of bridging of some outer balls; these were static load tests. The component can survive forces greater than the 5 gm limit while in short-term situations. However, sustained higher loads should be avoided (particularly if they are overlaid with thermal or power cycle loads). Within the recommended limits, circuit board needs to be properly supported to prevent any flexing resulting from force application. Any flexing or bowing resulting from such a force can likely damage the package-to-board connections. Besides the damage that can occur from bending, the only major concern is long-term creep and bulging of the solder balls in compression to cause bridging. For the life of a part, staying below the recommended limit will ensure against that remote possibility.

Clockwise or Counterclockwise

The orientation of the die in the package and the orientation of the package on the PC board affect the PC board layout. PLCC and PQFP packages specify pins in a counterclockwise direction, when viewed from the top of the package (the surface with the Xilinx logo). PLCCs have pin 1 in the center of the beveled edge while all other packages have pin 1 in one corner, with one exception: The 100-pin and 165-pin CQFPs (CB100 and CB164) for the XC3000 devices have pin 1 in the center of one edge.

CQFP packages specify pins in a clockwise direction, when viewed from the top of the package. The user can make the pins run counterclockwise by forming the leads such that the logo mounts against the PC board. However, heat flow to the surrounding air is impaired if the logo is mounted down.

Cavity-Up or Cavity-Down

Most Xilinx devices attach the die against the inside bottom of the package (the side that does not carry the Xilinx logo). Called “Cavity-Up,” this has been the standard IC assembly method for over 25 years. This method does not provide the best thermal characteristics. Pin Grid Arrays (greater than 130 pins), copper based BGA packages, and Ceramic Quad Flat Packs are assembled “Cavity-Down,” with the die attached to the inside top of the package, for optimal heat transfer to the ambient air. More information on “Cavity-Up” packages and “Cavity-Down” packages can be found in the [“Package Technology Descriptions”](#) section.

For most packages this information does not affect how the package is used because the user has no choice in how the package is mounted on a board. For Ceramic Quad Flat Pack (CQFP) packages however, the leads can be formed to either side. Therefore, for best heat transfer to the surrounding air, CQFP packages should be mounted with the logo up, facing away from the PC board.

Part Marking

Ordering Information

An example of an ordering code for a Xilinx FPGA is XC4VLX60-10FFG668CS2. The ordering code stands for:

XC4VLX – Family (Virtex®-4 LX)
60 – Number of system gates or logic cells (60,000 logic cells)
-10 – Speed grade (-10 speed)
FFG – Package type (Pb-free flip-chip BGA)
668 – number of pins (668 pins)
C – Temperature grade (Commercial)
S2 – Step 2

Other examples are shown in [Table 1-1](#).

Table 1-1: Example Part Numbers (FPGA, CPLD, and PROM)

Family	Part Number	Sample Ordering Code
Virtex-5 LX	XC5VLX##	XC5VLX110 -1 FFG676C
Virtex-5 LXT	XC5VLX##T	XC5VLX330T-1FF1738I
Virtex-5 SXT	XC5VSX##T	XC5VSX35T-2FF665C
Virtex-4 LX	XC4VLX##	XC4VLX25 -10 FF668C
Virtex-4 SX	XC4VSX##	XC4VSX55 -11 FF1148C
Virtex-II Pro	XC2VP##	XC2VP7 -7 FG456C
Virtex-II	XC2V##	XC2V1000 -5 FG456C
Virtex-E	XCV##E	XCV300E -6 PQ240C
Virtex	XCV##	XCV300 -6 PQ240C
Spartan®-3	XC3S##	XC3S1000 -4 FG676C
Spartan-3A	XC3S##A	XC3S50A -4 FTG256C
Spartan-3E	XC3S##E	XC3S250E -4 FT256C
Spartan-II	XC2S##	XC2S50 -6 PQ208C
Spartan-IIE	XC2S##E	XC2S50E -6 PQ208C
Spartan-3AN	XC3Sx###AN	XC3S400AN-4FG400I
Spartan-3A DSP	XC3SD#####A	XC3SD1800A-4CS484LI
Spartan	XCS##	XCS20 -4 PQ208C
Spartan-XL	XCS##XL	XCS20XL -4 PQ208C
4000E	XC4##E	XC4013E -3 HQ240C
4000XL	XC4##XL	XC4013XL -3 PQ208C
CoolRunner™-II	XC2C##	XC2C256 -7 PQ208C
CoolRunner (XPLA3)	XCR##XL	XCR3512XL -7 PQ208C
9500XV	XC95##XV	XC9536XV -7 VQ44I
9500XL	XC95##XL	XC9572XL -7 TQ100C
9500	XC95##	XC95216 -10 HQ208C

Notes:

1. Automotive parts use "XA" instead of "XC".
2. QML-certified parts use "XQ" instead of "XC".
3. Aerospace parts have an "R" after "XQ" instead of "XC".

Examples

CPLD Ordering Information

An example of an ordering number for a Xilinx CPLD is XC2C256-7PQ108I, and is defined as follows:

- XC2C – Family (CoolRunner-II)
- 256 – Number of macrocells (256 macrocells)
- 7 – Speed grade (-7 speed)
- PQ – Package type (Plastic Quad Flat Pack)
- 208 – Number of pins (208 pins)
- I – Temperature grade (Industrial)

PROM Ordering Information

An example of an ordering number for a Xilinx PROM is XC18V04VQ44C, and is defined as follows:

- XC18V – Family - 1800 (ISP) PROM
- 04 – PROM size (18V00, 17V00, 1700E/L) or equivalent Spartan-II or Spartan-IIE device (17S00A/XL/L), 4 Mb of storage capacity
- VQ – Package type (Plastic Quad Flat Pack)
- 44 – Number of pins (44 pins)
- C – Temperature grade (commercial)

To determine the valid ordering combinations for a given device, consult the device data sheet. Data sheets are available at

<http://www.xilinx.com/support/documentation/index.htm>

Marking Template

Large Form Factor Packages

On December 26, 1995, Product Change Notice (PCN) 95013 was issued to acknowledge a change to the Xilinx standard for package marking. You can view this notice at

http://www.xilinx.com/support/documentation/customer_notices/pcn95013.pdf

Xilinx part marking follows generalized marking templates that are different for small and large packages. Within each group, some minor variations exist due to device family branding.

The large package template (Figure 1-1) consists of the Xilinx Logo, the family brand logo, and 4 lines of information.

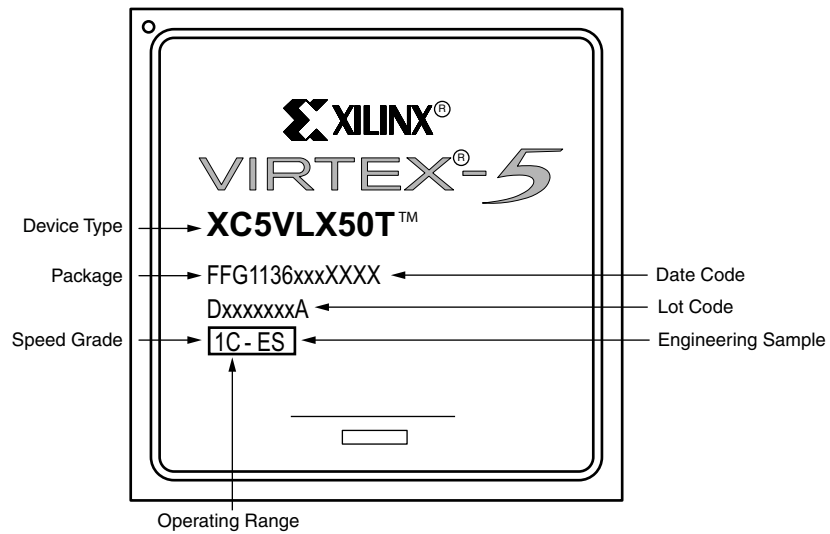


Figure 1-1: Top Marking (for Large Device Packages)

Table 1-2: Xilinx Device Marking Definition—Example

Item	Description
Corporate Logo	Xilinx logo, Xilinx name with trademark, and trademark-registered status.
Family Brand Logo	Product family name with trademark and trademark-registered status. This line is optional and could appear blank.
1st Line	Device type.
2nd Line	Package type and pin count, circuit design revision, the location code for the wafer fab, the geometry code, and date code. A G in the third letter of a package type indicates a Pb-free RoHS compliant package. For more details on Xilinx Pb-Free and RoHS Compliant Products, see: http://www.xilinx.com/system_resources/lead_free/index.htm .
3rd Line	Ten alphanumeric characters for assembly, lot, and step information. The last digit is usually an A or an M if a stepping version does not exist.
4th Line	Device speed grade and temperature range. If a grade is not marked on the package, the product is considered commercial grade. Other variations for the 4th line:
	1C-xxxx The xxxx indicates the SCD for the device. An SCD is a special ordering code that is not always marked in the device top mark.
	1C-ES The ES indicates an Engineering Sample.

Small Form Factor Packages

A second template is used on smaller packages that do not have enough room for six lines of marking. This marking is used mainly for PROMs, and can be found on some medium-size packages as well.

Line 1

Product name code, eight characters. Five or six characters (for example, 1765D) designate the product name representation (usually the name without the “XC”). The name is followed by the PROM package designator (usually a single character). The last letter represents the temperature range (for example, M, I, C).

Line 2

Six numeric characters preceded by the “X” of the Xilinx logo. The first numeric character after the “X” designates the last digit of the year in which the product was assembled. This digit will be the same every 10 years. The next two numeric characters identify the assembly work week. The last three characters are the final three digits of the Assembly number for the lot.

Line 3

This line is usually left blank for customer PROM designator marking.

A third template is used for CPLD and Spartan FPGA small form factor packages. Information is provided on four lines.

Line 1

Product name code (without XC). For example, 9536XL or 3S250E preceded by the “X” of the Xilinx logo.

Line 2

Consists of 11 alphanumeric characters. The first character is a letter that represents the manufacturing location. The next five numeric characters are the lot number. The last four numeric characters are the four digit date code in YYWW format.

Line 3

Indicates the country of origin.

Line 4

Consists of about seven alphanumeric characters. The first two characters are the CPLD or Spartan FPGA package designator and are followed by a three letter mask code. The last two characters are the speed and temperature range.

Package Technology Descriptions

Pb-Free Packaging

Recent legislative directives and corporate driven initiatives around the world have called for the elimination of Pb and other hazardous substances in electronics used in many sectors of the electronics industry. The Pb-free program at Xilinx was established in 1999 as a proactive effort to develop and qualify suitable material sets and processes for Pb-free applications. Xilinx has taken the leadership position by quickly forming partnerships with our customers, suppliers, and participating in industry consortiums to provide technical solutions that are aligned with industry requirements.

Pb-free Material Set

Xilinx has researched alternatives for Pb compounds and has selected matte Sn lead finish for lead-frame packages and SnAgCu solder balls for BGA packages. In addition, suitable material sets are chosen and qualified for higher reflow temperatures (245°C – 260°C) that are required by Pb-free soldering processes. Pb-free products from Xilinx are designated

with an additional “G” in the package designator portion of the part number. For example, FGG1152 is the Pb-free version of FG1152.

Features

- RoHS compliant
- Compliant to JEDEC-J-STD-020 standard for peak reflow temperature (245°C – 260°C)
- Packages marked with Pb-free identifier

Backward Compatibility

Backward compatibility, as described in this chapter, refers only to the soldering process. Pb-free devices from Xilinx have the same form, fit and function as standard Pb-based products. No changes are required for board design when using Pb-free products from Xilinx. However, finish materials for boards might need to be adjusted.

Lead frame packages (PQG, TQG, VQG, PCG, QFG, etc.) from Xilinx are backward compatible, meaning that the component can be soldered with Sn/Pb solder using Sn/Pb soldering process. Lead-frame packages from Xilinx use a matte Sn plating on the leads which is compatible with both Pb-free soldering alloys and Sn/Pb soldering alloy.

BGA packages (CPG, FTG, FGG, BGG, etc.), however, are not recommended to be soldered with SnPb solder using a Sn/Pb soldering process. The traditional Sn/Pb soldering process usually has a peak reflow temperature of 205°C - 220°C. At this temperature range, the SnAgCu BGA solder balls do not properly melt and wet to the soldering surfaces. As a result, reliability and assembly yields might be compromised.

For more information on Xilinx Pb-free solutions, refer to http://www.xilinx.com/system_resources/lead_free/index.htm, and for more information on the Pb-free reflow process, refer to [XAPP427](#).

Tin Whisker Mitigation

Following are some of the efforts Xilinx is making to mitigate tin whiskering in Pb-free lead-frame packages (non-BGA):

- a. Tin whisker growth mitigation practices are:
 - Annealing matte tin for 1 hour @ 150°C within 8 hours after tin plating
 - Minimum thicker plating thickness 400 micro inches (10 micro meter)
- b. Xilinx assembly subcontractors comply with JEDEC standards for tin whisker test conditions outlined by:
 - JESD22A121.01 (May 2005)
 - JESD201 (March 2006)
- c. The lead finish method for Xilinx Pb-Free lead-frame product is:
 - 100% matte tin plating over a bare Cu lead frame

Cavity-Up Plastic BGA Packages

BGA is a plastic package technology that utilizes area array solder balls at the bottom of the package to make electrical contact with the system circuit board. The area array format of solder balls reduces package size considerably when compared to leaded products. It also results in improved electrical performance as well as having higher manufacturing yields.

The substrate is made of a multilayer BT (bismaleimide triazene) epoxy-based material. Power and ground pins are grouped together and the signal pins are assigned in the perimeter format for ease of routing on to the board. The package is offered in a die up format and contains a wirebonded device that is covered with a mold compound.

Package Construction

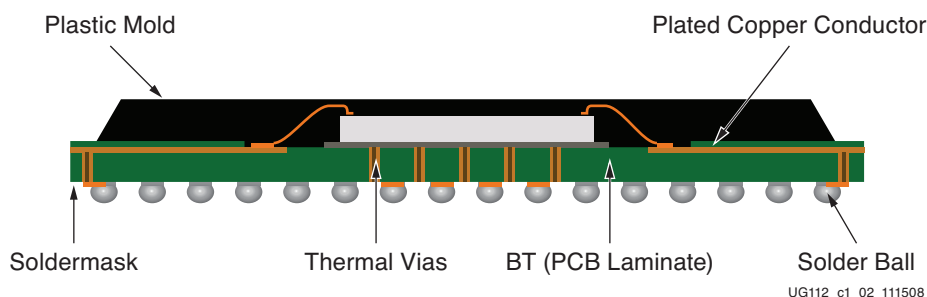


Figure 1-2: Cavity-Up Ball Grid Array Package

As shown in the cross section of [Figure 1-2](#), the BGA package contains a wire bonded die on a single-core printed circuit board with an overmold. Beneath the die are the thermal vias which can dissipate the heat through a portion of the solder ball array and ultimately into the power and ground planes of the system circuit board. This thermal management technique provides better thermal dissipation than a standard PQFP package. Metal planes also distribute the heat across the entire package, enabling a 15–20% decrease in thermal resistance to the case.

Key Features/Advantages of Xilinx Cavity-Up BGA Packages

- High board assembly yield since board attachment process is self-centering
- SMT compatible, resulting in minimum capital investment
- Extendable to multichip modules
- Low profile and small footprint
- Improved electrical performance (short wire length)
- Enhanced thermal performance
- Excellent board level reliability

Cavity-Down Thermally Enhanced BGA Packages

Copper-based cavity-down BGAs are high-performance, low-profile packages that offer superior electrical and thermal characteristics. This technology is especially applicable for high-speed, high-power semiconductors such as the Virtex device family.

Package Construction

[Figure 1-3](#) depicts the cross-section of the cavity-down BGA package. It should be noted that this is a solid construction without any internal cavity. The backside die is attached directly to the copper heat spreader and conducts heat out of the package through an epoxy die attach adhesive. The larger the die size and the package body size, the better the thermal performance. The incorporation of the copper heat spreader also results in thermal resistance values that are lowest among the packages offered by Xilinx.

Attached to the heatsreader is a copper stiffener with cavity out to accommodate the die. Along with the heatsreader, this stiffener provides the mechanical flexural strength and warpage control for the package. On the exposed surface of the stiffener is a laminate or build-up structure that contains the circuit traces, the power and ground planes if any, and the sites for the connecting solder balls. The laminate is made of either a glass-reinforced high-glass transition temperature (T_g) bismaleimide triazine (BT) or build-up structure. Xilinx uses laminate with up to four layers, including PWR and GND planes.

Key Features/Advantages of Xilinx Cavity-Down BGAs

- Lowest thermal resistance ($\theta_{JA} < 13^{\circ}\text{C}/\text{W}$)
- Superior electrical performance
- Low profile and light weight construction
- Excellent board-level reliability

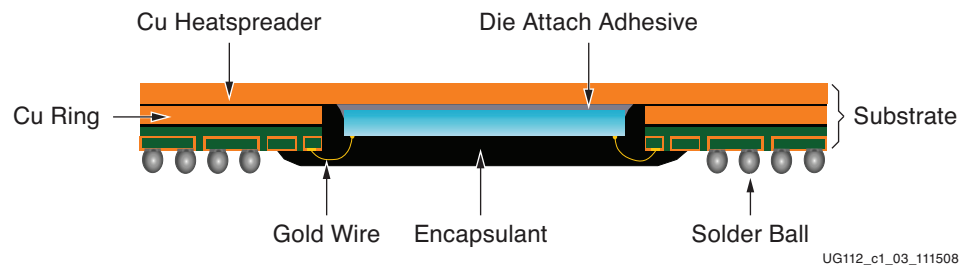


Figure 1-3: Cavity-Down BGA Package

Flip-Chip BGA Packages

Flip chip is a packaging interconnect technology that replaces peripheral bond pads of traditional wirebond interconnect technology with area array interconnect technology at the die/substrate interface. The bond pads are either redistributed on the surface of the die or in some very limited cases, they are directly dropped from the core of the die to the surface. Because of this inherent distribution of bond pads on the surface of the device, more bond pads and I/Os can be packed into the device.

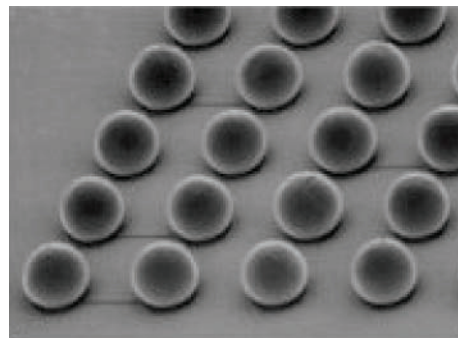


Figure 1-4: Eutectic Bumps

The Xilinx flip-chip BGA package is offered for Xilinx high-performance FPGA products. Unlike traditional packaging in which the die is attached to the substrate face up and the connection is made by using wire, the solder bumped die in flip-chip BGA is flipped over and placed face down, with the conductive bumps connecting directly to the matching metal pads on the laminate substrate.

Unlike traditional packaging technology in which the interconnection between the die and the substrate is made possible using wire, flip chip utilizes conductive bumps that are placed directly on the area array pads of the die surface. The area array pads contain wettable metallization for solders (either eutectic or high lead) where a controlled amount of solder is deposited either by plating or screen-printing. These parts are then reflowed to yield bumped dies with relatively uniform solder bumps over the surface of the device. The device is then flipped over and reflowed on a ceramic or organic laminate substrate. The solder material at molten stage is self-aligning and produces good joints even if the chips are placed offset to the substrates. After the die is soldered to the substrate, the gap (standoff) formed between the chip and the substrate is filled with an organic compound called underfill. The underfill is a type of epoxy that helps distribute stresses from these solder joints to the surface of the whole die and hence improve the reliability and fatigue performance of these solder joints.

This interconnect technology has emerged in applications related to high performance communications, networking and computer applications as well as in consumer applications where miniaturization, high I/O count, and good thermal performance are key attributes.

Package Construction

Flip-chip BGA packages for high-performance applications are built on high-density multi-layer organic laminate substrates. Because the flip-chip bump pads are in area array configuration, it requires very fine lines and geometry on the substrates to be able to successfully route the signals from the die to the periphery of the substrates. Multilayer build-up structures offer this layout flexibility on flip-chip packages.

Figure 1-5 and Figure 1-6 show cross-section views of the package constructions. Note that two types of lids are used to assemble flip-chip BGA packages; type I lids (as shown in with flat top) and type II lids (as shown in Figure 1-6 with hat-type top), depending on the package type. Use the package drawing specification (to determine the lid type used on the specific packages, see http://www.xilinx.com/support/documentation/package_specifications.htm).

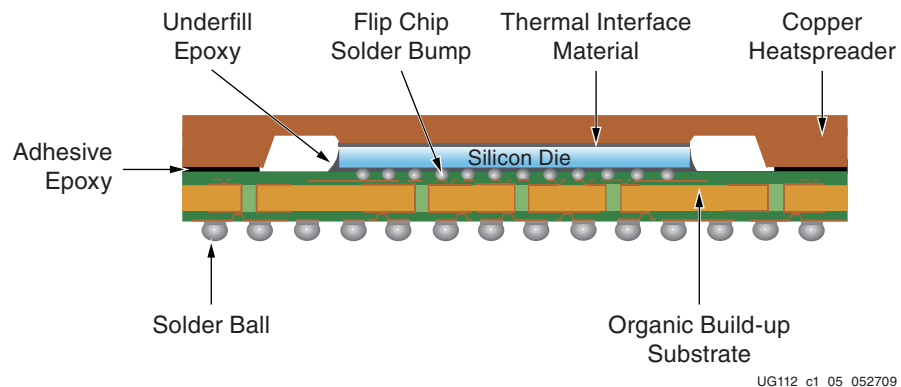


Figure 1-5: Flip-Chip BGA Package with Type I Lid

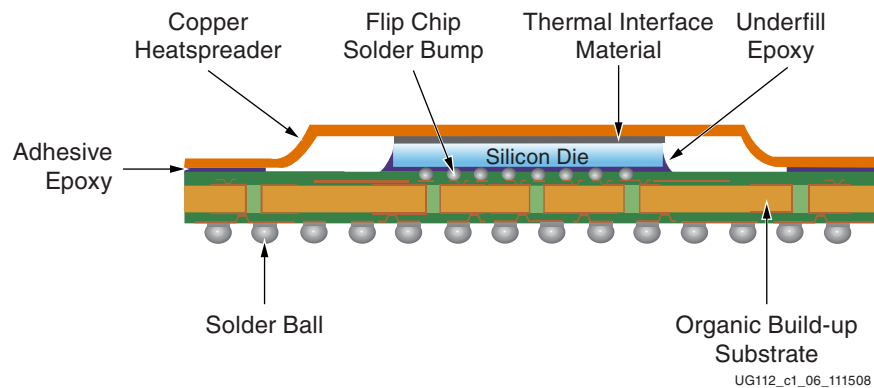


Figure 1-6: Flip-Chip BGA Package with Type II Lid

Xilinx flip-chip packages are not hermetically sealed, and exposure to cleaning solvents or excessive moisture during board assembly can pose serious package reliability concerns. Small vents are placed by design between the heatspreader (lid) and the organic substrate to allow for outgassing and moisture evaporation. These vent holes are located in the middle of all four sides of FF flip-chip packages. Solvents or other corrosive chemicals can seep through these vents and attack the organic materials and components inside the package and are strongly discouraged during board assembly of Xilinx flip-chip BGA packages. The only exception would be for EF flip-chip packages in which special epoxy protection is applied to protect against solvents.

Key Features/Advantages of Flip-Chip BGA Packages

- Easy access to core power/ground, resulting in better electrical performance
- Excellent thermal performance (direct heatsinking to backside of the die)
- Higher I/O density since bond pads are in area array format
- Higher frequency switching with better noise control

Assembling Flip-Chip BGAs

The Xilinx flip-chip BGAs conform to JEDEC body sizes and footprint standards. These packages follow the EIA moisture level classification for plastic surface mount components (PSMC). Standard surface mount assembly process should be used with consideration for the slightly higher thermal mass for these packages.

Like other SMT components, flip-chip BGA assembly involves the following process: screen printing, solder reflow, post reflow washing. The following will serve as a guideline on how to assemble flip-chip BGAs onto PCBs.

Screen Printing Machine Parameters

Below is an example of the parameters that were used for the screen printing process. Note that these might not be optimized parameters. Optimized parameters will depend on user's applications and setup.

- Equipment: MPM Ultraprint 2000
- Squeegee Type: Metal
- Squeegee Angle: 45°

- Squeegee Pressure: 24 lbs/sq. in.
- Squeegee Speed: 0.7 in/second
- Print Cycle: One pass
- Stencil Snap Off: 0.10 inches
- Stencil Lift Off Speed: Slow

Screen Printing Process Parameters

- Solder paste: Alpha Metals WS609 (water soluble)
- Stencil aperture: 0.0177 inches diameter
- Stencil thickness: 0.006 inches
- Aperture creation: Laser cut

It is highly recommended to use either a no-clean solder paste or a water soluble solder paste. If cleaning is required, then a water soluble solder paste should be used.

Chip Scale Packages

Chip Scale Packages have emerged as a dominant packaging option for meeting the demands of miniaturization while offering improved performance. Applications for Chip Scale Packages are targeted to portable and consumer products where real estate is of utmost importance, miniaturization is key, and power consumption/dissipation must be low. A Chip Scale Package is defined as a package that fits the definition of being between 1 to 1.2 times the area of the die that the package contains while having a pitch of less than 1 mm.

By employing CSP packages, system designers can dramatically reduce board real estate and increase the I/O counts.

Package Construction

Although there are currently more than 50 different types of CSPs available in the market, Xilinx CSP packages fall into two categories, as shown in [Figure 1-7](#): flex-based substrates and rigid BT-based substrates. Although, both types meet the reliability requirement at the component and board level, BT-based substrate was chosen for the newer devices because of the large vendor base producing/supporting the BT-based substrates.

Key Features/Advantages of CSP Packages

- An extremely small form factor which significantly reduces board real estate for such applications as PCMCIA cards, portable and wireless designs, and PC add-in cards
- Lower inductance and lower capacitance
- The absence of thin, fragile leads found on other packages
- A very thin, light-weight package

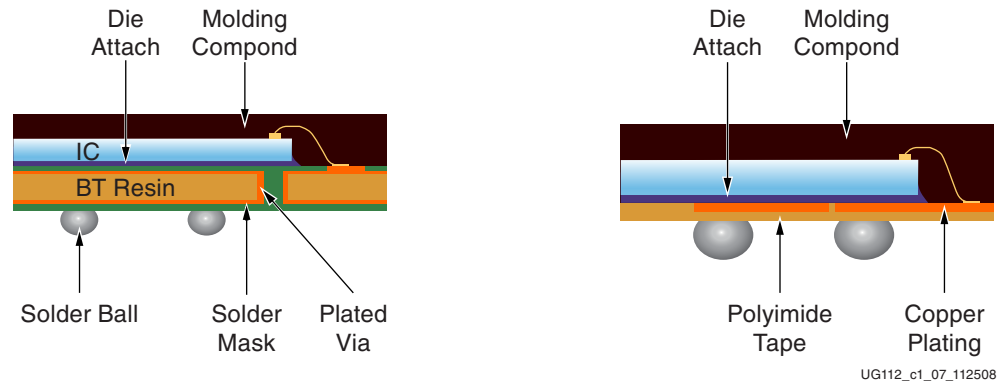


Figure 1-7: Rigid BT-Based Substrate Chip Scale Packages, Left; Flex-Based Tape Substrate, Right

Quad Flat No-Lead (QFN) Packages

Quad Flat No-Lead (QFN) or MLF package is a robust and low-profile lead frame-based plastic package that has several advantages over traditional lead frame packages. The exposed die-attach paddle enables efficient thermal dissipation when directly soldered to the PCB. Additionally, this near chip scale package offers improved electrical performance, smaller package size, and an absence of external leads. Since the package has no external leads, coplanarity and bent leads are no longer a concern.

Xilinx Quad Flat No-Lead packages are ideal for portable applications where size, weight, and performance matter.

Package Construction

The QFN is a molded leadless package with land pads on the bottom of the package. Electrical contact to the PCB is made by soldering the land pads to the PCB. The backside of the die is attached to the exposed paddle through the die attach material which is electrically conductive. The exposed pad therefore represents a weak ground and should be left floating or connected to a ground net.

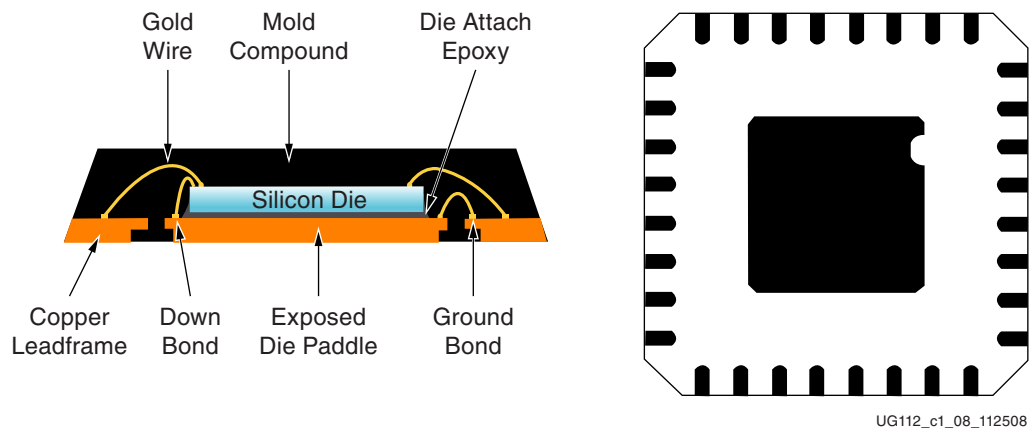


Figure 1-8: QFN Cross Section (Left) and Bottom View (Right)

Key Features/Advantages of QFN Packages

- Small size and light weight
- Excellent thermal and electrical performance
- Compatible with conventional SMT processes

Ceramic Column Grid Array (CCGA) Packages

Ceramic Column Grid Array (CCGA) packages are surface-mount-compatible packages that use high-temperature solder columns as interconnections to the board. Compared to the solder spheres, the columns have lower stiffness and provide a higher stand-off. These features significantly increase the reliability of the solder joints. When combined with a high-density, multilayer ceramic substrate, this packaging technology offers a high density, reliable packaging solution. Ceramic offers the following benefits:

Key Features/Advantages of CCGA Packages

- High planarity and excellent thermal stability at high temperature
- CTE matches well with the silicon die
- Low moisture absorption

Xilinx offers 3 different formats of CCGA: “Cavity-Down” wire-bonded CCGA, “Cavity-Up” wire-bonded CCGA, and flip-chip CCGA.

Cavity-Down Wire-Bonded CCGA – CG560 Package Construction

CG560 is offered with the Xilinx XQV1000 and XQVR1000 devices. It is pin-compatible with the plastic BG560 package. Below are additional attributes of CG560.

- Interconnect: 90Pb/10Sn hard solder column interposer, attached with 63Sn/37Pb soft solder.
- Hermetically sealed with eutectic Sn/Au

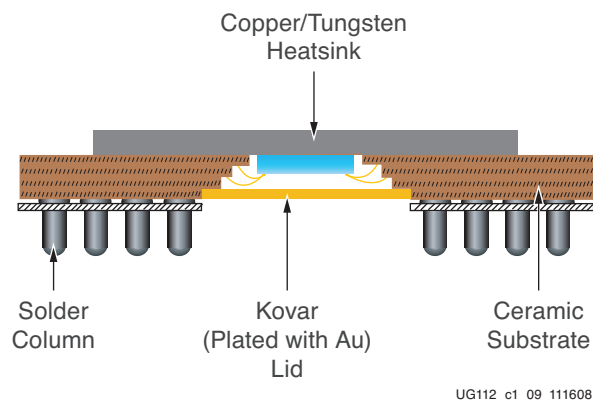


Figure 1-9: **CG560 Package**

Cavity-Up Wire-Bonded BGA – CG717 Package Construction

CG717 is offered with the Xilinx XQ2V3000 and XQR2V3000 devices. It is pin-compatible with the plastic BG728 package. Below are additional attributes of CG717.

- Interconnect: 80Pb/20Sn hard solder column, attached with 63Sn/37Pb soft solder.

- Hermetically sealed with eutectic Sn/ Au

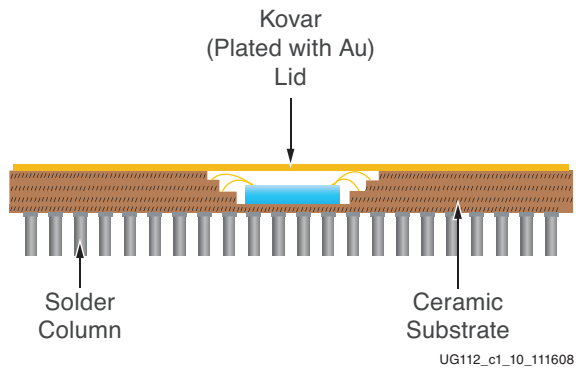


Figure 1-10: **CG717 Package**

Flip-Chip CCGA – CF1144 Package Construction

Flip-Chip CCGA is targeted for applications that require high performance, density, and high reliability. CF1144 is offered with the Xilinx XQ2V6000 and XQR2V6000 devices. The CF1144 package is pin-compatible with the plastic flip-chip FF1152 package. Below are additional attributes of CF1144:

- 95Pb/5Sn flip-chip solder bumps
- 90Pb/10Sn hard solder column

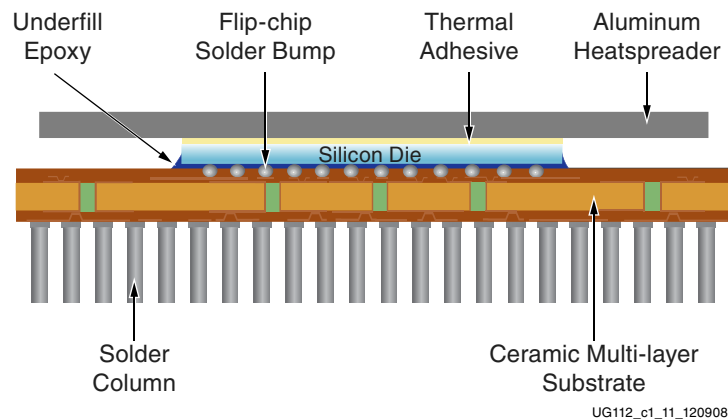


Figure 1-11: **CF1144 Package**

Thermally Enhanced Lead Frame Packaging

Xilinx offers thermally enhanced quad flat pack packages on XC4000 Series devices and some earlier Virtex devices. This section discusses the performance and usage of these packages (designated HQ).

Key Features/Advantages of Thermally Enhanced Lead Frame Packages

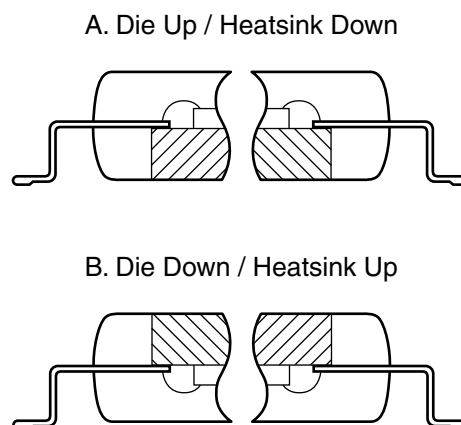
- The HQ-series and the regular PQ packages conform to the same JEDEC drawings.
- The HQ and PQ packages use the same PCB land patterns.

- The HQ packages have more mass
- Thermal performance is better for the HQ packages

Applications of HQ Packages

- HQ packages are offered as the thermally enhanced equivalents of PQ packages. They are used for high gate count or high I/O count devices in packages, where heat dissipation without the enhancement might be a handicap for device performance. Such devices include XC4013E, XC4020E, XC4025E, and XC5215.
- The HQ series at the 240-pin count level or below are offered with the heatsink at the bottom of the package. This was done to ensure pin to pin compatibility with the existing PQ packages.

At the 304-pin count level, the HQ is offered with the heatsink up. This arrangement offers a better potential for further thermal enhancement by the designer.



A. Heatsink Down Orientation B. Heatsink Up Orientation

UG112_c1_12_040709

Figure 1-12: Heatsink Orientation

- In the die-up/heatsink-down configuration, the heatsink surface is insulated.

Package Mass Table

The numbers provided in [Table 1-3](#) represent average values for typical devices used in the package. Die size variation from device to device, slight changes in moisture content, number of specific layers used in the specific substrate etc., will provide some variation. In some cases the data accuracy can be up to $\pm 10\%$. More precise numbers for specific devices in a lot can be obtained from in situ weighing. If this is critical, specific lot information can be requested.

Table 1-3: Package Mass (Weight) by Package Type

Package	Description	Mass (g)
BF957, BFG957	957 ball flip-chip BGA 40 x 40 body (1.27 mm pitch)	18.5
BG225, BGG225	Molded BGA 27 mm Full Matrix	2.2
BG256, BGG256	Molded BGA 27 mm Peripheral	2.2
BG352, BGG352	SuperBGA 35 x 35 mm Peripheral	7.1
BG388	MPM BGA 35 x 35 mm (1.27 mm pitch)	4.6
BG432, BGG432	SuperBGA 40 x 40 mm Peripheral	9.1
BG492, BGG492	Molded BGA 35 mm (1.27 mm pitch)	4.6
BG560, BGG560	SuperBGA 42.5 x 42.5 mm SQ	12.3
BG575, BGG575	575 BGA 31 x 31 mm body (1.27 mm pitch)	4.4
BG728, BGG728	728 BGA 35 x 35 mm body (1.27 mm pitch)	6.2
CB100	NCTB Top Brazed XC3000/XC4000 VER	10.8
CB164	NCTB Top Brazed XC3000/XC4000 VER	11.5
CB196	NCTB Top Brazed XC4000 VER	15.3
CB228	NCTB Top Brazed XC4000 VER	17.6
CC20	Ceramic Leaded Chip Carrier	8.4
CC44	Ceramic Leaded Chip Carrier	2.9
CD48	Ceramic Side Brazed DIP	8.0
CD8	Ceramic Side Brazed DIP	0.9
CF1144	Ceramic Column flip chip, 35 x 35 mm, 1.0 mm pitch	44.0
CG560	Ceramic SPGA 42.5 x 42.5	44.0
CG717	Ceramic Column Grid Array, 35 x 35 mm, 1.27 mm pitch	13.3
CP56, CPG56	CSP 56 BGA 6 mm (0.5 mm pitch)	0.1
CP132, CPG132	CSP 132 BGA 8 x 8 mm, 0.5 mm ball pitch	0.1
CS48, CSG48	CSP 48 BGA 7 mm (0.8 pitch)	0.2
CS144, CSG144	CSP 144 BGA 12 mm (0.8 pitch)	0.3
CS280, CSG280	CSP 280 BGA 16 mm (0.8 pitch)	0.5
CS484, CSG484	CSP 484 BGA 19 mm (0.8 pitch)	1.4
DD8	Cerdip Package (.300" Row Spacing)	1.1
FF665, FFG665	Flip-chip BGA 27 x 27 mm 1.0 mm pitch	4.4
FF668, FFG668	668 ball Ceramic Column flip-chip BGA, 27 x 27 mm, 1.0 mm ball pitch	4.4

Table 1-3: Package Mass (Weight) by Package Type (Cont'd)

Package	Description	Mass (g)
FF672, FFG672	672 ball flip-chip BGA, 27 x 27 mm, 1.0 mm ball pitch	4.4
FF676, FFG676	676 ball flip-chip BGA, 27 x 27 mm, 1.0 mm pitch Full	4.4
FF896, FFG896	896 ball flip-chip BGA 31 x 31 mm body (1.0 mm pitch)	11.2
FF1136, FFG1136	Flip-chip BGA, 35 x 35 mm, 1.0 mm	14.0
FF1148, FFG1148	1148 ball flip-chip BGA 35 x 35 mm body (1.0 mm pitch)	14.0
FF1152, FFG1152	1152 ball flip-chip BGA 35 x 35 mm body (1.0 mm pitch)	14.0
FF1153, FFG1153	Flip-chip BGA 35 mm x 35 mm 1.0 mm	14.0
FF1513, FFG1513	1513 ball flip-chip BGA 40 x 40 mm body (1.0 mm pitch)	17.0
FF1517, FFG1517	1517 ball flip-chip BGA 40 x 40 mm body (1.0 mm pitch)	17.2
FF1696, FFG1696	1696 ball flip-chip BGA 42.5 x 42.5 mm body (1.0 mm pitch)	20.5
FF1704, FFG1704	1704 ball flip-chip BGA 42.5 x 42.5 mm body (1.0 mm pitch)	21.1
FF1738, FFG1738	Flip-chip BGA 42.5 x 42.5 mm 1.0 mm pitch	22.0
FF1760, FFG1760	Flip-chip BGA 42.5 x 42.5 mm 1.0 mm pitch	22.0
FG256, FGG256	Fine pitch BGA 17 x 17 mm, 1.0 mm ball pitch	0.8
FG320, FGG320	Fine pitch BGA 19 x 19 mm, 1.0 mm ball pitch	1.4
FG324, FGG324	Molded BGA 23 mm 1.0 mm pitch	2.2
FG456, FGG456	Fine pitch BGA 23 x 23 mm, 1.0 mm ball pitch	2.2
FG400, FGG400	Fine pitch BGA 21 x 21 mm, 1.0 mm ball pitch	2.2
FG484, FGG484	Molded BGA 23 mm 1.0 mm pitch	2.2
FG556, FGG556	Fine pitch BGA 31 x 31 mm, 1.0 mm ball pitch	3.9
FG580	SuperBGA 35 x 35 mm, 1.0 mm pitch	7.1
FG676, FGG676	Fine pitch BGA 27 x 27 mm, 1.0 mm ball pitch	3.06
FG680, FGG680	Fine pitch BGA 40 x 70 mm, 1.0 mm ball pitch	10.6
FG860, FGG860	Fine pitch BGA 42.5 x 42.57 mm, 1.0 mm ball pitch	13.8
FG900, FGG900	Fine pitch BGA 31 x 31 mm, 1.0 mm ball pitch	4.2
FG1156, FGG1156	Fine pitch BGA 35 x 35 mm, 1.0 mm ball pitch	6.2
FS48, FSG48	CSP 48BGA, 6 x 8 mm, 0.8 mm ball pitch	0.1

Table 1-3: Package Mass (Weight) by Package Type (Cont'd)

Package	Description	Mass (g)
FT256, FTG256	256 Thin PBGA 17 x 17 mm body (1.0 mm pitch)	0.9
HQ160, HQG160	Metric 28 x 28 0.65 mm 1.6H/S Die Up	10.8
HQ208, HQG208	Metric 28 x 28 H/S Die Up	10.8
HQ240, HQG240	Metric QFP 32 x 32 H/S Die Up	15.0
HQ304, HQG304	Metric QFP 40 x 40 H/S Die Down	26.2
HT144	Thin QFP 1.4 H/S (HQ) Die Up	2.6
HT176	Thin QFP 1.4 H/S (HQ) Die Up	3.5
PC20, PCG20	PLCC JEDEC MO-047	0.8
PC28, PCG28	PLCC JEDEC MO-047	1.1
PC44, PCG44	PLCC JEDEC MO-047	1.2
PC68, PCG68	PLCC JEDEC MO-047	4.8
PC84, PCG84	PLCC JEDEC MO-047	6.8
PD8, PDG8	DIP .300 Standard	0.5
PD48	DIP .600 Standard	7.9
PG68	Ceramic PGA "Cavity Up" 11 x 11	7.0
PG84	Ceramic PGA "Cavity Up" 11 x 11	7.2
PG84	Windowed CPGA "Cavity Up" 11 x 11	7.5
PG120	Ceramic PGA 13 x 13 Matrix	11.5
PG132	Ceramic PGA 14 x 14 Matrix	11.8
PG144	Ceramic PGA 15 X15 Cavity Up	16.9
PG156	Ceramic PGA 16 x 16 Matrix	17.1
PG175	Ceramic PGA 16 x 16 Standard Version	17.7
PG191	Ceramic PGA 18 x 18 Standard (All)	21.8
PG223	Ceramic PGA 18 x 18 Type	26.0
PG299	Ceramic PGA 20 x 20 Heatsink	37.5
PG299	Ceramic PGA 20 x 20 Matrix	29.8
PG411	Ceramic PGA 39 x 39 Stagger	36.7
PG475	Ceramic PGA 41 x 41 Stagger	39.5
PG559	Ceramic PGA 43 x 43	44.5
PQ44, PQG44	EIAJ 10 x 10 x 2.0 QFP	0.5
PQ100, PQG100	EIAJ 14 x 20 QFP - 1.60 (default)	1.6
PQ100, PQG100	EIAJ 14 x 20 QFP - 1.80 (not used)	1.6

Table 1-3: Package Mass (Weight) by Package Type (Cont'd)

Package	Description	Mass (g)
PQ100, PQG100	EIAJ 14 x 20 QFP - 1.95 (old version)	1.6
PQ160, PQG160	EIAJ 28 x 28 0.65 mm 1.60	5.8
PQ208, PQG208	EIAJ 28 x 28 0.5 mm 1.30	5.3
PQ240, PQG240	EIAJ 32 x 32 0.5 mm	7.1
SF363, SFG363	Flip-chip BGA 17 x 17, 0.8 mm pitch	1.6
SO8, SOG8	Version 1 0.150/50 mil	0.1
SO20, SOG20	300 mil SOIC	0.5
SO24	300 mil SOIC	0.6
TQ100, TQG100	Thin QFP 1.4 mm thick	0.7
TQ128, TQG128	Thin QFP 1.4 mm thick RECT	0.8
TQ144, TQG144	Thin QFP 1.4 mm thick	1.4
TQ176, TQG176	Thin QFP 1.4 mm thick	1.9
VO8, VOG8	Thin SOIC - II	0.1
VO20, VOG20	Thin SSOP, 4.4 mm	0.1
VO48, VOG48	Thin SOP	0.5
VQ44, VQG44	Thin QFP 1.0 thick	0.4
VQ64, VQG64	THIN QFP 1.0 thick	0.5
VQ100, VQG100	Thin QFP 1.0 thick	0.6

Pack and Ship

Introduction

Xilinx offers several packing options for our through-hole and surface-mount products. The devices are packed in either tubes, trays, or tape and reel.

Tape and Reel

Xilinx offers a tape and reel packing for PLCC, BGA, QFP, and SO packages. The packing material is made of black conductive polystyrene and protects the packages from mechanical and electrical damage. The reel material provides a suitable medium for pick and place equipment.

The tape and reel packaging consists of a pocketed carrier tape, sealed with a protective cover. The device sits on pedestals (for PLCC, QFP packages) to protect the leads from mechanical damage. All devices loaded into the tape carriers are baked, lead scanned before the cover tape is attached and sealed to the carrier. In-line mark inspection for mark quality and package orientation is used to ensure shipping quality.

Benefits

- Increased quantity of devices per reel versus tubes improves cycle time and reduces the amount of time to index spent tubes.
- Tape and reel packaging enables automated pick and place board assembly.
- Reels are uniform in size enabling equipment flexibility.
- Transparent cover tape allows device verification and orientation.
- Antistatic reel materials provides ESD protection.
- Carrier design include a pedestal to protect package leads during shipment.
- Bar code labels on each reel facilitate automated inventory control and component traceability.
- All tape and reel shipments include desiccant pouches and humidity indicators to ensure products are safe from moisture.
- Compliant to Electronic Industries Association (EIA) 481. Material and Construction Carrier Tape.
- The pocketed carrier tape is made of conductive polystyrene material, or equivalent, with a surface resistivity level of less than 106 ohms per square inch.
- Devices are loaded “live bug” or leads down, into a device pocket.
- Each carrier pocket has a hole in the center for automated sensing of whether a unit is in the pocket or not.

- Sprocket holes along the edge of the carrier tape enable direct feeding into automated board assembly equipment.

Cover Tape

An anti-static, transparent, polyester cover tape, with heat activated adhesive coating, sealed to the carrier edges to hold the devices in the carrier pockets.

Surface resistivity on both sides is less than 1011 ohms per square inch.

Reel

The reel is made of anti-static polystyrene material. The loaded carrier tape is wound onto this conductive plastic reel.

A protective strip made of conductive polystyrene material is placed on the outer part of the reel to protect the devices from external pressure in shipment.

Surface resistivity is less than 1011 ohms per square inch.

Device loading orientation is in compliance with EIA Standard 481.

Bar Code Label

The bar code label on each reel provides customer identification, device part number, date code of the product and quantity in the reel.

Print quality are in accordance with ANSI X3.182-1990 Bar Code Print Quality Guidelines. Presentation of Data on labels are EIA-556-A compliant.

The label is an alphanumeric, medium density Code 39 labels.

This machine-readable label enhances inventory management and data input accuracy.

Shipping Box

The shipping container for the reels are in a 13 in. x 13 in. x 3 in. C-flute, corrugated, #3 white "pizza box," rated to 200 lb. test.

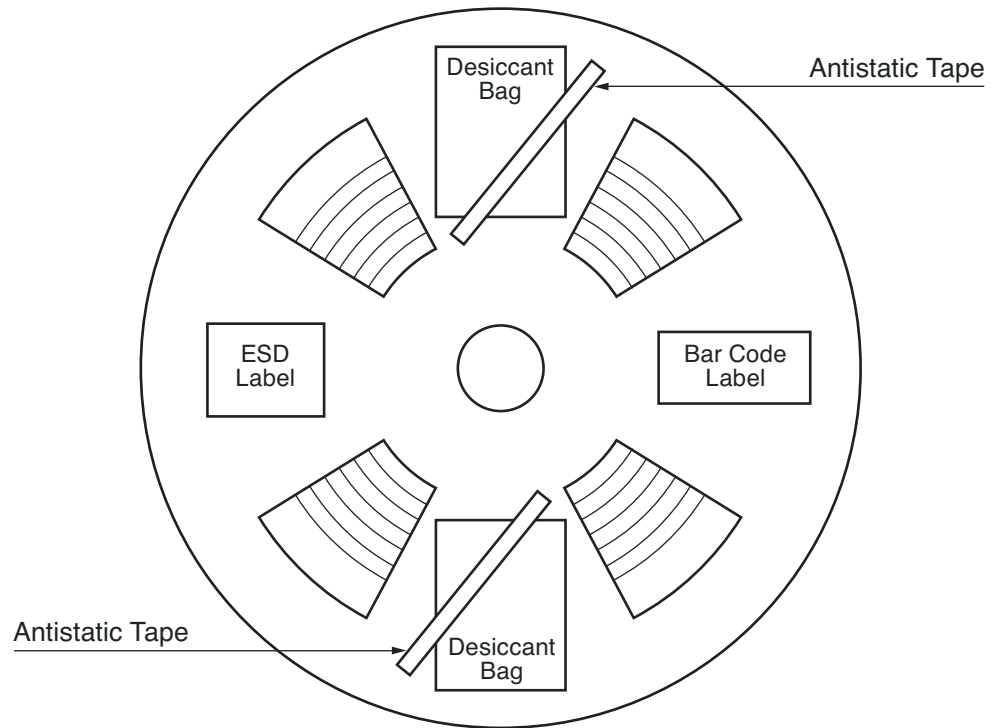
Table 2-1: Tape and Reel Packaging

Package Code	Qty. Per Reel	Reel Size (inches)	Carrier Width (mm)	Cover Width (mm)	Pitch (mm)
BG225 ⁽¹⁾ , BGG225 ⁽¹⁾	500	13	44	37.5	32
BG256 ⁽¹⁾ , BGG256 ⁽¹⁾	500	13	44	37.5	32
BG272 ⁽¹⁾ , BGG272 ⁽¹⁾	500	13	44	37.5	32
CP56 ⁽¹⁾ , CPG56 ⁽¹⁾	4000	13	12	9.2	8
CS48 ⁽¹⁾ , CSG48 ⁽¹⁾	1500	13	16	13.3	12
CS144 ⁽¹⁾ , CSG144 ⁽¹⁾	2000	13	24	21.0	16
FG256 ⁽¹⁾ , FGG256 ⁽¹⁾	1000	13	24	21.0	20
FG456 ⁽¹⁾ , FGG456 ⁽¹⁾	500	13	44	37.5	32
FG676 ⁽¹⁾ , FGG676 ⁽¹⁾	500	13	44	37.5	32
FT256, FTG256	1000	13	24	21	20.0
PC20 ⁽¹⁾ , PCG20 ⁽¹⁾	750	13	16	13.3	12
PC44 ⁽¹⁾ , PCG44 ⁽¹⁾	500	12	32	25.5	14
PC68 ⁽¹⁾ , PCG68 ⁽¹⁾	250	13	44	37.5	32
PC84 ⁽¹⁾ , PCG84 ⁽¹⁾	250	13	44	37.5	36
PQ100, PQG100	250	13	44	37.5	32
PQ160, PQG160	200	13	44	37.5	40
BG352 ⁽¹⁾ , BGG352 ⁽¹⁾	200	13	56	49.5	40
BG432 ⁽¹⁾ , BGG432 ⁽¹⁾	200	13	56	49.5	48
BG560 ⁽¹⁾ , BGG560 ⁽¹⁾	200	13	56	49.5	48
SO8	750	7	12	9.2	8
SO20	1000	13	24	21.0	12
TQ100, TQG100	1000	13	24	21.0	32
TQ144, TQG144	750	13	44	37.5	24
VO8, VOG8	750	7	12	9.2	8
VO20, VOG20	2500	13	16	13.3	12.0
VQ44, VQG44	2000	13	24	21.0	16
VQ64, VQG64	2000	13	24	21.0	16
VQ100, VQG100	1000	13	24	21.0	32

Note:

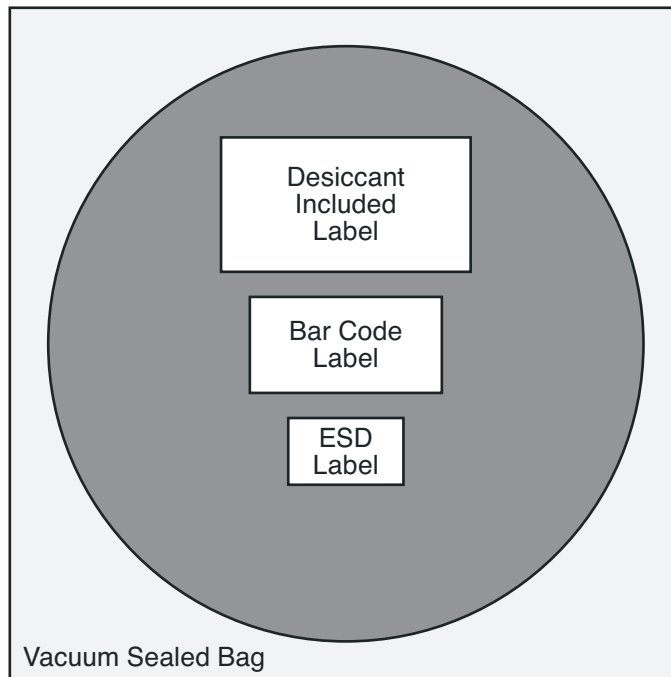
1. In-house capability.

Standard Bar Code Label Locations



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Figure 2-1: Standard Bar Code Label Locations



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Figure 2-2: Standard Bar Code Label Locations

Tubes

Tubes are used as unit carriers for most of Xilinx smaller packages. All of our tubes are coated with an antistatic material to protect the product from ESD damage.

Table 2-2: Standard Device Quantities per Tube

Package	Full Tube Quantity	Max. Tube Qty. per ESD Bag (8.5" x 27")	Max. Tube Qty. per ESD Bag (12" x 27")
PC84, PCG84, WC84	15	24	40
PC68, PCG68, WC68	18	36	50
PC44, PCG44, CC44, WC44	26	40	50
PC28, PCG28	37	40	50
PC20, PCG20, CC20	46	50	60
CD48	7	24	30
PD48	7	24	30
CD8	37	10	15
PD8	50	50	60
DD8	50	50	60
SO24	31	40	50

Table 2-2: Standard Device Quantities per Tube

SO20	37	60	100
SO8	98	240	350
VO20, VOG20	74	240	350
VO24	62	240	350
VO8, VOG8	98	240	350

Trays

Trays are used to pack most of Xilinx surface-mount devices since they provide excellent protection from mechanical damage. In addition, they are coated with antistatic material to provide protection against ESD damage and can withstand operation temperature of up to 150° C.

Table 2-3: Standard Device Counts per Tray and Box

Package	Max Number of Devices Per Tray	Max Number of Units In One Internal Box
BF957/BFG957	21	105
BG225/BGG225 BG256/BGG256	40	200
BG352/BGG352 BG492/BGG492 BG728/BGG728	24	120
BG432/BGG432	21	105
BG560/BGG560	12	60
BG575/BGG575	27	135
CB100, CB164, CB196, CB228	4	20
CP56/CPG56	360	1800
CP132/CPG132	360	1800
CS48/CSG48	416	2080
CS144/CSG144	198	990
CS225/CSG225	160	800
CS280/CSG280	119	595
CS324/CSG324	126	630
CS484, CSG484	84	420
FG256/FGG256	90	450
FG320/FGG320	84	420
FG324/FGG324	60	300

Table 2-3: Standard Device Counts per Tray and Box (Cont'd)

Package	Max Number of Devices Per Tray	Max Number of Units In One Internal Box
FG400/FGG400 FG456/FGG456, FG484/FGG484	60	300
FG676/FGG676	40	200
FG860	12	60
FG900/FGG900	27	135
FG680/FGG680	21	105
FF323/FFG323 FF324/FFG324	84	420
FG1156/FGG1156	24	120
FF665/FFG665 FF668 / FFG668	40	200
FF672/FFG672 FF676/FFG676	40	200
FF896/FFG896	27	135
FF1136/FFG1136 FF1148/FFG1148 FF1152/FFG1152 FF1153/FFG1153 FF1156/FFG1156	24	120
FF1513/FFG1513 FF1517/FFG1517	21	105
FF1696/FFG1696 FF1704/FFG1704 FF1738/FFG1738 FF1760/FFG1760	12	60
FS48/FSG48	108	525
FT256/FTG256	90	450
HQ160/HQG160 HQ208/HQG208	24	120
HQ240/HQG240	24	120
HQ304	12	60
HT144	60	300
HT176	40	200
PG68, PG84	40	200
PG120	24	120
PG132/PP132	21	105
PG144	18	90

Table 2-3: Standard Device Counts per Tray and Box (Cont'd)

Package	Max Number of Devices Per Tray	Max Number of Units In One Internal Box
PG156/PP156 PG175/PP175	14	70
PG191, PG223	12	60
PG299	10	50
PG411, PG475, PG559	10	50
PQ44/PQG44	96	480
PQ100/PQG100	66	330
PQ160/PQG160 PQ208/PQG208	24	120
PQ240/PQG240	24	120
QFG32	490	2450
QFG48	260	1300
SF363/SFG363	90	450
TQ144, TQG144	60	300
TQ160, TQ176	40	200
TQ100/TQG100	90	450
TQ128	72	360
VO48/VOG48	96	480
VQ44/VQG44 VQ64/VQG64	160	800
VQ100/VQG100	90	450

Thermal Management & Thermal Characterization Methods & Conditions

Introduction

This chapter addresses the need to manage the heat generated in CMOS logic devices, an industry wide pursuit, and describes the measures Xilinx uses and recommends to its customers to quantify and manage potential thermal problems in FPGAs.

Thermal Management

Modern high-speed logic devices consume an appreciable amount of electrical energy. This energy invariably turns into heat. Higher device integration drives technologies to produce smaller device geometry and interconnections. With chip sizes getting smaller and circuit densities at their highest levels, the amount of heat generated on these fast-switching CMOS circuits can be very significant. As an example, Xilinx 7 series FPGAs incorporate multiple processors, multiple-gigabit transceivers, digital-controlled impedance I/Os, and I/Os capable of supporting various high current standards. Special attention must be paid to addressing the heat removal needs for these devices.

The need to manage the heat generated in a modern CMOS logic device is not unique to Xilinx. This is a general industry pursuit. However, unlike the power needs of a typical industry application-specific integrated circuit (ASIC) gate array, the field-programmable device's power requirement is not determined in the factory. Customers' designs can vary in power as well as physical needs. This is the challenge in predicting FPGA thermal management needs.

Xilinx Packages

In assigning packages to devices, efforts have been made to tailor the packages to the power needs of typical users. For each device, suitable packages are chosen to handle typical designs and gate utilization for the device. Sometimes, the choice of a package as the primary or internal heat removal casing works well without any external heat management. Increasingly, with highly integrated devices, the need arises for customers to utilize an FPGA device beyond typical design parameters. For these situations, the use of the primary package without external enhancement might not be adequate to address the heat removal needs of the device. In that case it becomes essential to manage the heat removal through external means. Heat has to be removed from a device to ensure that the device is maintained within its functional and maximum design temperature limits. If heat buildup becomes excessive, the device temperature might exceed its limits. Consequently, the device might fail to meet the speed-file performance specifications. In addition to performance considerations, there is also the need to satisfy system reliability objectives by

operating at a lower temperature. Failure mechanisms and the failure rate of devices have an exponential dependence on the device's operating temperatures. Thus, the control of the package, and by extension device temperature, is essential to ensure product reliability.

Heatsinks, Heatsink Interface Materials, and Heatsink Attachments

The primary purpose of a heatsink is to help remove heat from a device more efficiently than just the device's package alone. Heatsinks accomplish this by decreasing the overall thermal resistance between the case of a device and the surrounding air. They effectively increase the surface area over which heat can be dissipated. Three factors should be considered for a given heatsink design: the heatsink itself, the heatsink interface material, and the attachment mechanism. With a heatsink attached to an integrated circuit (IC), heat from the device flows from the junction of the device to the case, from the case to the interface material, from the interface material to the heatsink, and finally from the heatsink to ambient air. In situations where a heatsink is used with a heatsink compound, the thermal resistance of the heatsink is referenced as θ_{SA} (sink-to-ambient) and that of the attached material as θ_{CS} (case-to-heatsink). These thermal resistances can be added. For example, $\theta_{JAtop} = \theta_{JCTop} + \theta_{CS} + \theta_{SA}$ is an expression used in heatsink situations with interface material resistance θ_{CS} .

Heatsinks come in a variety of materials, shapes, and sizes, but share the common goal of maximizing the heat dissipation between the device that they attach to and the surrounding air, which might be still air or air flowing via a forced convection system (typically fans). The improved heat dissipation of a heatsink is accomplished by maximizing surface area through the use of fins of varying dimensions and spacings, and might also include components such as copper heat spreaders that can help distribute the heat from smaller ICs more evenly over the surface area of the heatsink.

Heatsink interface materials, which are used between the heatsink and the device, can be of many kinds, including greases, gels, adhesives, tapes, silicon rubber materials, and special thermoplastic adhesives known as phase change materials. Each of these has unique benefits and drawbacks that need to be considered for their ability to meet the requirements and priorities of the particular design. When choosing a heatsink, the manufacturer should provide recommendations for possible interface materials.

Heatsink attachments attach the heatsink either directly to the device package, or to the PCB around the device. Possible heatsink attachments include thermal epoxies and tapes, mechanical attachments such as clips that attach directly to the package, or pins and screws that attach to the PCB. Each of these attachments has unique benefits and drawbacks that need to be considered for their ability to meet the needs of the particular design. When choosing a heatsink from a manufacturer, the attachment mechanism can be part of the heatsink, or they might be options recommended by the manufacturer. For additional information about heatsinks and other thermal management solutions, refer to [“Additional Power Management Options,” page 57](#).

Power Estimation Tools

Xilinx offers two software-based power-estimator tools to help the user predict power consumption: XPower Estimator (XPE) and XPower Analyzer (XPA). These tools provide the capability of performing detailed power estimation and analysis for designs running in Xilinx FPGAs. With these tools, it is possible to perform “what if” scenarios to analyze the power consumption of variations to a given design. θ_{JA} for still or forced air flow, θ_{JB} , and even θ_{SA} for heatsinks are all provided as estimates within the XPE tool. These can also be overridden if the values are extracted from higher accuracy simulations or methods. A key output of these tools is the device junction temperature (T_J) based on the power estimates.

Like most tools, however, the predicted output depends on the work put into the predicting effort. For more information on power estimation and optimization in the Xilinx design tools, see:

- [UG786](#), *Power Methodology Guide*
- [UG440](#), *XPower Estimator User Guide*
- [UG907](#), *Vivado Design Suite User Guide: Power Analysis and Optimization*
- XPower Analyzer details
www.xilinx.com/products/design_tools/logic_design/verification/xpower_an.htm
- [UG733](#), *Xilinx Power Tools Tutorial*

Compact Thermal Models

While the XPE and XPA power-estimator tools can provide the traditional thermal resistance data for all Xilinx packages in addition to the estimated power consumption of a design, this resistance data is measured using a prescribed JEDEC standard that might not necessarily reflect the actual user environment. The quoted θ_{JA} and θ_{JC} numbers are environmentally dependent, and JEDEC has traditionally recommended that these be used with that awareness. For more accurate junction temperature prediction, these might not be enough, and a system-level thermal simulation might be required. To aid in this, Delphi boundary condition independent compact thermal models (BCI-CTM) are available for most Xilinx device/packages at the Xilinx support download center:

<http://www.xilinx.com/support/download/index.htm>.

These models are available to use with computational fluid dynamic (CFD) software to do detailed thermal simulation and analysis of entire boards and systems, including the printed circuit board design, other devices, heatsinks, enclosures, and airflows. Xilinx provides these models in both the Mentor FloTHERM and ANSYS Icepack formats.

[Figure 3-1](#) shows two forms of compact thermal model topologies, the DELPHI BCI-CTM, and the two-resistor model. Xilinx provides models in the DELPHI BCI-CTM format.

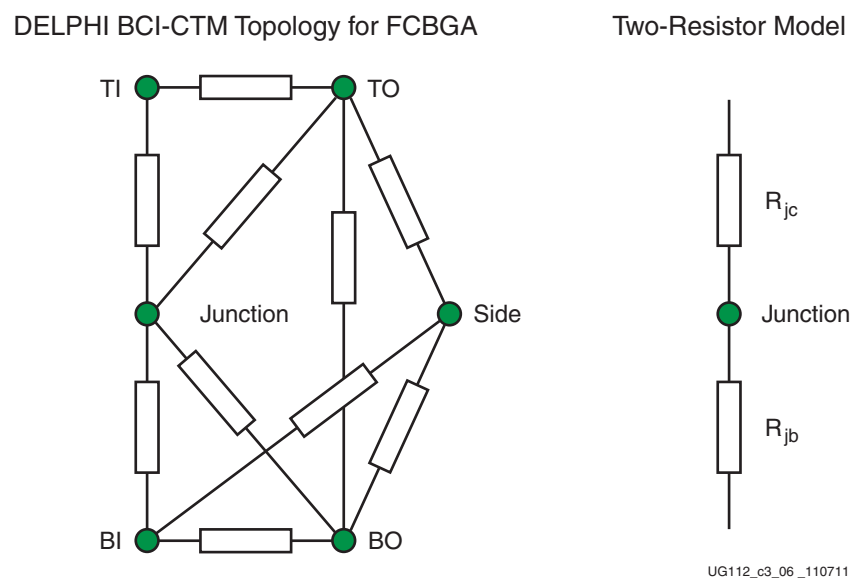


Figure 3-1: Compact Thermal Model Topologies

PCB Design: Layer, Board, and Layout Considerations

The majority of heat flow from an IC generally follows two paths:

- Through the top of the case to the surrounding air (optionally through a heatsink)
- Through the soldered interface to the PCB, and from the PCB to the surrounding air

Thus, a two-resistor compact model is commonly used to model the thermal behavior of a package. The two-resistor compact model for a package consists of $\theta_{JA\text{top}}$ in parallel with $\theta_{JA\text{board}}$. A graphical representation of this can be found in the JEDEC standard JESD51-12, as shown in [Figure 3-2](#).

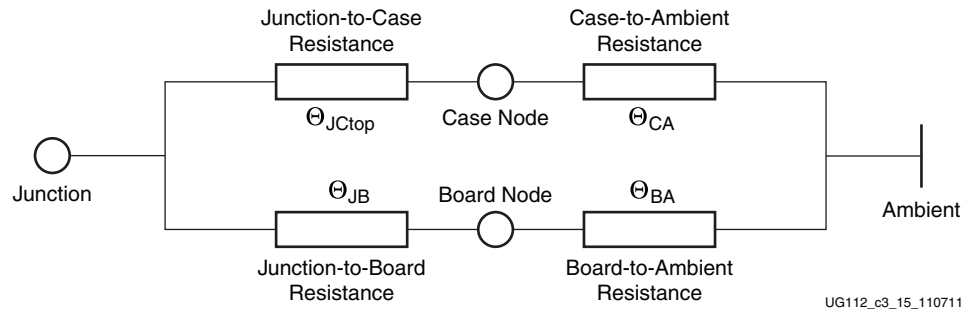


Figure 3-2: Equivalent Thermal Resistance Diagram of the Two-Resistor Model on a PCB

While this is known as a two-resistor model, it is really more of a four-resistor model, with $\theta_{JA\text{top}}$ being the sum of $\theta_{JC\text{top}} + \theta_{CA}$, and $\theta_{JA\text{board}}$ being the sum of $\theta_{JB} + \theta_{BA}$. The overall θ_{JA} value can be estimated by calculating the parallel thermal resistance of $\theta_{JA\text{top}}$ in parallel with $\theta_{JA\text{board}}$.

The θ_{JB} and θ_{BA} thermal resistances can vary significantly depending on the PCB design, in particular due to the size of the board and the number and thickness of the copper layers. The more the copper material and surface area, the better the heat dissipation and the lesser the thermal resistance between the devices and the board (θ_{JB}), as well as between the board and the surrounding air (θ_{JA}). Larger boards provide larger surface area and usually provide more copper material. As layer counts and copper thickness increase, θ_{JB} and θ_{JA} tend to decrease—in particular for power or ground plane layers, as those tend to be solid copper layers. [Table 3-2, page 45](#) illustrates the effect of both board size and layer count on the overall θ_{JA} .

Other layout considerations that can affect θ_{JB} and θ_{BA} include the types of power and ground plane layers that are used (hatching vs. solid), and the use of thermal reliefs, particularly at the board vias that connect the device being analyzed to the ground and V_{CC} planes. Historically, hatched plane layers provided a number of benefits including aiding in the manufacturing process and providing flexibility to meet transmission line impedance goals. However, they had the drawback of not having a solid plane of copper to aid with thermal heat dissipation. There are better alternatives to cross-hatching planes for modern board design and fabrication, and consequently, this technique is seldom used today. Because of the reduction in the thermal heat dissipation, it is strongly recommended to completely avoid the use of hatched planes. Thermal reliefs at the through-hole pads and vias serve the purpose of actually increasing the thermal impedance between the board landing pads for a component and the copper planes and traces that it connects to. This is used to improve the solderability of devices, particularly for devices with through-hole packages that require wave solder or similar assembly techniques (vs. solder oven installation). However, thermal reliefs work in direct conflict to the goal of improving

the overall thermal heat dissipation for when the board is operating—the thermal reliefs effectively increase θ_{JB} . Most Xilinx device packages are not of the through-hole type and are primarily offered in QFP and BGA packages. For these package types, it is not necessary to use thermal reliefs on the pad vias for assembly purposes, and it is advised to avoid doing so to minimize θ_{JB} .

Ambient temperature, Enclosures, and Airflow

One of the most critical variables required to analyze the thermal management of ICs on a PCB is the device's junction temperature (T_J). All ICs have requirements or specifications for minimum and maximum T_J for the device and can include absolute maximum ratings, as well as recommended operating condition ratings (Xilinx devices have both). T_J is a direct function of the power dissipated in the device, the thermal conductivity of the device's package, and the PCB it is mounted on, the ambient temperature (T_A) inside the enclosure the board is contained within, and the cooling systems that might include natural airflow, forced airflow, heatsinks, or even more complex systems.

When designing boards and the enclosures that they are housed in, it is possible to select the device placement to create air paths and take advantage of natural convection cooling, and also to optimize the physical locations so that heat sensitive devices are not next to heat generating devices. However, it is important to also consider challenges presented by the specific manufacturing or application environment. For example, when dealing with dirty industrial environments, the objective is to find a thermal management solution that includes protection against dust, dirt, and oil that a sealed enclosure provides. To this end, enclosure designs need to strike a balance between protecting components from the detrimental influences of the outside environment, while also preventing excessive build-up of heat and humidity inside the enclosure. It is also important to consider the enclosure's surface area because the physical size of the enclosure is a primary factor in determining its ability to dissipate heat to the surrounding environment.

Airflow is a critical factor to consider when evaluating or optimizing the heat dissipation for devices on a PCB. Airflow provides heat dissipation through convection. It is a key component for determining the thermal resistance between a device and the surrounding air (the overall θ_{JA}). Even still air in which the heat dissipation is dominated by radiation typically has some small amounts of airflow created by the natural heat radiating from the devices inside the PCBs. However, the direct use of forced air as a tool to improve heat dissipation through convection can be a required component of a system design. In sealed enclosures, it is possible to use circulating fans to reduce hot spots within the enclosure, as well as fans mounted directly to heatsinks. For non-sealed enclosures, heat dissipation can be maximized by using cabinet fans to force airflow through the enclosure in from and out to the surrounding environment.

Humidity

Humidity is a thermal management component that is frequently overlooked. While the humidity of the air inside an enclosure can somewhat affect the air's ability to conduct heat, this is generally considered an insignificant effect. A bigger challenge related to humidity is to identify a thermal solution that can regulate both humidity and temperature inside the enclosure. If left unchecked, excessive humidity can lead to condensation and subsequent corrosion of both the enclosure and the internal components, as well as increased heat from corroded connection points.

Altitude

Because the density of air varies with altitude, so does the efficiency of a heatsink. As can be seen from [Table 3-1](#), the effects are not insignificant.

Table 3-1: Altitude Derating Factors

Altitude (Metres)	Altitude (Feet)	Derating Factor
0 (sea level)	0	1.00
1,000	3,000	0.95
1,500	5,000	0.90
2,000	7,000	0.86
3,000	10,000	0.80
3,500	12,000	0.75

The altitude effect should be considered in all cases. While the air temperature of an indoor environment is normally controlled and is not affected by altitude change, the indoor air pressure does change with altitude. Because many electronic systems are installed at an elevated altitude, it is necessary to derate the heatsink performance mainly due to the lower air density caused by the lower air pressure at higher altitudes. [Table 3-1](#) shows the performance derating factors for typical heatsinks at high altitudes.

To determine the actual thermal performance of a heatsink at altitudes other than sea level, the thermal resistance values read off from the performance graphs should be divided by the derating factor before the values are compared with the required thermal resistance. For example, a 1°C/W heatsink would become 1.16°C/W at an altitude of 2,000 meters, or 1.25°C/W at 3,000 meters.

Thermal Data Comparison

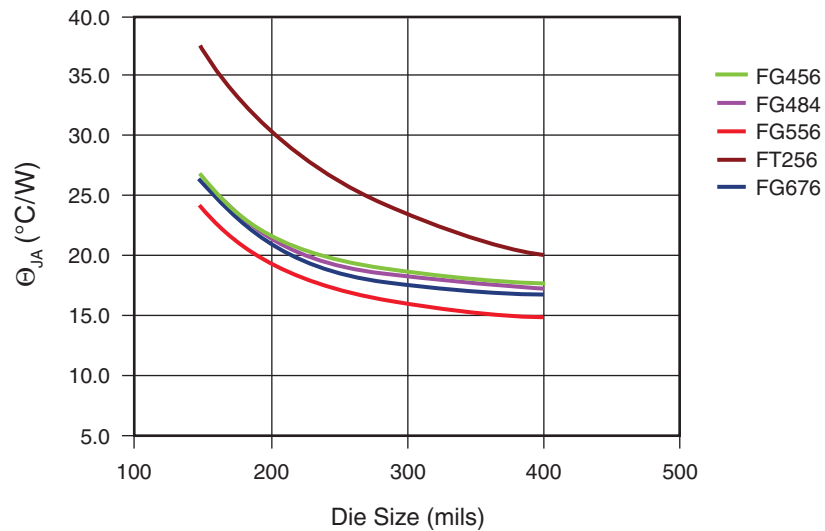
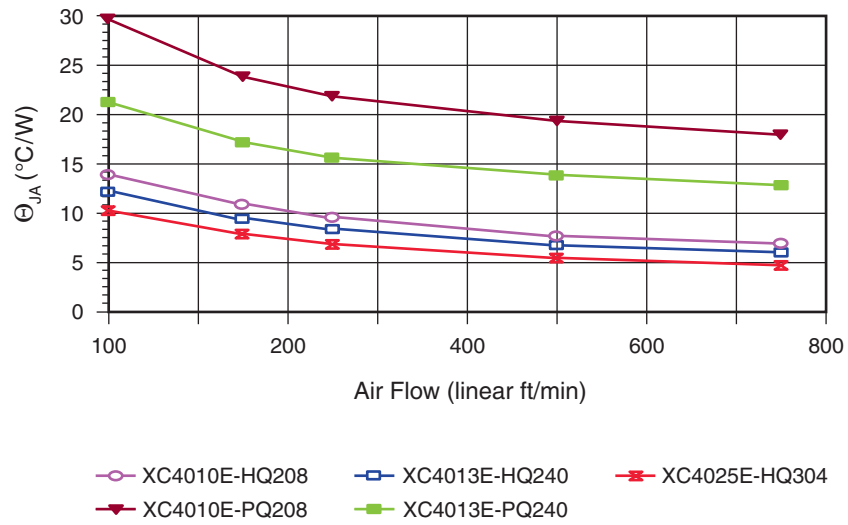


Figure 3-3: Effect of Die Size on the Thermal Resistance (θ_{JA}) of PBGA Packages



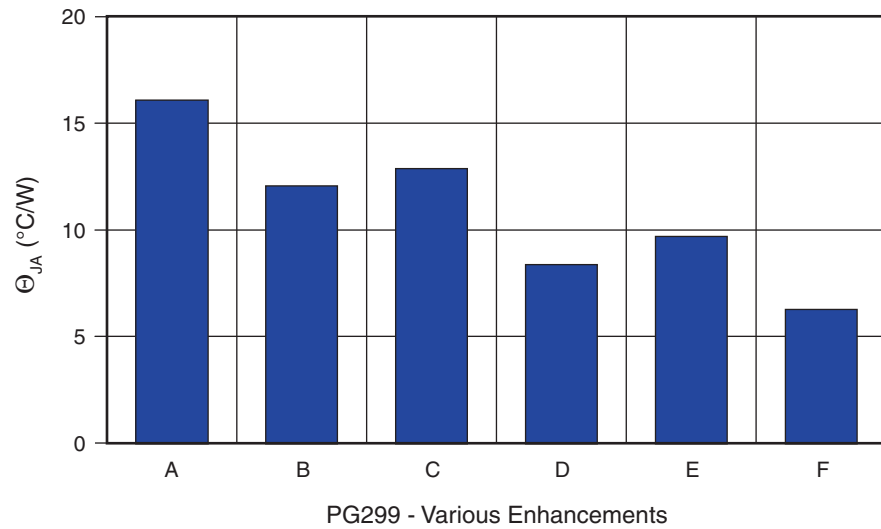
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Figure 3-4: Effect of Air Flow on the Thermal Resistance (θ_{JA}) of HQ/PQ Packages

Table 3-2: Impact of Mounted Board Characteristics on θ_{JA} Flip-Chip FF1148

Xilinx 35 x 35 mm FF1148-4VLX100		Board Size		
		4 in x 4 in Board	10 in x 10 in Board	20 in x 20 in Board
Layer Count of Mounted Board	4	10.1 (100%)	9.2 (91%)	N/A
	8	8.9 (88%)	6.1 (60%)	5.5 (54%)
	12	8.3 (82%)	5.2 (51%)	4.9 (48%)
	16	8.0 (79%)	5.0 (50%)	4.6 (46%)
	24	N/A	4.7 (47%)	4.5 (44%)

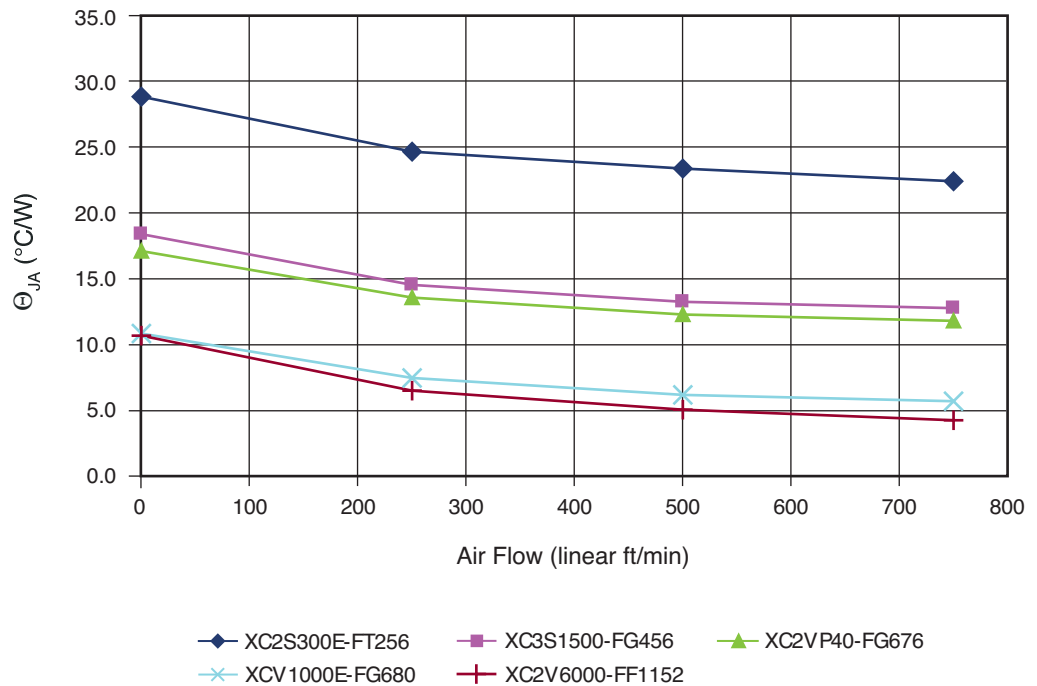
1. JEDEC mount conditions.



- A Standard Pkg
- B Pkg+Finned HS (Passive)
- C Pkg+Active Fan (V=0)
- D Pkg+Active Fan (V=12)
- E Std Pkg +250LFM
- F Pkg+Finned HS+ 250LFM

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Figure 3-5: Effect of Active and Passive Heat Sinks on the Thermal Resistance (θ_{JA}) of PG299 Packages



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Figure 3-6: Effect of Air Flow on the Thermal Resistance (θ_{JA}) of BGA Packages

Package Thermal Characterization Methods and Conditions

Characterization Methods

Xilinx uses several methods to obtain thermal performance characteristics of integrated circuit packages. The methods include thermal simulation using finite element software tools, and an indirect electrical method utilizing an isolated diode on a special thermal test die. This can even be done on a Xilinx FPGA housed in the package of interest or by using System Monitor to measure die temperature. The majority of the data reported by Xilinx on previous technologies is based on the indirect diode method, but on newer devices, System Monitor has been the main characterization method. Simulation tools, calibrated with actual measurement data, are used to supplement thermal collateral data generation. Most published compact thermal model data is based on such an effort.

Calibration of Isolated Diode

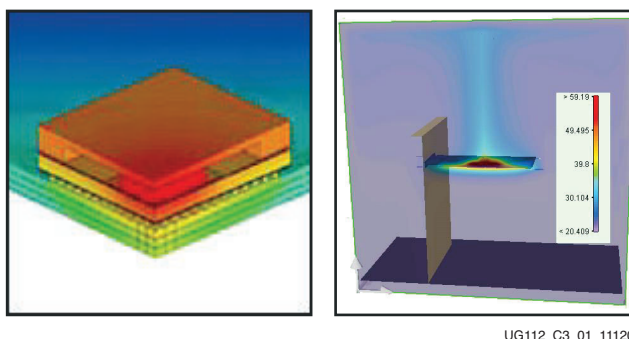
In the direct electrical method, the forward-voltage drop of an isolated diode residing on a special test die or the temperature diode of the Xilinx FPGA is calibrated by applying a constant forcing current (from 0.100 mA to 0.500 mA) over a temperature range of 0°C – 125°C (degrees Celsius). The calibrated packaged device is then mounted on an appropriate board and placed in the testing environment — *e.g.*, still air or forced convection. Power (P_D) is applied to the device through diffused resistors on the same thermal die. In the FPGA case, a known self-heating program is loaded and clocked to generate the monitored power. Usually, between 0.5 watts to 4 watts can be applied. Higher power (up to 10 watts) is possible, depending on the package. The resulting rise in junction temperature is monitored with the forward-voltage drop of the precalibrated diode.

Calibration of System Monitor

The System Monitor calibration is done through the internal settings of the device. A voltage reference regulator that sets the accuracy level is connected to the System Monitor. This voltage reference should be set to a level that is above the voltage limit of the System Monitor, which is set to 3.0 V. Providing a voltage below this limit compromises the accuracy of the System Monitor.

Simulation Methods

In the simulation effort, finite element (FEA) methodology is used to represent the packages of interest. The package geometrical details (based on CAD data), as well as the board stack-up details are captured. Published material properties are used as input to derive the thermal characteristics based on JEDEC environment and boundary conditions. Using sample test data, the FEA inputs and assumptions are optimized to minimize variation between measurement and simulation.



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Figure 3-7: Simulation Tool Outputs:
a) Quarter Model of a Package, b) CTM in JEDEC Enclosure

Once the simulation inputs and assumptions are refined, the FEA method is used to obtain the thermal characteristics including thermal models of devices in a family using the same material set and construction details.

Measurement Standards

Previously, Xilinx Thermal lab used the SEMI thermal test methods (#G38-87) and associated SEMI-based boards (#G42-87) to perform thermal characterization. Most of our recent measurements and simulations are based on provision of the JEDEC and EIA Standard — JESD51-n series specifications. It is our assessment that the latter standard offers some options that are not available in the SEMI method. We will continue to quote the SEMI-based data (designated by SEMI in the comment column) for older packages measured in the earlier era, and when we quote new data, they will be designated as JESD in the comment section.

It is also essential to note that these standard-based measurements give characterization results that allow packages and conditions to be compared. Like miles per gallon (MPG) figures quoted on new cars, the numbers should be used with caution. As specific user environments will not be identical to the conditions used in the characterization, the numbers quoted might not precisely predict the performance of the package in an application-specific environment.

For better in-system T_J prediction, Xilinx provides compact thermal models for its devices. Some of these are available in model libraries for download at the Download Center <http://www.xilinx.com/support/download/index.htm>

Models for older products can be requested from ctm_team@xilinx.com.

Definition of Terms

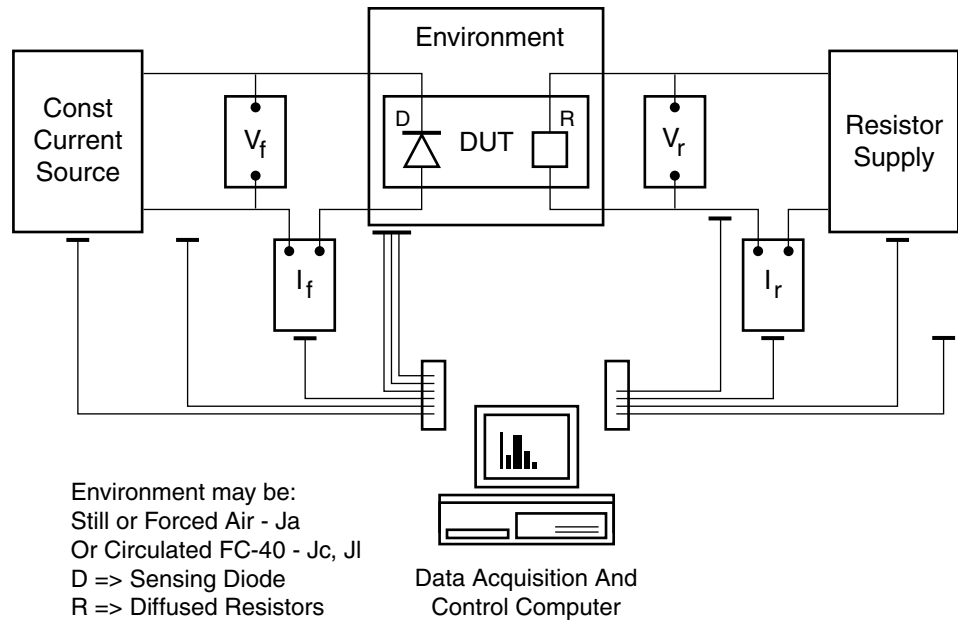
T_J – Junction Temperature, defined as the maximum temperature on the die, expressed in °C (degrees Celsius).

T_A – Ambient Temperature, defined as the temperature of the surrounding environment, expressed in °C (degrees Celsius).

T_C – Temperature of the package taken at a defined location on the body. In most situations, it is taken at the primary heat flow path on the package and will represent the hottest part on the package, expressed in °C. See the next item for when T_C is taken at the top.

- T_B – This is the board temperature taken at a predefined location on the board near the component under test, expressed in °C.
- P_D – The total device power dissipation, expressed in watts.
- T_S – This is the heatsink temperature, expressed in °C.

Junction-to-Reference General Setup



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Figure 3-8: Thermal Measurement Setup (Schematic for Junction to Reference)

Junction-to-Case Measurement — θ_{JC}

Theta-JC (θ_{JC}) measures the heat flow resistance between the die surface and the surface of the package (case). This data is relevant for packages used with external heatsinks. It assumes that heat is flowing through the top to the exclusion of the others. In the ideal case, all the heat is forced to escape the package at the path where T_C is taken. The lateral heat flow is not allowed or minimized so that the source of temperature differential will be attributable to the total known heat input.



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Figure 3-9: θ_{JC} Measurement Setup

A copper heatsink plate at the top of the package is used in θ_{JC} methods to achieve the forced preferred directional flow.

Prior to 1999, the junction-to-case characterization on some heatsink packages was accomplished in a 3M Fluorinert (FC-40) isothermal circulating fluid stabilized at 25°C. Current Xilinx data on θ_{JC} is simulated using the cold plate approach.

Prior to 2010, The JEDEC standard proposed to use thermocouples to measure T_C . The new JEDEC standard JESD51-14 does not include the measurement of case temperature. Instead, it describes the transient dual interface (TDI) test method for the measurement of the junction-to-case thermal resistance.

From the previous JEDEC standards, with applied power (P_D) and under stabilized conditions, case temperature (T_C) is measured with a low gauge thermocouple (36-40 AWG) at the primary heat-flow path of the particular package. Junction temperature (T_J) is calculated from the diode forward-voltage drop from the initial stable condition before power is applied:

$$\theta_{JC} = (T_J - T_C) / P_D$$

where the terms are as defined above. A poorly defined θ_{JC} condition usually leads to lower numbers being reported. In such cases, the recorded temperature difference ($T_J - T_C$) is the result of having a fraction of the power going through the path. However, in the calculation, the full power is used.

Because the necessary thermocouple measurement of the case temperature is prone to errors, these results are often not sufficiently reproducible. Some of the errors that could occur are:

- A temperature distribution at the package case while the thermocouple measures the temperature at its contact point to the case. This might not be the maximum case temperature.
- A potentially low case temperature reading because the thermocouple beads are often not sufficiently insulated against the cold plate and could therefore be cooled from the wire and cold plate side.
- The application of considerable clamping pressure to press the semiconductor device against the heatsink, which closes delaminations.
- The drill hole for the thermocouple in the heatsink influencing the thermocouple measurement. This influence increases with smaller devices.

The new JEDEC standard JESD51-14 specifies the TDI measurement method of the junction-to-case thermal resistance without a case temperature measurement. The thermal impedance or Zth-function $Z\theta_{JC}(t)$ of a semiconductor device that is heated with constant power (P_H) starting at time $t = 0$ while its case surface is connected to a heatsink is defined as:

$$Z\theta_{JC}(t) = (T_J(t) - T_J(t = 0)) / P_H$$

Thus, the thermal impedance equals the time-dependent change of the junction temperature $T_J(t)$ divided by the heating power. If the cooling condition at the package case is changed, this should have no influence on the thermal impedance until the temperature starts to increase at the package case where the contact to the heatsink is located. However, a measurement with a different contact resistance changes the total thermal resistance at steady state and therefore separates the impedance curves of different measurements starting from the point where the external contact resistance begins, which can be identified as the package case interface.

Two thermal impedance measurements are made with different contact resistances for cooling the package case surface connected to the heatsink to identify this surface in transient measurements. The cumulative thermal resistance at the separation point of these two measurements is defined as $R\theta_{JC}$ (θ_{JC}).

Junction-to-Ambient Measurement — θ_{JA}



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Figure 3-10: θ_{JA} Measurement Setup

SEMI method: Some of the data reported are based on the SEMI standard methods and associated board standards. θ_{JA} data reported as based on SEMI were measured on FR4-based PC boards measuring 4.5 in x 6.0 in x .0625 in (114.3 mm x 152.4 mm x 1.6 mm) with edge connectors. Several versions are available to handle various surface mount (SMT) devices. They are, however, grouped into two main types. Type I board (the equivalent of the JEDEC low-conductivity board) is single layer with two signal planes (one on each surface) and no internal Power/GND planes. This is the 2L/0P or 2S/0P board and the trace density on this board is less than 10% per side. The type II board (the equivalent of the JEDEC 2S/2P board) has two internal copper planes — one power and one ground. These planes are in addition to the two signal trace layers on both surfaces. This is the 4L/2P (four-layer, also referred to as 2S/2P) board.

JEDEC measurements: Packages are measured in a one foot-cube enclosure based on JESD51-2. Test boards are fashioned per test board specification JESD51-3 and JESD51-7.

The board sizes depend on the package and are typically 76.2 mm x 114.3 mm x 1.6 mm or 101.6 mm x 114.3 mm x 1.6 mm. These come in low-conductivity as well as high-conductivity versions.

Thermal resistance data can be taken with the package mounted in a socket or with the package mounted directly on traces on the board. Socket measurements typically use the 2S/0P or low-conductivity boards. SMT devices, on the other hand, can use either board. Published data always reflect the board and mount conditions used (ref 2S/0P or 4L/2P).

The board with the device under test (DUT) is mounted in the test enclosure and data is taken at the prevailing temperature and pressure conditions — between 20°C and 30°C ambient (T_A). Appropriate power is used, depending on the anticipated thermal resistance of the package. Applied power, signal monitoring — including the enclosure (ambient) temperatures are noted. The junction to ambient thermal resistance is calculated as follows:

$$\theta_{JA} = (T_J - T_A) / P_D$$

In the case of airflow measurement, this is done in a special airflow enclosure section of a suction-type low-velocity wind tunnel. Airflow velocities from 0–1000 linear feet per minute (LFM), *i.e.*, 0–5.08 m/s, are used with very low turbulence. The controlling specification is JESD51-6. Airflow measurements use similar boards as θ_{JA} with air conditions noted with hot wire anemometer.

Thermal Resistance: Junction-to-Board — θ_{JB}

This is defined as:

$$\theta_{JB} = (T_J - T_B) / P_D$$

where T_B is the board temperature at steady state measured at specified location on the board. P_D is the actual power in watts that produces the change in temperature.

T_B is monitored on a board with a 40-gauge thermocouple at specific location in the proximity of the package leads or balls. As an example, for BGA package, the thermocouple is attached to a trace midway along the side of the package with the attachment point within 1 mm of the package body.

Like θ_{JC} , θ_{JB} depends on constrained flow in a preferred direction. In actual measurement or simulations the heat flow is forced to go preferably through the board by excluding other paths with insulation. The measurement conditions are not likely to be reproduced in a real application.

Data Acquisition and Package Thermal Database

Data for a package type is gathered for various die sizes, power levels, cooling modes (air flow and sometimes heatsink effects) with a Data Acquisition and Control System (DAS). The system controls and conditions the power supplies and other ancillary equipment for hands-free data taking. A package is completely characterized with respect to the major variables that influence the thermal resistance. A database is generated for the package. From the database, thermal resistance data is interpolated as typical values for individual Xilinx devices that are assembled in the characterized package.

Figure 3-11 is a screen shot of the Package Thermal Data Query for Xilinx components. This tool is located on Xilinx.com at <http://www.xilinx.com/cgi-bin/thermal/thermal.pl>. Device-specific data from the thermal database can be obtained from this web site. The data from this query is specific to the devices of the individual packages.

Home : [Support](#) : Package Thermal Data Query

Package Specifications

Device Package User Guide

Package Thermal Data Query

This Query allows the user to use Device Family (for example, Virtex™-4), Device name (for example, XC4VLX25) and Package code (for example, FF668) to obtain product specific Thermal Data. The results of the QUERY include the thermal resistances - Theta-Jc, Theta-ja (still air up to 750 LFM) per the EIA-JESD51 methods.

Device Family :

Device Name :

Package Name :

Note:
If you do not find a package or product in the list contact support. While the list is constantly reviewed to reflect current supported products, note that the availability of thermal data for a product in the Query results does not necessarily imply that the product is currently supported or will be supported in the future. Do NOT use the Query to check current device availability and support.

If you need technical support or assistance, please see [Contact Support](#) page.

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Figure 3-11: Package Thermal Data Query for Device-Specific Data

Thermal data consistent with the above query results can also be found in product-specific user guides for newer device families. Below are three examples:

- [UG365](#), *Virtex-6 FPGA Packaging and Pinout Specifications*
- [UG385](#), *Spartan-6 FPGA Packaging and Pinouts Product Specification*
- [UG475](#), *7 Series FPGAs Packaging and Pinout Advance Specification*

The linked query provides thermal data for all released and active Xilinx products. The supporting data table is updated periodically to include newer products and prune inactive products. Data from the Query replaces the generic package based (summarized by package type) thermal data that used to be tabulated in previous versions of this user guide.

Application of Thermal Resistance Data

Thermal resistance data is used to gauge the IC package thermal performance. There are several ways to express the thermal resistance between two points. The following are a few of them:

- θ_{JA} = Junction to ambient thermal resistance ($^{\circ}\text{C}/\text{W}$).
- θ_{JC} = Junction to case thermal resistance ($^{\circ}\text{C}/\text{W}$)
- θ_{JB} = Junction to board thermal resistance ($^{\circ}\text{C}/\text{W}$)
- θ_{CA} = Case to ambient thermal resistance ($^{\circ}\text{C}/\text{W}$)
- θ_{CS} = Case to heatsink thermal resistance ($^{\circ}\text{C}/\text{W}$)
- θ_{SA} = Heatsink to ambient thermal resistance ($^{\circ}\text{C}/\text{W}$)

Other thermal parameters include

- Ψ_{JC} = Junction to board thermal characteristic parameter ($^{\circ}\text{C}/\text{W}$)
- Ψ_{JT} = Junction to package thermal characteristic parameter ($^{\circ}\text{C}/\text{W}$)

θ_{JC} measures the internal package resistance to heat conduction from the die surface, through the die mount material to the package exterior. θ_{JC} strongly depends on the package material's heat conductivity and geometrical considerations.

θ_{JA} measures the total package thermal resistance including θ_{JC} . θ_{JA} depends on the package material properties and such external conditions as convective efficiency and board mount conditions. For example, a package mounted on a socket can have a θ_{JA} value 20% higher than the same package mounted on a four-layer board with power and ground planes.

In general, θ_{MN} expresses the thermal resistance between points M and N. In the above expression, the source and end points are indicated.

In situations where a heatsink is used with a heatsink compound, thermal resistance of heatsink is referenced as θ_{SA} (sink-to-ambient) and the attached material as θ_{CS} (case-to-heatsink). These thermal resistances can be added. For example, $\theta_{JA} = \theta_{JC} + \theta_{CS} + \theta_{SA}$ is an expression used in heatsink situations with interface material resistance θ_{CS} .

Thermal Data Usage Examples

Note: Actual thermal resistance in a system can be impacted by several user conditions. In the examples that follow, it should be noted that unique user conditions will impact predictions and estimates. Such user conditions have not been taken into consideration in the examples. One of the main influences on thermal resistance is board conditions. Table 3-2 shows a table that illustrates how the thermal resistance of a flip-chip package (FF1148) is influenced by the board characteristics. The package with a high-conductivity JEDEC board-based measured θ_{JA} of 10.1°C/watt can exhibit almost a 50% reduction in θ_{JA} if a 10 in square board with 16 copper layers is used. Other user boundary conditions can also affect the effective thermal resistance in a system. Figure 3-4 depicts the impact when airflow is applied to packages. In general, as users work their way through these examples, external influences have not been taken into account in the estimates.

The following are some data requirements for using thermal resistance in an application.

- Xilinx-supplied data:
 - Thermal data for θ_{JA} and θ_{JC} is available at:
<http://www.xilinx.com/cgi-bin/thermal/thermal.pl>
 - Thermal data for θ_{SA} is provided by heatsink supplier.
- Items that the user might need to supply:
 - T_{Jmax}
 - This can go as high as the absolute maximum temperature for the package — typically 125°C to 135°C for plastic
 - Note that components are tested to meet the speed file specifications at the temperatures associated with them – 85°C for C grade, and higher I and M grades. Running the parts at a higher T_J than specified might not meet the specifications.
 - The user will have to pick a T_{Jmax} for reliability considerations, and plan the thermal budget around that
 - T_A : Ambient temperature in a system
 - This is also another variable that the user can control. Typically, this is set to approximately 45°C to 55°C. It could also be as high as 75°C or 100°C, based on the application.
- Items usually estimated:

- Power dissipation. The thermal equation can be used to determine a power range that can satisfy some given conditions
- Also, if power is known, T_{Jmax} can be calculated from the equations
- If the temperature on the top of a bare part is well monitored in a system (not the way θ_{JC} is measured), the thermal parameter Ψ_{JT} can be used to get junction temperature
- Similarly, a well monitored board temperature can be used to predict junction with the Ψ_{JC} parameter

In non-heatsink situations, the following inequality formula should hold:

$$T_{Jmax} > \theta_{JA} \times P_D + T_A$$

The two examples below illustrate the use of the above inequality formula. Specific packages are used in the examples, but any package—Quad, BGA, FGs, or even flip-chip based BGs—are applicable.

Example 1

The manufacturer’s goal is to achieve $T_{Jmax} < 85^\circ\text{C}$

A module is designed for a $T_A = 45^\circ\text{C}$ max.

An XCV300 in a FG456 has a $\theta_{JA} = 16.5^\circ\text{C}/\text{watt}$. $\theta_{JC} = 2.0^\circ\text{C}/\text{watt}$.

Given an XCV300 with a logic design with a rated power P_D of 2.0 watts.

With this information, the maximum die temperature can be calculated as:

$$T_J = 45 + (16.5 \times 2.0) = 78^\circ\text{C}.$$

The system manufacturer’s goal of $T_J < 85^\circ\text{C}$ is met in this case.

Example 2

A module has a $T_A = 55^\circ\text{C}$ max.

The Xilinx FPGA XCV400E is in a PQ240 package.

A logic design in XCV400E is determined to be 2.70 watts. The module manufacturer’s goal is to achieve T_J (max.) $< 100^\circ\text{C}$.

[Table 3-3](#) shows the package and thermal enhancement combinations required to meet the goal of $T_J < 100^\circ\text{C}$.

Table 3-3: Thermal Resistance for XCV400E in PQ240 Package

Device Name	Package	θ_{JA} still air	θ_{JA} (250 LFM)	θ_{JA} (500 LFM)	θ_{JA} (750 LFM)	θ_{JC}	Comments
XCV400E	PQ240	17.9	13.2	11.7	10.8	3.2	Cu, SMT 2L/0P

For all solutions, the junction temperature is calculated as: $T_J = \text{Power} \times \theta_{JA} + T_A$. All solutions meet the module requirement of less than 100°C , with the exception of the PQ240 package in still air. In general, depending on ambient and board temperatures conditions, and most importantly the total power dissipation, thermal enhancements such as forced air cooling, heat sinking, etc., might be necessary to meet the T_J (max) conditions set.

Possible solutions to meet the module requirements of 100°C :

- Using the standard PQ240: $T_J = 55 + (17.9 \times 2.70) = 103.33^\circ\text{C}$.
- Using standard PQ240 with 250 LFM forced air: $T_J = 55 + (13.2 \times 2.70) = 90.64^\circ\text{C}$.

Heatsink Calculation

Example illustrating the use of heatsink:

Device is XCV1000E-FG680

There is a need for external thermal enhancements.

Data supplied from Xilinx on XCV1000E-FG680 is shown in [Table 3-4](#)

Table 3-4: Data Supplied from Xilinx on XCV1000E-FG680

Package Code	θ_{JA} still air	θ_{JC} °C/W	θ_{JA} (250 LFM)	θ_{JA} (500 LFM)	θ_{JA} (750 LFM)
FG680	10.6	0.9	7.5	6.1	5.6

- Customer requirements
 - $T_a = 50^\circ\text{C}$
 - Power = 8.0 watts (user's estimate)
 - User does not want to exceed T_{Jmax} of 100°C
- Determination with base Still Air data:
 - $T_J = T_A + (\theta_{JA}) \times P$
 - $T_J = 50 + 8 \times 10.6 = 134.8^\circ\text{C}$
 - Unacceptable! θ_{JA} in still air will not work because the 134.8°C is beyond the stated goal of 100°C or less.
- Calculating acceptable thermal resistance:
 - Determine what θ_{JA} will be required to stay below 100°C with the 8 watts power?
 - Thermal budget = $(T_J - T_A) = 50^\circ\text{C}$.
 - $\theta_{JA} = (50)/8 = 6.25^\circ\text{C}/\text{watt}$.
 - The package and any enhancement to it need to have an effective thermal resistance from the junction to ambient less than $6.25^\circ\text{C}/\text{watt}$. That becomes the goal any thermal solution ought to meet.
- Solution Options:
 - The bare package with 500 LFM (2.54 meters/s) of air will give $\theta_{JA} = 6.1^\circ\text{C}/\text{watt}$. (from the data table above). That will be a workable option, if that much airflow will be tolerable.
 - Heatsink calculation. With a heatsink, heat will now pass through the package (θ_{JC}) then through an interface material (θ_{CS}), and from the heatsink to ambient (θ_{SA}). This can be expressed as follows:
 - $\theta_{JA} \geq \theta_{JC} + \theta_{CS} + \theta_{SA}$
 - $6.25 \geq 0.9 + 0.1 + \theta_{SA}$

where

- $6.25^\circ\text{C}/\text{watt}$ is the condition to be met
- $0.9^\circ\text{C}/\text{watt}$ — θ_{JC} from data

- $0.1^{\circ}\text{C}/\text{watt} - \theta_{\text{CS}}$ from interface material data
- From above, $\theta_{\text{SA}} \leq 5.25^{\circ}\text{C}/\text{watt}$
- The objective will be to look for a heatsink with $\theta_{\text{SA}} < 5.25^{\circ}\text{C}/\text{watt}$ that meets the physical constraints in the system
- Passive heatsink with some air flow — 250 LFM (1.25 m/s) can be selected
- Active heatsinks — it might be possible to use small low-profile heatsinks with DC fans

Additional Power Management Options

The variety of applications that the FPGA devices are used in makes it a challenge to anticipate the power requirements and thus the thermal management needs a particular user might have. While Xilinx programmable devices might not be the dominating power consumers in some systems, it is conceivable that high-gate-count FPGA devices will be exercised sufficiently to generate considerable heat.

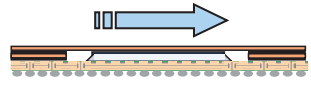
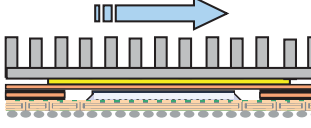
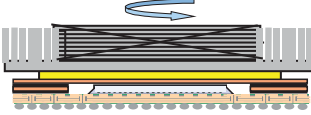


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Figure 3-12: Enhanced BGA with Low Profile Retainer Type Passive Heatsinks

In general, high-I/O and high-gate-count devices have the potential of being clocked to produce high wattage. Being aware of this potential in power needs, the package offering for these devices includes medium- and high-power-capable package options. This allows a system designer to further enhance these high-end BGA packages to handle more power.

When the actual or estimated power dissipation appears to be more than the specification of the bare package, some thermal management options can be considered. The accompanying Thermal management chart illustrates the incremental nature of the recommendations — ranging from simple airflow to schemes that can include passive heatsinks and active heatsinks.

Low end 1–6W	Bare package with moderate airflow 8–12°C/W.	Bare package can be used with moderate airflow within a system.	
Mid range 4–10W	Passive heat sink with moderate airflow 5–10°C/W.	Package used with various forms of passive heat sinks and heat spreader techniques.	
High end 8–25W	Active heat sink 2–3°C/W or better.	Package used with active heat sinks, TEC and board level heat spreader techniques.	

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Figure 3-13: Thermal Management — Incremental Options

The use of heat pipes, and even liquid-cooled heat plates, can be considered in the extreme for some of these packages. Details on the engineering designs and analysis of some of these suggested considerations might require the help of thermal management consultants. The references listed at the end of this section can provide heatsink solutions for industry-standard packages.

Some of the options available in thermal management can include the following:

- Most high-gate-count Xilinx devices come in more than two package types. Explore thermally enhanced package options available for devices. The quad packages and some BGA packages have heat enhancement options. Typically, 25% to 40% improvement in thermal performance can be expected from these heatsink-embedded packages.
- In a system design, natural convection can be enhanced with venting in the system enclosure. This will effectively lower the T_a and increase available thermal budget for moderate power dissipation.
- The use of forced-air fans is the next step beyond natural convection, and it can be an effective way to improve thermal performance. As seen on the graphs and the calculations above, forced air (200-300 LFM) can reduce junction-to-ambient thermal resistance by up to 30%.
- For moderate power dissipation, the use of passive heatsinks and heat spreaders attached with thermally conductive double-sided tapes or retainers can offer quick solutions.
- The use of lightweight finned external passive heatsinks can be effective for dissipating up to 8 watts on some packages. If implemented with forced air as well, the benefit can be a 40% to 50% reduction as illustrated in the XCV1000E-FG680 example. The more efficient external heatsinks tend to be tall and heavy. When using a bulky heatsink, it is advisable to use spring-loaded pins or clips to reduce heatsink-induced stress on the solder joints of the component as these pins or clips help transfer the mounting stress to the circuit board. The diagonals of some of these heatsinks can be designed with extensions to allow direct connection to the board (see [Figure 3-14](#)).

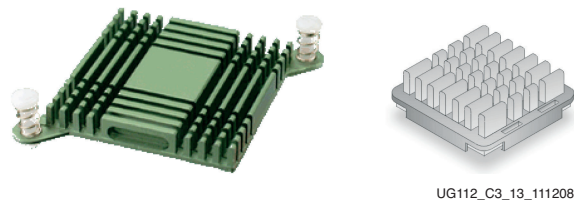


Figure 3-14: Heatsink with Clips

- Exposed metal heatsink packages: All thermally enhanced BGAs with dies facing down (including these package codes - BG352, BG432, BG560, FG680, FG860, and flip-chip BGAs) are offered with an exposed metal heatsink at the top. These are considered high-end thermal packages and they lend themselves to the application of external heatsinks (passive or active) for further heat removal efficiency. Again, precautions should be taken to prevent component damage when a bulky heatsink is attached.
- Active heatsinks can include a simple heatsink incorporating a mini fan or even Peltier Thermoelectric Coolers (TECs) with a fan to carry away any heat generated. Any consideration of applying TEC in heat management should include consultation with experts in using the devices, as these devices can be reversed and this might damage components. Also, condensation can be an issue.
- Molded packages (FG456, FG676, FG1156, PQs, etc.) without exposed metal at the top also can use these heatsinks at the top for further heat reduction. These BGA packages are similar in construction to those used in graphic cards in PC applications, and heatsinks used for those applications can easily be used for these packages as well. In this case, the θ_{JC} resistance will be the limiting consideration.



Figure 3-15: Example of Active Heatsink for BGA (Malico)

- Outside the package itself, the board on which the package sits can have a significant impact on thermal performance. Board designs can be implemented to take advantage of a board's ability to spread heat. Heat flows to the outside of a package and is sunk into the board to be conducted away – through heatpipes or by normal convection. The effect of the board will be dependent on the size and how it conducts heat. Board size, the level of copper traces on it, and the number of buried copper planes all lower the θ_{JA} thermal resistance for a package mounted on it. Some of the heatsink packages – like HQ, with the exposed heatsink on the board side – can be glued to the board with thermal compound to enhance heat removal into the board. BGA packages with full matrix of balls can be cooled with this scheme. Users need to be aware that a direct heat path to the board from a component also exposes the component to the

effect of other heat sources, particularly if the board is not cooled effectively. An otherwise cooler component can be heated by other heat-contributing components on the board.

See “[Web Sites for Heatsink Sources](#)” for lists of Web sites that offer more information on heat management and sources for interface material.

System Simulation Support

For more accurate in-system T_J prediction, Xilinx can provide Compact Thermal Models (CTMs) to be used in system thermal simulations. The figure of merit thermal data Xilinx provides can be used to select packages and perform comparative thermal analysis and some preliminary T_J predictions. However, when the thermal margins are very tight, or the component is integrated with other heat sources in a system, a full system thermal analysis might be required. These CTMs are provided to reduce the computational complexity.

Our CTMs are based on the Delphi approach that JEDEC has proposed. Since the JEDEC neutral (XML) format proposal has not been adopted yet, the Delphi approach is used to generate these files and the data saved in the native and proprietary file formats of the targeted CFD tools, rather than follow a neutral file. We are closely following JC15-1 developments and hope to offer the neutral file format when it is ready and adopted by the CFD tool vendors.

In the meantime, these CTMs are based on the Delphi (dotcomp optimization) approach for specific tools. These tools occupied the first two places in our pre-introduction customer survey. The libraries are available in Flotherm (pdml) format; V5.1 and above and Icepack (ver. 4.2 and above) format.

The Virtex-4 device, and newer products are supported. CTM data can be downloaded from the Xilinx Support Download Center <http://www.xilinx.com/support/download/index.htm>.

Models for older products can be requested from: ctm_team@xilinx.com.

The plan is to support models for other CFD tools through the neutral format approach. Before the neutral file format is adopted, there might be limited support of Xilinx formatted ASCII-based file defining nodes and listing the associated resistances between nodes for manual entry into various other tools that support CTM usage; requests of this type should be directed to: ctm_team@xilinx.com.

References

These references provide additional information to support the material in this chapter:

<http://www.jedec.org/standards-documents/results/jesd51>

<http://www.irf.com/technical-info/appnotes/an-1057.pdf>

<http://www.aavidthermalloy.com/technical/papers/pdfs/select.pdf>

http://goliath.ecnext.com/coms2/gi_0199-832204/Approaches-to-thermal-management-enclosure.html

http://www2.emersonprocess.com/siteadmincenter/PM%20DeltaV%20Documents/WHITEPAPERS/WP_Heat_Airflow_Encl.pdf

<http://www.midwestequipment.com/docs/enclosureratings.pdf>

<http://www.midwestequipment.com/docs/enclosureenmaratings.pdf>

<http://www.midwestequipment.com/docs/heatdissipation.pdf>

Package Electrical Characteristics

Introduction

As data rates increase and signal rise times become shorter, the effects of package parasitics are becoming increasingly significant as the hardware engineers model their circuits. Discontinuities that might have had minimal impact on circuit performance in past generations of components are now of paramount importance as designers strive to achieve higher performance in their systems.

The IC package forms an interconnect system just like traces on a printed circuit board (PCB) or conductors in connectors. When a designer simulates the signaling performance from a driver to a receiver, all the interconnect parasitics in the path, including the package, must be considered in order to achieve simulation results that represent the entire system's performance.

Current Xilinx packages are constructed with either wirebond or flip chip interconnect technology. Some components use simpler leadframe-based packages, while others use laminate-based packages with multilayer construction. The choice of package matches the performance and marketing objectives sought for the device family. In multilayer packages, innovative pin-out selections and creative design techniques are used in a co-design effort to optimize package performance and to prevent the package from being a limiting factor for the device. For these high performance FPGA packages, Xilinx also provides package models that allow the user to take package parasites into account to accurately model the component's performance prior to committing to hardware.

This chapter focuses on defining certain critical concepts associated with electrical characterization of packages. It is also intended to provide relevant theoretical review of electrical issues and concepts as they relate to the characterization effort. The document provides descriptions of the methods utilized to generate the parasitic data and derive appropriate models for their use. Some data examples, ranging from simple tabulated RLC to s-parameter models, are given to illustrate the range of electrical data that are available for the packages.

Terminology - Definitions and Reviews

There are a number of key concepts that should be understood in order to appreciate how packages affect the signals transiting through them, as well as how package parasitics are modeled or measured in the lab.

Any conductor system is characterized by some basic electrical parameters which are dependent of the physical design of the system, a package is no exception. The basic electrical parameters associated with packages are resistance, inductance, conductance, and capacitance. These are commonly referred to as RLGC parameters. The parameters will be defined in the following subsections. The section also explains several other metrics

which are derived from RLGC parameter values. Finally, more advanced concepts such as s-parameters, crosstalk, and SSN will be covered.

Resistance (R)

Resistance is one of the basic electrical parameters that commonly defines the series loss in a conductor. Electrically, Ohm's law defines resistance as the ratio of voltage to current in a conductor:

$$R = \frac{E}{I} \quad \text{Equation 4-1}$$

Where:

R = electrical resistance (Ω)

E = voltage (V)

I = current (A)

Physically, resistance is defined as:

$$R = \frac{\rho l}{A} \quad \text{Equation 4-2}$$

Where:

R = resistance (Ω)

ρ = resistivity of the conductor material

l = length of conductor

A = cross-sectional area of the conductor

The physical equation above is valid at DC where the current flows through the whole cross sectional area of the conductor. At higher frequencies, where skin effect becomes important, the cross sectional area is decreased and consequently the resistance increases at higher frequencies. The amount that the cross sectional area is decreased is highly geometry-dependent and is also a function of the proximity of the conductor to other nearby current carrying conductors. Typically, the reported R component of the package resistances are given at DC for nets intended to operate below about 1 GHz. Higher frequency nets, such as those associated with transceivers (MGTs and GTPs), are characterized with frequency-dependent losses. These frequency-dependent losses are best determined with 2D or 3D extractor software.

The skin depth (which is the depth of electric and magnetic field penetration) of a conductor is given by:

$$\delta = 50\mu\sqrt{\frac{\rho}{f}} \quad \text{Equation 4-3}$$

Where:

δ = skin depth in microns (μ)

ρ = conductor resistivity ($\mu\Omega - cm$)

f = frequency (MHz)

As a point of reference, δ is about 20 microns at 10 MHz frequency if the conductor is copper. Note that δ decreases with $1/\sqrt{f}$, so at a frequency of $4f$, the skin depth would be one half the value that it was at a frequency of f .

Inductance (L)

Inductance is one of the fundamental properties of any electrical conductor. Any current carrying conductor is surrounded by lines of magnetic flux. These lines are circular loops which encircle the current carrying conductor. The number of loops in any instance is concentrated near the conductor with the density of the lines decreasing as the distance from the conductor increases. A basic relationship for inductance is:

$$L = \frac{N}{I} \quad \text{Equation 4-4}$$

Where:

L = inductance in (H)

N = number of magnetic lines encircling the conductor in (Wb)

I = current (A)

Inductance is geometry-dependent.

Whether a conductor has 1 Amp or 100 Amps flowing through it, the inductance is the same since the ratio remains constant. The presence of dielectric material near the conductor will not alter the inductance. The presence of ferro-magnetic material with permeability greater than 1 will affect the inductance.

When we discuss inductance, the terms *loop inductance*, *partial inductance*, *self inductance*, and *mutual inductance* are some of the items that come up. These are explained below:

- Loop inductance is the inductance of a complete current carrying loop. It is a unique value dependent on the loop geometry. The larger the area encompassed by the loop, the larger the loop inductance will be.
- A partial inductance is the inductance contributed by a portion of the loop. It is not a unique value.
- Self Inductance - When one refers to the inductance of a conductor the reference is usually meant to imply the self inductance. This is the ratio of lines of magnetic flux to current where the lines encircle their own conductor.
- The concept of mutual inductance comes into play when one considers lines of magnetic flux generated by a current carrying conductor that also encircle (or couple to) another conductor. These lines of flux will cause a voltage to be generated into the coupled conductor.

Some Inductance Expressions

Closed form analytical equations to calculate inductance do exist for simple geometries. In a complex system like a package, such simplified closed form expressions are hard to come by; approximations abound with varying degrees of accuracy. To accurately determine the partial inductance of conductor geometry in a package, the use of a good 2D or 3D electromagnetic extractor program is recommended. Below are some closed-form formulas that are reasonably accurate for geometries commonly found in packages.

- Partial self inductance of a round wire (with ground at infinity):

$$L_{wire} = 5 \cdot d \left[\ln\left(\frac{2d}{r}\right) - \frac{3}{4} \right] \quad \text{Equation 4-5}$$

Where:

L_{wire} = inductance (nH)
 d = wire length (inches)
 r = wire radius (inches)

- Partial self inductance of a round wire over a metal plane:

$$L_{wire} = 5 \cdot d \cdot \left[\ln\left(\frac{2 \cdot h}{r}\right) \right] \quad \text{Equation 4-6}$$

Where:

L_{wire} = inductance (nH)
 d = wire length (inches)
 h = height of wire above the plane (inches)
 r = wire radius (inches)

- Partial self inductance of a rectangular conductor (with ground at infinity):

$$L = 5 \cdot d \cdot \left[\ln\left(\frac{2d}{(w+t)}\right) + \frac{1}{2} \right] \quad \text{Equation 4-7}$$

Where:

L = inductance (nH)
 d = conductor length (inches)
 w = conductor width (inches)
 t = thickness of conductor (inches)

- Partial self inductance of a rectangular conductor - like a trace or perhaps a leadframe lead over a metal plane:

$$L = 5 \cdot d \cdot \left[\ln\left(\frac{8h}{(w+t)}\right) + \frac{w+t}{4h} \right] \quad \text{Equation 4-8}$$

Where:

L = Inductance (nH)

d = conductor length (inches)

h = height of conductor above the plane (inches)

w = conductor width (inches)

t = thickness of conductor (inches)

These relationships are compiled from publications by several authors^(1,2,3) including Eric Bogatin, and Brian Young and Grover.

Capacitance (C)

The capacitance of a conductor is dependent on the area of the conductor, the distance the conductor is placed from some reference conductor and the dielectric constant of the dielectric material. An expression for simple parallel plate capacitance is commonly expressed as:

$$C = \frac{\epsilon_0 \cdot A}{t} \quad \text{Equation 4-9}$$

Where:

C = capacitance

ϵ_0 = permittivity of free space

A = conductor area

t = dielectric thickness

If the dielectric material between the conductors is some material other than air or vacuum the equation is modified to include the relative dielectric constant ϵ_r as follows:

$$C = \frac{\epsilon_0 \cdot \epsilon_r \cdot A}{t} \quad \text{Equation 4-10}$$

Where:

C = capacitance

ϵ_0 = permittivity of free space

A = conductor area

t = dielectric thickness

ϵ_0 is equal to 0.0885 pF/cm or equivalently 0.225 pF/inch. The capacitance of a conductor increases if the size of the conductor increases, the thickness of the dielectric decreases, or the dielectric constant of the dielectric material increases. While this expression is not directly applicable to the geometries of package transmission lines and planes, it does illustrate the basic relationships between capacitance and the dielectric constant, conductor area and dielectric thickness.

Other ways of expressing capacitance:

- Capacitance is also defined as the ratio of charge to voltage that can be stored between a pair of conductors:

$$C = \frac{Q}{V} \quad \text{Equation 4-11}$$

Where:

C = capacitance (Farads)

Q = charge (Coulombs)

V = voltage (volts)

- Transmission lines commonly have their capacitance specified as a per-unit-length (PUL) value such that $C_{total} = C_{PUL} \times length$:
- Self capacitance is the capacitance of a conductor to ground (C_1 would be the capacitance of conductor 1 to ground). Mutual capacitance is the capacitance between two conductors (C_{12} would be the capacitance between conductor 1 and conductor 2).

Examples of closed form expressions for capacitance:

For complex structure a field solver is the preferred method of determining the capacitance of a conductor, however for a couple simple structures the following equations can provide answers accurate to within about 5%.

- Wire over a ground:

$$C = \frac{1 \cdot 4 \cdot \epsilon_{eff}}{\ln\left(\frac{2h}{r}\right)} \quad (\text{pF/inch}) \quad \text{Equation 4-12}$$

$$\epsilon_{eff} = \frac{\epsilon_r + 1}{2} + \left(\frac{\epsilon_r - 1}{2}\right) \frac{1}{\sqrt{\left(1 + \frac{10h}{r}\right)}} \quad \text{Equation 4-13}$$

Where:

ϵ_r = relative dielectric constant of the dielectric

h = distance from the ground plane to the center of the wire (inches)

r = is the radius of the wire (inches)

- Capacitance between two parallel wires:

$$C = \frac{1 \cdot 4 \cdot \epsilon_r}{\ln\left(\frac{s^2}{ab}\right)} \quad (\text{pF/inch}) \quad \text{Equation 4-14}$$

where:

s = distance between wire centers

a = diameter of first wire

b = diameter of second wire

Conductance (G)

The conductance parameter (G) is related to the losses in the insulating substrate material. This is a frequency dependent parameter that scales directly with frequency. Most all substrate materials utilized in package construction have very low losses at low frequencies (less than 1 GHz). As a result, the conductance (a parallel loss) is very low and is usually ignored when modeling SelectIO™ lines. The dielectric loss does become significant at the higher frequencies where high speed nets are utilized. These lines are typically characterized by s-parameters as opposed to RLGC parameters.

Impedance (Z)

The impedance of a transmission line can be calculated readily if the line's inductance and capacitance are known. The relevant equation is:

$$Z = \sqrt{\frac{L}{C}} \quad \text{Equation 4-15}$$

Where:

Z = impedance in (Ω)

L = the line's per-unit-length inductance (H)

C = the line's per-unit-length capacitance (F)

When circuit elements interface with each other (for example, package trace and PCB trace, or PCB trace and termination), any mismatch in their impedances at their boundaries will result in reflections. The higher the mismatched magnitude, the greater the associated reflection, hence distortion in the signal traversing the mismatched interface. For this reason, it makes sense to minimize the impedance mismatches in a system.

Time Delay (T_d)

The time delay for transmission line (i.e., conductor) in a package is calculated by the equation [$T_d = \sqrt{LC}$] where the delay is in seconds, the capacitance is in Farads and the inductance is in Henrys. Knowledge of a line's delay contribution is needed in determining timing closure. Time delay can also be determined if one knows the relative dielectric constant ϵ_r of the substrate material associated with a transmission line. A transmission line with air as a dielectric propagates signals at the speed of light ($c = 3 \times 10^{10}$ cm/second) or about 5.9 inches/psec. In a material with a relative dielectric of ϵ_r the velocity of propagation is given by the expression:

$$v = \frac{c}{\sqrt{\epsilon_r}} \quad \text{Equation 4-16}$$

Where:

v = velocity in the material

c = speed of light

ϵ_r = relative dielectric constant of the dielectric material

For example, typical FR4 material has a dielectric constant of about 4, so the velocity of propagation in a transmission line utilizing FR4 as the dielectric material will be $c/2$ (one half the speed of light) or 2.95 inches/psec. The time delay of a transmission line is simply the reciprocal of the velocity. In the case of FR4, the T_d is about 169.5 inches/psec. Additionally, the time of flight (T_{of}) in a transmission line is simply the line's length times T_d . This T_{of} number is what would be used in timing closure calculations.

For large size laminate and ceramic-based packages where T_d is likely to be over 50 ps, the delay data is provided. This T_d is derived from the LC data if the per-pin data is available. In some cases, T_d is derived directly from the trace length data of the relevant package design.

Crosstalk

Coupling (usually unwanted) from one conductor to another is termed "Crosstalk". The line generating the signal is called the "aggressor" and the line into which the signal is coupled is termed the "victim." Generally, this coupled signal is considered noise and is undesired. There are two mechanisms involved in this unwanted coupling between circuits; capacitive and inductive. Capacitive coupling occurs when the victim net is affected by the electric-field lines generated by the aggressor. Inductive coupling is caused by the magnetic-field lines generated by the aggressor inducing a voltage in the victim circuit. Physically, the two items that affect coupling are the distance between the two circuits and the length of the coupling regions. The most effective way to minimize crosstalk is to increase the spacing between the aggressor and victim nets.

Crosstalk is broadly divided into "near-end" and "far-end" crosstalk. Near-end crosstalk is always positive since the currents generated by the inductive and capacitive coupling components add and sum at the near end. Far-end crosstalk can be either negative or positive. If the magnitude of the inductively coupled component is larger than the capacitive coupled component then the difference of the currents at the far end is positive, however, if the capacitive component predominates then the far end effect will be a negative voltage. Also note, that the magnitude of the near-end crosstalk is insensitive to the coupled length of the aggressor and victim nets. However, the far-end crosstalk will increase with increasing coupled length until a saturation point is reached.

The exact mathematical relationships for calculating crosstalk can be complex and vary in detail depending on whether the nets are terminated or open circuited and whether near-end or far-end crosstalk are considered.

The following expressions, taken from *High Speed Digital System Design*⁴, illustrate a couple of cases where both the aggressor and victim nets are terminated at both the near and far-end (quite often the case): The above reference reviews other terminated cases as well.

- Far-end Crosstalk

$$\frac{\left(\frac{L_{ij}}{L_i}\right) - \left(\frac{C_{ij}}{C_i + C_{ij}}\right)}{4}$$

Equation 4-17

- Near-end Crosstalk

$$\frac{\left(\frac{L_{ij}}{L_i}\right) + \left(\frac{C_{ij}}{C_i + C_{ij}}\right)}{2}$$

Equation 4-18

Where:

C_i and L_i are the self capacitance and inductances of the victim lines, respectively.

C_{ij} and L_{ij} are the mutual capacitances and inductances respectively between nets i and j .

Ground Bounce

Ground bounce is the voltage difference between any two grounds (typically between an IC and circuit board ground) induced by simultaneously switching current through bond wire, lead, or other interconnect inductance. When IC outputs change state, large current spikes result from charging or discharging the load capacitance. The larger the load capacitance and faster the rise/fall times, the larger the current spikes are: $I = C * dv/dt$. Current spikes through the IC pin and bondwire induce a voltage drop across the leads and bondwires: $V = L * di/dt$. The result is a momentary voltage difference between the internal IC ground and system ground, which show up as voltage spikes and unswitched outputs.

Factors that affect ground bounce include:

- rise and fall times
- load capacitance
- package inductance
- number of output drivers sharing the same ground path
- device type

Signal Integrity and Package Performance

Resistance, Capacitance and Inductance (defined in the “[Terminology - Definitions and Reviews](#)” section) are the three major electrical parameters used in one format or another to describe package electrical performance. These metrics are used to describe I/O, as well as power networks of the packages. The parameters, also known as interconnect parasitics, can be the source of many serious issues in digital systems. For example, a large resistance can cause RC and RL off-chip delays, power dissipation, and edge-rate degradation. Large capacitance in I/O nets can cause RC delays, crosstalk, edge-rate degradation, and signal distortion. Lead inductance, perhaps the most damaging parasitic in digital circuitry, can cause such problems as ground bounce (also known as simultaneous switching noise or delta-I noise), RL delays, crosstalk, edge-rate degradation, and signal distortion.

In the design of Xilinx packages, the challenge is to seek the appropriate balance for these parameters so that signal integrity issues are minimized. Package characterization is geared to assist the package designers in a co-design effort to make the appropriate choices backed by simulation and measurements in optimizing the package design and layout for performance. A further goal of the effort is to gather the parasitics data and seek the appropriate data representation of these parameters to help end-users deploy these packages. To this end, Xilinx offers raw tabulated package parasitic data, summaries of data, and various models as part of the deliverable. Representative samples will be shown at appropriate sections.

The measurement and 3D extraction capability, as well as the models support, will be described in the subsequent sections.

Electrical Data Generation and Measurement Methods

With regards to experimental measurements, Xilinx uses both the Time-Domain Reflectometry (TDR) method for parasitic inductance and capacitance measurements, as well as frequency domain measurements performed with a 4-port Vector Network Analyzer (VNA). The practical measurement capability is augmented by a range of analytical calculators, 2D and 3D full wave FEM tools that are utilized through simulations to extract various signal integrity-based parameters about the packages.

Review of Practical Measurements

The main components of a TDR setup includes a digitizing sampling oscilloscope, a fast rise-time step generator (<17 ps), a device-under-test (DUT) interface, and impedance-profile analysis software to extract parasitic models from the TDR reflection waveforms. In this method, a voltage step is propagated down the package under test, and the incident and reflected voltage waves are monitored by the oscilloscope at a particular point on the line. The resulting characteristic impedance of the package interconnect shows the nature (resistive, inductive, and capacitive) of each discontinuity.

The VNA measurement setup is composed of a 20 GHz 4-port VNA, a probing station, and microprobes. Using the VNA, s-parameter measurements of various package nets are made over wide bandwidths. The VNA injects a swept frequency signal into the DUT. The instrument then measures both reflected and transmitted voltages at various package nodes which are being probed.

Package Sample and Fixture Preparation

Prior to performing package measurements utilizing either the TDR or VNA, the package and the DUT interface must be fixtured. Proper fixturing ensures accurate and repeatable measurements.



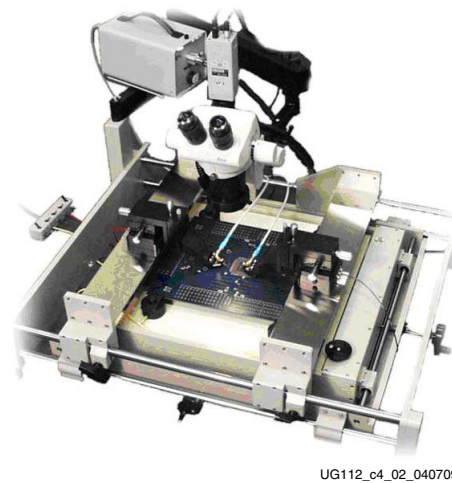
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Figure 4-1: Altair BGA Fixture Used for TDR Measurement

Figure 4-1 depicts an Altair BGA test fixture that is used in some of the TDR measurements on BGA packages. For TDR measurements, the DUTs for all inductance (self and mutual) are specially assembled components with all leads shorted to the internal package ground. For packages without an internal ground (i.e., QFP, PLCC, etc.), the die-paddle is used instead (i.e., bonds are made to the paddle). Measurement includes the wire parasitics.

The DUT samples for capacitance (self and mutual) measurements are special assembled package units with all internal leads floating (un-bonded). In the actual testing, the lead/ball under test is isolated and all other package leads are connected to a common potential (ground) in the all conductor grounded (OCG) mode.

The DUT interface provides a physical connection between the oscilloscope and the DUT with minimum crosstalk and probe/DUT reflection. It also provides a small ground loop to minimize ground inductance of the fixture.



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Figure 4-2: GTL VNA Fixture

For VNA measurements, either single-sided or two-sided measurements can be made. In most cases, the package to be measured is attached to a test fixture board that facilitates holding the sample package during the measurement procedure. Two-sided measurements allow characterization of the package from the bumps sites to the BGA balls. The package is held at right angles to the probing station table. Single-side measurements are sometimes made when it is difficult or impossible to achieve two-sided probing of the package. In this case, the package is held parallel to the probe station table.

In both TDR and VNA cases, measured waveforms are usually downloaded to an integrated PC running analysis software for package parasitic model extraction. The software for TDR uses a method called the Z-profile algorithm, or the impedance-profile algorithm, for parasitic analysis. This method translates the downloaded reflection waveforms into true impedance waveforms, from which package models for inductance and capacitance are extracted.

Software-Based Simulations and Extractions

Xilinx data generation approach consists of a mix of electrical models based on 2-D and Full Wave 3-D package simulations/extraction that are calibrated with time and frequency domain measurements. Once the simulation assumptions are optimized and calibrated with data, we deploy the extraction tools to generate per pin data and other full package

models that might be impossible to deal with a TDR or VNA directly. The simulation tools are used to make determinations and provide design guidelines for pre-layout feasibility, pin assignment review, and layout design rule generation. In the post-layout/fab stage, these software tools are deployed to, among other things, extract parasitics on the whole package. In addition to parasitic extraction, the tools also provide voltage drops and current densities of the power and ground nets. These same tools are used to generate data and models for internal as well as external use.

Some of the tools used in this effort are listed below.

Modeling and Simulation Tools

- Ansoft Maxwell Q2D
- Ansoft HFSS (High Frequency Structure Simulator)
- Optimal Corp. PakSi-E High Speed 3D Field Solver
- Optimal Corp. O-wave/PowerGrid
- Cadence Advance Package Engineer (APE)/SpectraQuest
- Sigrity; Power SI
- TDA Systems I-Connect

Package Electrical Data Delivery Formats

The tables below show some typical electrical data summaries. In general, generated electrical data is tabulated for the product and can be used in the appropriate IBIS models for the component. Specific products data, packages not listed, or additional information (such as mutual and power plane data), can be obtained through a model at the download area or by contacting Xilinx Support with the specifics.

- **Summary data tables:** On most leadframe type packages (TQ, PQs, PC, etc.) and smaller laminate packages, Xilinx typically acquires electrical parasitic data on the longest and shortest lead/traces of the package based on design data. This provides the best and worst case for each package type (defined by package design, lead/ball count, pad size, etc.). [Table 4-1](#) below shows some typical data for some laminate-based FPGA packages. Similar data is depicted in [Table 4-2](#) for leadframe-based packages. For specific product-based data, users can review the [Package] section of the IBIS file or work through their field engineer.
- **The IBIS header file - [Package].** Most electrical data generated for recent device families will be summarized in the [Package] section of the device IBIS file. The [Package] section data will be formatted in the Typical, Min and Max format of the file. In the completed IBIS file, all of the packages should be represented. The user might need to uncomment the specific package of interest. The [Package] section of the Spartan-3E FPGA file is shown in [Figure 4-4](#) to illustrate this method of conveying package-specific electrical data for a device family. Note that in this example, the FG320 is uncommented for use. The device IBIS files can be downloaded from <http://www.xilinx.com/support/download/index.htm>
- **Per pin data tabulation:** Per pin electrical data is available for packages for most high end FPGA devices. Per pin data is not available for legacy products or leadframe devices. Xilinx keeps a database for this data type and will make them available to end-users in Excel format on request. The header for a typical Excel formatted per pin data tabulation can be found in [Figure 4-5](#).

- IBIS .pkg type file format:** See next section - models at Xilinx for description of IBIS format. This method conveys per pin RLC data in both coupled and uncoupled .pkg format. This is usually a long data file that can be parsed to get to the per pin data.

Data Examples

Table 4-1 contains typical measured electrical data for some common laminate packages.

Table 4-1: Electrical Data for Common Laminate Packages

Package Type	Xilinx PkgCode	Lself-Max (nH)	Lself-Min (nH)	C-Max (pF)	C-Min (pF)	R-Max (mΩ)	R-Min (mΩ)
1.27 pitch BGA	BG225	11.5	0.9	2.20	0.67	210	15
	BG256	6.9	0.6	1.30	0.68	185	12
	BG352	7.2	0.7	1.50	0.80	282	26
	BG432	9.6	1.4	1.30	0.80	325	57
	BG560	10.7	2.2	2.70	0.30	551	190
	BG728	10.3	0.3	3.20	0.20	341	14
Small Form Factor	CP132	3.8	1.2	0.30	0.10	158	135
	CP56	2.2	0.3	0.40	0.14	313	48
	CS144	3.0	1.5	0.30	0.20	143	76
	CS280	8.9	2.7	0.80	0.20	371	148
	CS48	2.4	1.8	0.30	0.20	126	26
	CS484	6.6	2.5	1.55	0.63	257	110

Table 4-1: Electrical Data for Common Laminate Packages (Cont'd)

Package Type	Xilinx PkgCode	Lself-Max (nH)	Lself-Min (nH)	C-Max (pF)	C-Min (pF)	R-Max (mΩ)	R-Min (mΩ)
Fine pitch 1.0 mm BGA	FT256	9.9	1.8	1.30	0.40	333	92
	FG256	6.4	1.6	1.20	0.50	230	73
	FG320	7.6	4.0	1.70	0.60	311	180
	FG324	9.3	3.6	1.90	0.80	353	187
	FG456	9.2	0.9	3.60	0.50	545	58
	FG484	9.7	2.1	2.30	0.70	573	77
	FG676	10.1	0.3	5.40	0.40	585	30
	FG680	9.7	3.9	2.30	0.20	606	199
	FG900	11.8	2.1	2.20	0.40	340	89
	FG1156	12.3	1.8	2.20	0.50	330	82

Notes:

1. Wirebond parasitics were part of the consideration.
2. The data depicted in the table is a summary of measured data of typical laminate packages used for FPGAs. They are summarized without reference to the specific device families and for a larger range to cover all devices.
3. For more recent devices, specific device-based parasitic limits, as well as typical values, can be found in the [Package] section of the appropriate downloadable device IBIS file.
4. These ranges also apply to the lead-free equivalent packages. The lead-free version of packages has the letter "G" appended before the numeric portions of the package code (e.g., the lead-free version of FT256 will become FTG256). The same data applies to both packages.

Table 4-2 contains a summary of parasitics for some leadframe-based packages. The data includes the wirebond parasitics.

Table 4-2: Parasitics for Leadframe-based Packages

Xilinx PkgCode(1)	Lself-Max (nH)	Lself-Min (nH)	C-Max (pF)	C-Min (pF)	R-Max (mΩ)	R-Min (mΩ)
PD8	6.4	3.0	1.0	0.6	52	32
VO8	2.0	1.6	0.3	0.3	44	41
SO20	3.0	1.7	0.4	0.2	60	40
PC20	3.6	1.8	0.7	0.6	60	11
PC44	4.3	2.1	1.0	0.7	69	14
PC68	10.2	5.0	1.3	0.9	60	39
PC84	13.0	6.8	1.8	1.6	58	43
VQ44	2.4	1.2	0.4	0.2	60	16
VQ64	1.7	1.3	0.4	0.4	30	23
VQ100	6.7	1.5	0.8	0.3	124	18
TQ44	1.6	1.1	0.4	0.3	20	15

Table 4-2: Parasitics for Leadframe-based Packages (Cont'd)

Xilinx PkgCode ⁽¹⁾	Lself-Max (nH)	Lself-Min (nH)	C-Max (pF)	C-Min (pF)	R-Max (mΩ)	R-Min (mΩ)
TQ100	5.9	1.1	0.7	0.3	108	17
TQ144	9.7	6.4	1.4	0.7	144	105
TQ176	10.1	3.5	1.3	0.7	58	44
PQ100	8.2	2.3	1.3	0.4	99	29
PQ160	15.2	5.2	1.9	1.0	127	62
PQ208	15.9	5.3	2.0	0.5	138	81
PQ240	15.2	6.9	2.0	1.3	126	71
HQ208	12.7	5.3	2.0	1.0	139	73
HQ240	12.1	4.9	2.5	1.2	119	57
HQ304	12.2	7.3	2.7	1.9	144	94

Notes:

1. This same data applies to the lead-free versions of the packages. The lead-free version of these packages has the letter "G" appended before the numeric portions of the package code (for example, the lead-free version of TQ144 will be TQG144). The same data applies to both packages.
2. This is a compilation of measured data for leadframe packages without regard to any specific device family. Most product data will fall within these limits. These limits can be used for components listed in these products. Recent family of products will have specific limits in the [Package] section of the device IBIS file.
3. This table will be updated periodically to reflect the addition of newer packages and updates to existing package data with newer limits, should those new devices expand the range.

Table 4-3 contains a summary of select I/O RLC parasitics for some flip-chip packages.

Table 4-3: Select I/O RLC Parasitics for Flip-Chip Packages

Xilinx PkgCode ⁽¹⁾	Lself-Max (nH)	Lself-Min (nH)	C-Max (pF)	C-Min (pF)	R-Max (mΩ)	R-Min (mΩ)
SF363	5.4	0.7	3.88	0.47	657	16
FF668	6.2	0.8	3.34	0.84	1854	30
FF672	7.9	0.5	3.11	0.40	1466	22
FF676	6.0	1.2	3.93	1.00	1837	71
FF896	8.2	0.8	7.50	0.90	680	21
BF957	12.2	0.8	1.90	0.60	561	27
FF1148	14.5	0.7	4.62	0.60	1962	38
FF1152	11.8	0.5	5.30	0.77	2076	23
FF1513	7.5	0.4	4.66	0.48	2450	32
FF1517	9.0	0.8	9.70	0.75	1848	24
FF1704	14.1	0.6	10.20	1.20	639	36

Table 4-3: Select I/O RLC Parasitics for Flip-Chip Packages (Cont'd)

Xilinx PkgCode ⁽¹⁾	Lself-Max (nH)	Lself-Min (nH)	C-Max (pF)	C-Min (pF)	R-Max (mΩ)	R-Min (mΩ)
FF1760	6.3	1.2	3.66	0.94	1884	75

Notes:

- These ranges also apply to the lead-free equivalent of the packages. The lead-free version of packages has the letter “G” appended before the numeric portions of the package code (for example, the lead-free version of FF1148 will become FFG1148). The same data applies to both packages.
- The I/O data reflects the full flip chip interconnect chain-bump, the vias, traces, and external balls as depicted in Figure 4-3.
- The data presented in Table 4-3 is a compilation of all SelectIO-based data for all devices used in these flip-chip packages across a couple of generations of Virtex devices. The range encompasses all the known devices at the time of publication. This table will be updated periodically to include newer packages and updates to older packages with newer data, should those new devices expand the range.
- Specific device family data can be obtained from the IBIS file (see example in Figure 4-4), or they can be requested through your field engineer.

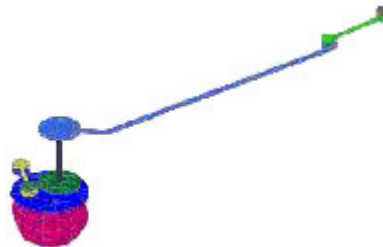


Figure 4-3: Flip Chip Interconnect Chain

Figure 4-4 is a representation of electrical parasitics data embedded in an XC3SE IBIS file depicting the package electrical summary data in the [Package] section. In this case the FG320 package is uncommented as the default package. Data for other packages are clearly visible in this window.

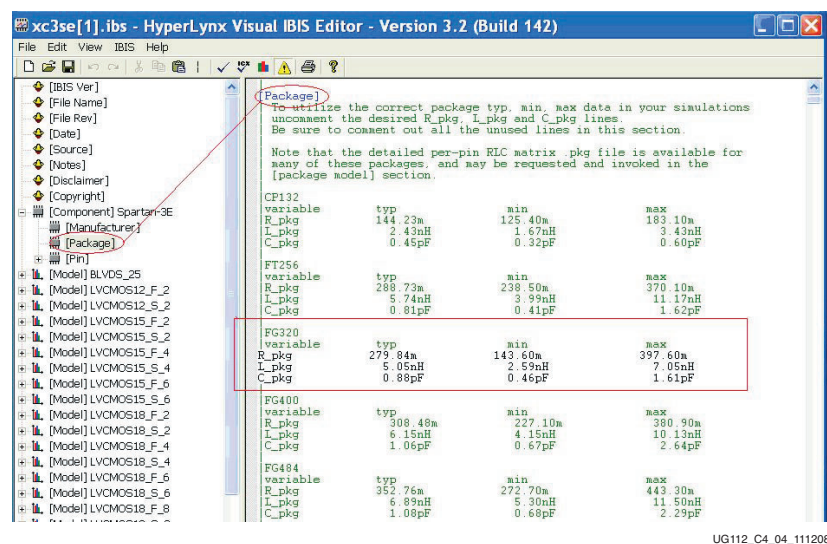


Figure 4-4: Embedded Electrical Parasitics Data

Figure 4-5 illustrates Excel formatted tabulation of per pin data. The top 20 balls of the file for XC4VLX60 in FF1148 are shown.

Package: **FF1148**
 Piecepart: **FGA0092**
 Device: **XC4VLX60**
 Freq: **500 MHz**
 Rev: **1.0**

	R (mΩ)	L (nH)	C (pF)
Max	1931.00	6.13	4.11
Mean	1013.00	4.01	2.59
Min	68.87	1.37	1.17

0	Ball	R (mOhm)	L (nH)	C (pF)	0	Ball	Function
1	A2	VCCO_6	VCCO_6	VCCO_6	1	A2	VCCO_6
2	A3	1765.00	5.93	3.55	2	A3	IO_L20N_VREF_6
3	A4	1604.00	5.64	3.48	3	A4	IO_L20P_6
4	A5	1483.00	5.44	3.48	4	A5	IO_L22P_6
5	A6	1460.00	5.17	3.00	5	A6	IO_L12P_6
6	A7	GND	GND	GND	6	A7	GND
7	A8	1446.00	5.06	2.93	7	A8	IO_L10P_6
8	A9	1440.00	4.86	2.92	8	A9	IO_L15N_6
9	A10	1288.00	4.59	2.70	9	A10	IO_L15P_6
10	A11	1076.00	4.08	2.33	10	A11	IO_L3P_6
11	A12	VCCO_6	VCCO_6	VCCO_6	11	A12	VCCO_6
12	A13	1397.00	4.68	2.75	12	A13	IO_L17N_6
13	A14	1355.00	4.75	2.91	13	A14	IO_L17P_6
14	A15	1753.00	5.68	3.60	14	A15	IO_L24P_LC_1
15	A16	NOPAD	NOPAD	NOPAD	15	A16	NOPAD
16	A17	NOPAD	NOPAD	NOPAD	16	A17	NOPAD
17	A18	NOPAD	NOPAD	NOPAD	17	A18	NOPAD
18	A19	GND	GND	GND	18	A19	GND
19	A20	1634.00	5.33	3.39	19	A20	IO_L17N_CC_LC_1
20	A21	1384.00	4.81	2.94	20	A21	IO_L21N_5

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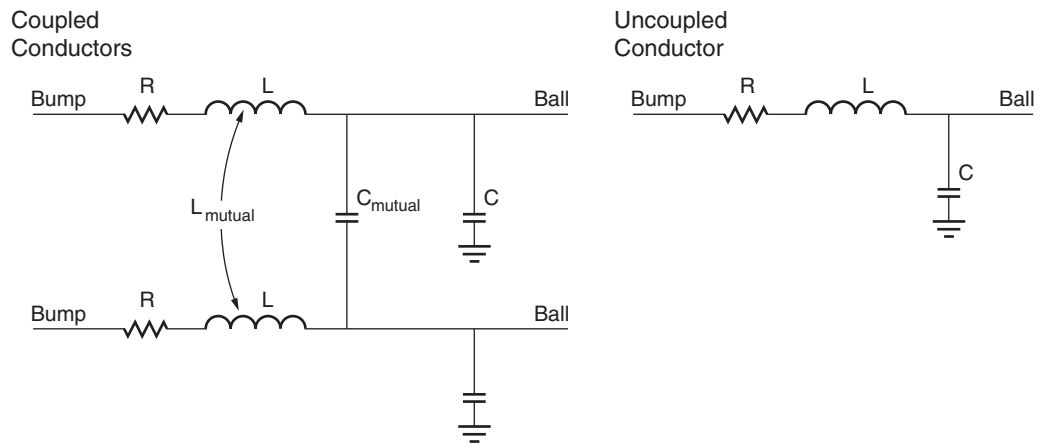
Figure 4-5: Excel Formatted Tabulation of Per Pin Data

Models at Xilinx - Electrical Data Delivery via Models

Package models are a means to convey package electrical data, as stated in the previous section. These are provided to allow device users to accurately predict the performance of their designs. Xilinx recognizes that there might be several I/O model types available. For this reason, package electrical data is provided through the following I/O model formats as default:

- Base [Package] section data in IBIS device file. The base [Package] section data is provided for all newer devices in the base IBIS file. This data usually lists the packages used with Typical, Min, and Max parasitics, as illustrated in Figure 4-4.
- RLC matrix .pkg data format in either coupled RLC or uncoupled - depends on the device and size of package for SelectIO. These whole package RLC matrix data models are recommended for use below at about 1 Gbit/second data rates. The R, L and C element values are not frequency dependent. (The R value is typically characterized at DC). The IBIS .pkg format data is intended to be read by an IBIS simulator which will utilize the data to create an appropriate package model that will be connected to the IBIS buffer model being simulated. These models can be utilized in simulators such as HyperLynx, ICX, Hspice, and others. These models are extracted

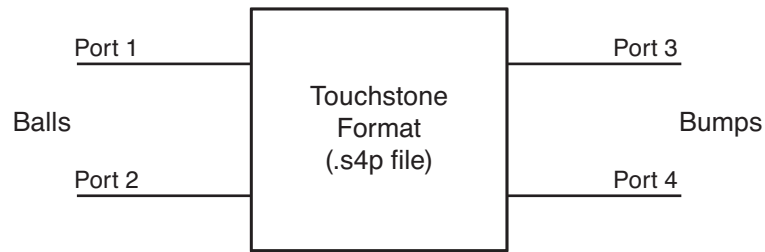
from the design database utilizing a 3D quasi-static FEM extracting tool. Figure 4-6 illustrates the topology of the extracted RLC parasitic data for both coupled and uncoupled conductors.



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Figure 4-6: Topology of Extracted RLC Parasitic

- Touchstone s-parameter data files for high speed (e.g., MGT) nets. The s-parameter based models are provided to model the package nets associated with the MGT drivers and receivers at data rates above 1 Gbit/second. The s-parameter data provided is extracted with 3D full-wave FEM extractor directly from the package design database. The tool setup and assumptions are optimized and calibrated with measured data. Typically, data is provided over the range of 1 GHz to 15 GHz, though wider bandwidth data might be available for some parts. S-parameters are measured and extracted with the assumption of a 50-ohm source and load impedance. At high frequencies, it is much easier to establish a good 50-ohm impedance than it is to establish a short or open, free from parasitic and fringing effects, as is often done in the characterization of low frequency components. S-parameter models are typically provided as Touchstone 4-port “.s4p” files to characterize differential MGT nets. The port assignment convention, as well as a sample 2-port formatted file, is illustrated in Figure 4-7.



```

!Sample 2-port Touchstone format file
! Port1:bump;IPort2:ball :IO_L29N_SM4_7
! 100 MHz to 500 MHz
!
# Hz S RI R SO
100000000 0.0061 0.0034 0.9920 -0.0497 0.9920 -0.0497 0.0058 0.0034
150000000 0.0071 0.0043 0.9894 -0.0737 0.9894 -0.0737 0.0064 0.0044
200000000 0.0082 0.0050 0.9862 -0.0975 0.9862 -0.0975 0.0070 0.0052
250000000 0.0094 0.0055 0.9825 -0.1210 0.9825 -0.1210 0.0075 0.0058
300000000 0.0105 0.0058 0.9783 -0.1443 0.9783 -0.1443 0.0079 0.0063
350000000 0.0117 0.0059 0.9737 -0.1674 0.9737 -0.1674 0.0082 0.0067
400000000 0.0129 0.0059 0.9685 -0.1903 0.9685 -0.1903 0.0083 0.0071
450000000 0.0141 0.0058 0.9629 -0.2130 0.9629 -0.2130 0.0083 0.0074
500000000 0.0153 0.0055 0.9568 -0.2355 0.9568 -0.2355 0.0082 0.0076
    
```

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Figure 4-7: 4-port Assignment Convention and Illustration of 2-port Touchstone Format

- Other models: upon request, it might be possible to provide other I/O models outside those outlined above. Xilinx is continuously reviewing formats and model delivery options, and will expand the above list as demand and practical needs of customers dictate. Following are some of the other models that can be supported on request.
 - SPICE sub-circuits: cover partial or all banks, distributed models, etc.
 - SSN models: models and simulations for simultaneous switching events depend on the I/O banks and number of nets considered. A full package model will be too complicated to generate and perhaps too unwieldy to use. The greater the number of ports, the more impractical it is to generate and verify such models. If there is a need for some reasonable n-port SSN model, please address this need through your FAE for review.
 - Power plane data and models: data for specific products will be supplied on request.
- For additional information about Xilinx electrical characterization methods and data, contact a local Xilinx field sales representative.

Further Explanations on Model Data and Terminology

The coupled RLC matrix IBIS format data contains three matrix definitions within the .pkg file.

- The R matrix section defines the series resistive component of each modeled signal path.
- The L matrix section provides both the self and mutual inductance values for each modeled signal path and the four most closely coupled neighbor paths. On files without coupling, the representation is similar to the resistance section.
- The C matrix provides the self and mutual capacitive coupling values for each modeled signal path as well as the four most strongly coupled neighbor paths. Note that the mutual capacitance values are negative since they are elements of a Maxwellian matrix (see below for a review of matrix formulations) where the off

diagonal terms are negative. The actual diagonal values and sign of the off-diagonal capacitances will be different from the corresponding nets in a spice deck. The following section explains the matrix formats.

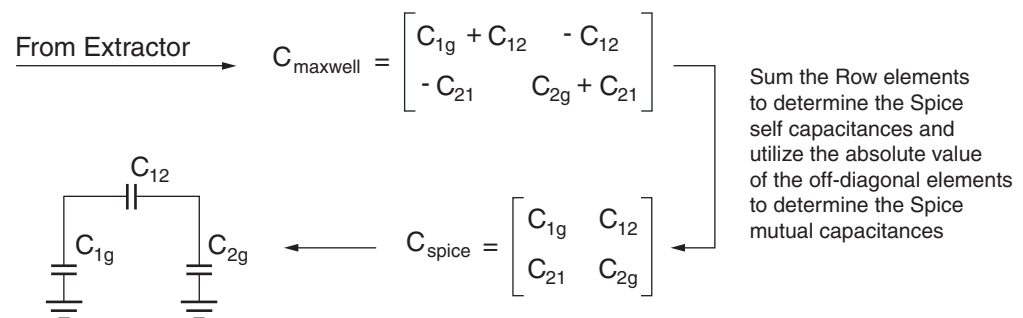
Capacitance Matrix formulations

When describing the RLC parasitics of a large package, it is convenient to utilize a matrix representation of the data. R and L data are quite straightforward to represent in a matrix. However, when it comes to capacitance, there is more than one option. Capacitance data is typically represented in the Maxwellian, Spice (or branch), and OCG (Other Conductors Grounded) matrix formats. Each of these formats has characteristics that make the format preferable for certain applications.

- **The Maxwellian format** is typically generated by field solvers. The main identifying feature of this format is that the off-diagonal terms are negative. This happens when the mutual capacitance terms are calculated in the solver by means of the relationship. When the matrix representation of the calculation is setup the off-diagonal C values are negative. These are the values presented in the Xilinx IBIS files.
- **The Spice matrix** formulation is particularly straightforward to utilize when describing a circuit topology in a nodal fashion as is done in spice. The mutual and self capacitance terms can be directly utilized as they appear in the matrix. Xilinx package Spice files already reflect the correct values.
- **The OCG format** arises from the way capacitance values are typically measured in the lab. All conductors in a package are grounded, except the ones that are being characterized. This causes the conductors under consideration to have somewhat greater capacitance to ground than they would otherwise.

In practical terms, users need not be concerned with using models, since the data elements are properly represented. However, awareness of the existence of these differences is important to avoid treating capacitance data for the same package in different models as potentially inconsistent. The guide below helps to understand the relationship among the formulations.

Figure 4-8 illustrates the relationship between Maxwellian and Spice formatted matrices for a 2 x 2 matrix. The corresponding OCG matrix (not shown) will be the same as the Maxwellian version with the data replaced with absolute value equivalents.



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Figure 4-8: Maxwellian and Spice-Formatted Matrices (2 x 2 matrix)

Figure 4-9 illustrates relationship numerically for a 2 x 2 matrix with mutual of 1, and $C_g = C_{2g} = 6$.

$$C_{\text{maxwell}} = \begin{bmatrix} 7 & -1 \\ -1 & 7 \end{bmatrix} \quad C_{\text{OCG}} = \begin{bmatrix} 7 & 1 \\ 1 & 7 \end{bmatrix} \quad C_{\text{spice}} = \begin{bmatrix} 6 & 1 \\ 1 & 6 \end{bmatrix}$$

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Figure 4-9: 2 x 2 Matrix

References

1. Eric Bogatin, *Signal Integrity - Simplified*, Prentice Hall 2004, ISBN 0-13-066946-6.
2. Brian Young, *Digital Signal Integrity*, Prentice Hall, ISBN 0140289043.
3. F. W. Grover, *Inductance Calculations: Working Formulas and Tables*, Instrument Society of America, 1945.
4. Stephen H. Hall, Garrett W. Hall & James A. McCall, *High-Speed Digital Systems Design: A handbook of interconnect theory and design practices*. John Wiley & Sons, 2000, ISBN 0-471-36090.

Recommended PCB Design Rules

Recommended PCB Design Rules for QFP Packages

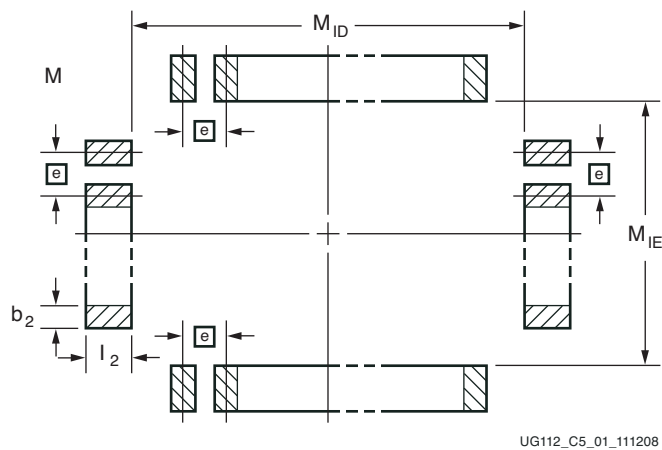


Figure 5-1: EIA Standard Board Layout of Soldered Pads for QFP Packages

Table 5-1: PCB Land Pad Dimensions for Xilinx Quad Flat Packs⁽¹⁾

Dim.	VQ44, VQG44	VQ64, VQG64	PQ100, PQG100	HQ160, HGG160, PQ160, PQG160	HQ208, HGG208, PQ208, PQG208	VQ100, VQG100, TQ100, TQG100	TQ144, TQG144	TQ176, TQG176	HQ240, HGG240, PQ240, PQG240	HQ304, HGG304
M_{ID}	9.80	9.80	20.40	28.40	28.20	13.80	19.80	23.80	32.20	40.20
M_{IE}	9.80	9.80	14.40	28.40	28.20	13.80	19.80	23.80	32.20	40.20
e	0.80	0.50	0.65	0.65	0.50	0.50	0.50	0.50	0.50	0.50
b_2	0.4-0.6	0.3-0.4	0.3-0.5	0.3-0.5	0.3-0.4	0.3-0.4	0.3-0.4	0.3-0.4	0.3-0.4	0.3-0.4
l_2	1.60	1.60	1.80 ⁽²⁾	1.80	1.60	1.60	1.60	1.60	1.60	1.60

Notes:

1. Dimensions in millimeters.
2. For 3.2 mm footprint per MS022, JEDEC Publication 95.

Recommended PCB Design Rules for TSOP/TSSOP Packages

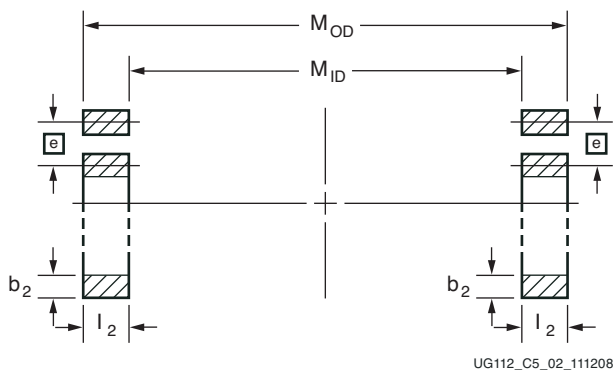


Figure 5-2: IPC Standard Board Layout of Soldered Pads for TSOP/TSSOP Packages

Table 5-2: Dimensions for Xilinx TSOP/TSSOP Packages (mm)

Dimension	VO20, VOG20	VO48, VOG48
M_{ID}	4.20 - 4.40	17.80 - 18.00
M_{OD}	7.20 - 7.40	20.80 - 21.00
e	0.65	0.50
b_2	0.40 - 0.50	0.30 - 0.40
l_2	1.50	1.50

Recommended PCB Design Rules for BGA, CSP, and CCGA Packages

The diameter of a land pad on the component side is provided by Xilinx. This information is required prior to the start of your board layout so you can design the board pads to match the component-side land geometry. The typical values of these land pads are described in [Figure 5-3](#) and summarized in [Table 5-3](#). for Xilinx BGA packages, non-solder mask defined (NSMD) pads on the board are suggested. This allows a clearance between the land metal (diameter L) and the solder mask opening (diameter M) as shown in [Figure 5-3](#). The space between the NSMD pad and the solder mask and the actual signal trace widths depends on the capability of the PCB vendor. The cost of the PCB is higher when the line width and spaces are smaller.

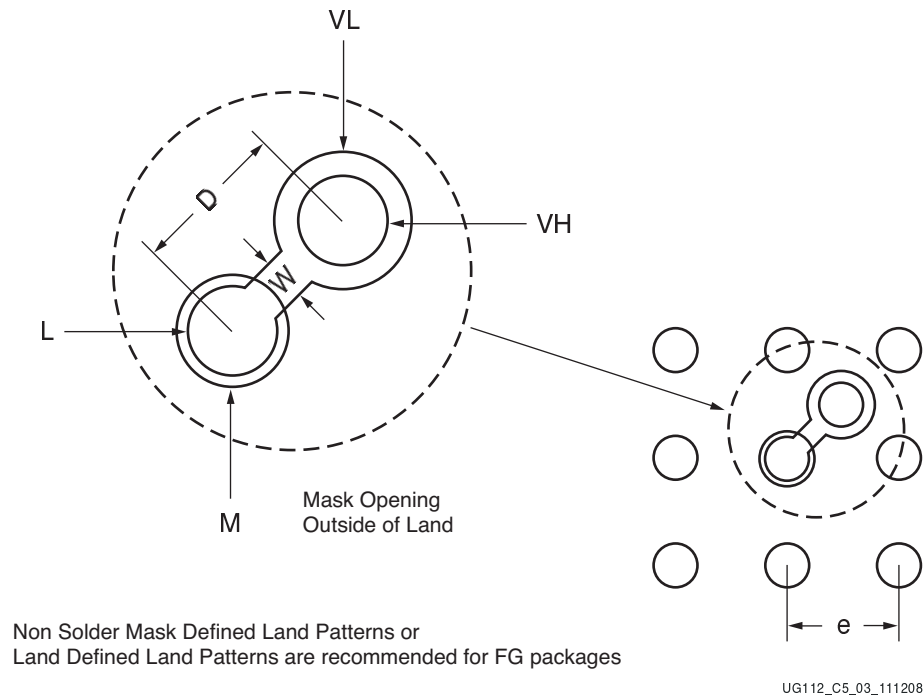


Figure 5-3: Suggested Board Layout of Soldered Pads for BGA, CSP, and CCGA Packages*

*3 x 3 matrix for illustration only, one land pad shown with via connection.

Table 5-3: Recommended PCB Design Rules (Dimensions in mm), Section 1

	FT64 FTG64	FT256 FTG256	FG256 FGG256 FG320 FGG320 FG324 FGG324	FG400 FGG400 FG456 FGG456 FG676 FGG676 FG484 FGG484	FG680 FGG680	FG860 FGG860	FG900 FGG900	FG1156 FGG1156	EF668 EF672 FF668 FFG668 FF672 FFG672 FF676 FFG676	FF896 EF1152 EF1704 FF1704 FF1148 FFG1148 FF1152 FFG1152	FF1513 FFG1513 FF1517 FFG1517	SF363 SFG363
Component land Pad Diameter (SMD) ⁽¹⁾	0.40	0.40	0.45	0.45	0.50	0.50	0.45	0.45	0.53	0.53	0.53	0.40
Solder Land (L) Diameter	0.40	0.40	0.40	0.40	0.40	0.40	0.40	0.40	0.45	0.45	0.45	0.33
Opening in Solder Mask (M) Diameter	0.50	0.50	0.50	0.50	0.50	0.50	0.50	0.50	0.55	0.55	0.55	0.50
Solder (Ball) Land Pitch (e)	1.00	1.00	1.00	1.00	1.00	1.00	1.00	1.00	1.00	1.00	1.00	0.80
Line Width Between Via and Land (w)	0.05 min.	0.13	0.13	0.13	0.13	0.13	0.13	0.13	0.13	0.13	0.13	0.13
Distance Between Via and Land (D)	0.35 min.	0.70	0.70	0.70	0.70	0.70	0.70	0.70	0.70	0.70	0.70	0.56
Via Land (VL) Diameter	0.30	0.61	0.61	0.61	0.61	0.61	0.61	0.61	0.61	0.61	0.61	0.50
Through Hole (VH) Diameter	0.15	0.300	0.300	0.300	0.300	0.300	0.300	0.300	0.300	0.300	0.300	0.300

Notes:

1. Component land pad diameter refers to the pad opening on the component side (solder mask defined).
2. FG456 package has solder balls in the center in addition to periphery rows of balls.
3. For Virtex-5 FPGA packages, refer to [UG195](#), *Virtex-5 FPGA Packaging and Pinout Specification*.

Table 5-4: Recommended PCB Design Rules (mm), Section 2

	BG225 BGG225	BG256 BGG256	BG352 BGG352	BG432 BGG432	BG560 BGG560	BG575 BGG575	BG728 BGG728	EF957 BF957 BFG957	CS48 CSG48 CS144 CSG144 CS280 CSG280	FS48 FSG48 CS484 CSG484	CP56 CPG56	CP132 CPG132
Component land pad diameter ⁽¹⁾ (SMD)	0.63	0.63	0.63	0.63	0.63	0.61	0.61	0.61	0.35	0.40	0.30	0.30
Solder land (L) diameter	0.58	0.58	0.58	0.58	0.58	0.56	0.56	0.56	0.33	0.37	0.27	0.27
Opening in solder mask (M) diameter	0.68	0.68	0.68	0.68	0.68	0.66	0.66	0.66	0.44	0.47	0.35	0.35

Table 5-4: Recommended PCB Design Rules (mm), Section 2 (Cont'd)

	BG225 BGG225	BG256 BGG256	BG352 BGG352	BG432 BGG432	BG560 BGG560	BG575 BGG575	BG728 BGG728	EF957 BF957 BFG957	CS48 CSG48 CS144 CSG144 CS280 CSG280	FS48 FSG48 CS484 CSG484	CP56 CPG56	CP132 CPG132
Solder (ball) land pitch (e)	1.50	1.27	1.27	1.27	1.27	1.27	1.27	1.27	0.80	0.80	0.50	0.50
Line width between via and land (w)	0.300	0.203	0.203	0.203	0.203	0.203	0.203	0.203	0.13	0.13	0.13	0.13
Distance between via and land (D)	1.06	0.90	0.90	0.90	0.90	0.90	0.90	0.90	0.56	0.56	0.35	0.35
Via land (VL) diameter	0.65	0.65	0.65	0.65	0.65	0.65	0.65	0.65	0.51	0.51	0.51	0.27
Through hole (VH) diameter	0.356	0.356	0.356	0.356	0.356	0.356	0.356	0.356	0.250	0.25	0.250	0.15

Note:

1. Component land pad diameter refers to the pad opening on the component side (solder mask defined).

Table 5-5: Recommended PCB Design Rules (mm), Section 3

	CG560	CG717	CF1140	CF1144	CF1509 CF1752
Component land pad diameter ⁽¹⁾ (SMD)	0.86	0.86	0.80	0.80	0.80
Solder land (L) diameter	0.80	0.80	0.70	0.70	0.70
Opening in solder mask (M) diameter	0.90	0.90	0.80	0.80	0.80
Solder (column) land pitch (e)	1.27	1.27	1.00	1.00	1.00
Line width between via and land (w)	0.30	0.30	0.20	0.20	0.20
Distance between via and land (D)	0.90	0.90	0.70	0.70	0.70
Via land (VL) diameter	0.65	0.65	0.46	0.46	0.46
Through hole (VH) diameter	0.305	0.305	0.200	0.200	0.200

Note:

1. Component land pad diameter refers to the pad opening on the component side (solder mask defined).

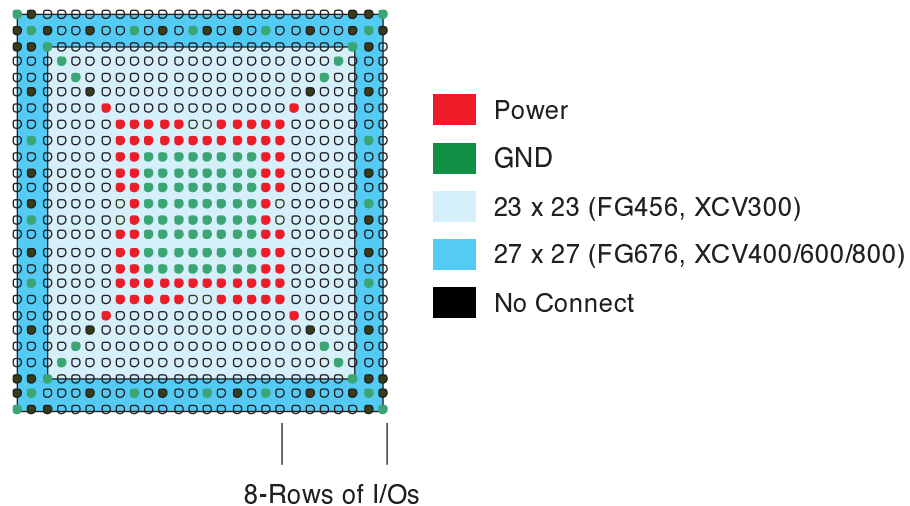
Board Routability Guidelines with Xilinx Fine-Pitch BGA Packages

Xilinx supplies full array fine-pitch BGA (Ball Grid Array) packages with 1.00 mm ball pitch. Successful and effective routing of these packages on PC boards is a significant challenge to designers. This application note provides board level routing guidelines for using Xilinx fine-pitch BGA packages. Specific examples are provided to choose appropriate routing schemes. These examples are based on package and board design rules for standard PCB technology and are not drawn to scale.

Board Level Routing Challenges

1.0 mm Ball Pitch, Fine-Pitch BGA

Xilinx fine-pitch BGA packages have a full matrix of solder balls (Figure 5-4). These packages are made of multilayer BT substrates. Signal balls are in a perimeter format extending up to eight rows in FG676 packages and up to ten rows in FG1156 packages. Power and ground pins are grouped together appropriately.



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Figure 5-4: Fine Pitch BGA Pin Assignments

The number of layers required for effective routing of fine-pitch BGA packages is dictated by the layout of pins on each package. If several other technologies and components are already present on the board, the system cost is factored with every added board layer. The intent of a board designer is to optimize the number of layers required considering both cost and performance. This application note provides guidelines to minimize the required board layers for routing fine-pitch BGA products using standard PCB technologies (5/5 mils lines/space or 6/6 mils lines/space).

For high performance and other system needs, designers can use premium technologies with finer lines/spaces on the board. The pin assignment and pin grouping scheme on full array fine-pitch BGA packages enables an efficient way of routing the board with an optimum number of required board layers.

Board Routing Strategy

Minimum Requirements

The diameter of a land pad on the component side is provided by Xilinx. This information is required prior to the start of the board layout to design the board pads to match the component side land geometry. The typical values of these land pads are described in Figure 5-4.

For FG series packages, NSMD (non-solder mask defined) pads on the board are suggested. This allows a clearance between the land metal (diameter L) and the solder mask opening (diameter M) as shown in Figure 5-3. The space between the NSMD pad and

the solder mask, and the actual signal trace widths depends on the capability of the PCB vendor. The cost of the PCB is higher when the line width and spaces are smaller.

Selection of the pad types and pad sizes determines the available space between adjacent balls for signal escape. Based on PCB capability, the number of lines that can share the available space is described in Figure 5-5. Based on geometrical considerations, if one signal escapes between adjacent balls, then two signal rows can be routed on a single metal layer. This is illustrated in Figure 5-5 as routing with one line/channel, either at 6 mils lines and spaces or 5 mils lines and spaces. Using this suggested routing scheme, a minimum of eight PCB layers are required to route 10 signal rows in a package.

A slightly lower trace width can be used by the inner signal rows routed in internal layers than the top and bottom external or exposed traces. Depending on the signal being handled, the practice of “necking down” a trace in the critical space between the BGA balls is allowable. Changes in width over very short distances can cause small impedance changes. Validate these issues with the board vendor and signal integrity engineers responsible for design.

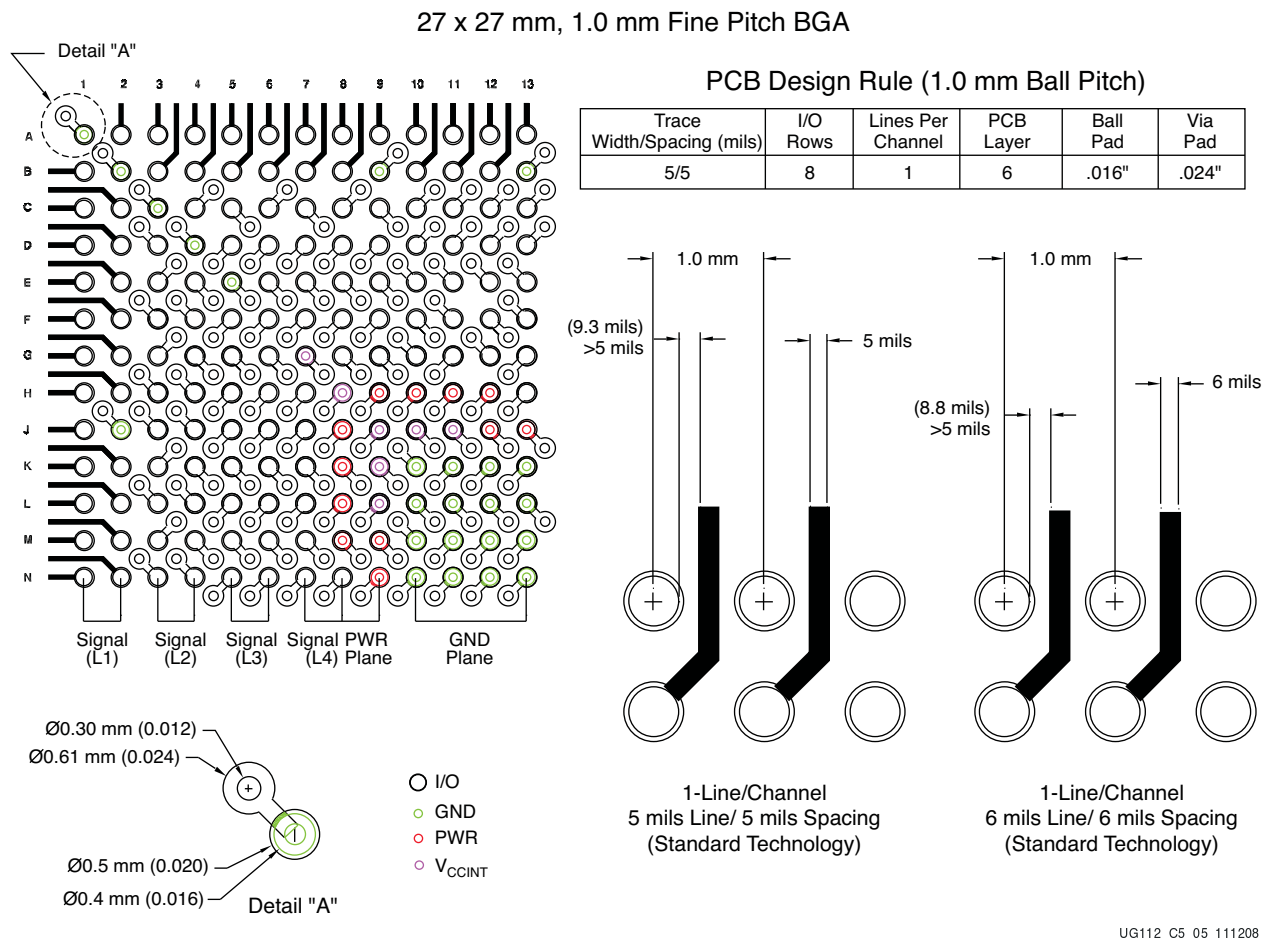


Figure 5-5: FG676 PC Board Layout/Land Pattern

Figure 5-5 describes a board-level layout strategy for a Xilinx 1.0 mm pitch FG676 package. Detail A in Figure 5-5 describes the opening geometry for the land pad and the solder mask. Routing with 5 mils lines/trace allows one signal per channel (between the balls). For successful routing, eight row deep signal traces require six PCB layers. Figure 5-6

shows the suggested schematic of layers for the six-layer routing scheme.

Using premium board technology such as Microvia Technology (allowing up to 4 mils lines and spaces) efficient routing is possible with a reduced number of board layers. A grouping scheme for power, ground, control and I/O pins, can also enable efficient routing.

Signal	L - 1
Power/Gnd	L - 2
Signal	L - 3
Signal	L - 4
Power/Gnd	L - 5
Signal	L - 6

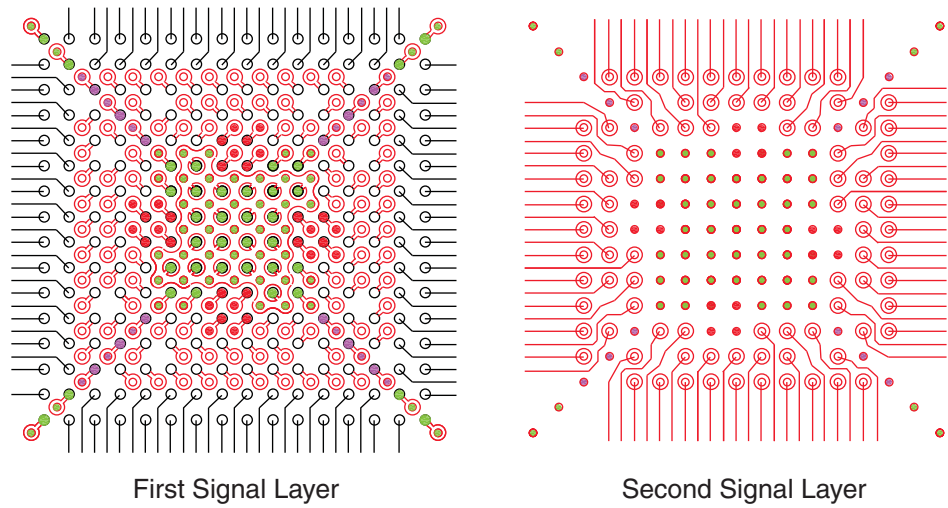
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Figure 5-6: **Six-Layer Routing Scheme**

Board Routing Examples

Figure 5-7 through Figure 5-11 offer examples of layer-by-layer board routing implementation using the rules outlined above for the Virtex®-E family of 1.0 mm BGA packages - FG256, FG456, FG676, FG900, and FG1156. The rule used assumes 5 mils lines and spaces. This is just an illustration of how the strategies outlined above can be used; it does not represent any specific implementation pin-out.

Similar board layout examples can be generated for other family (Virtex-II, Virtex-II Pro, etc.) pin-outs with the rules and strategies discussed in this section. It should be noted that the need to shield high-speed signals and meet Signal Integrity constraints might disrupt the plane sequence.

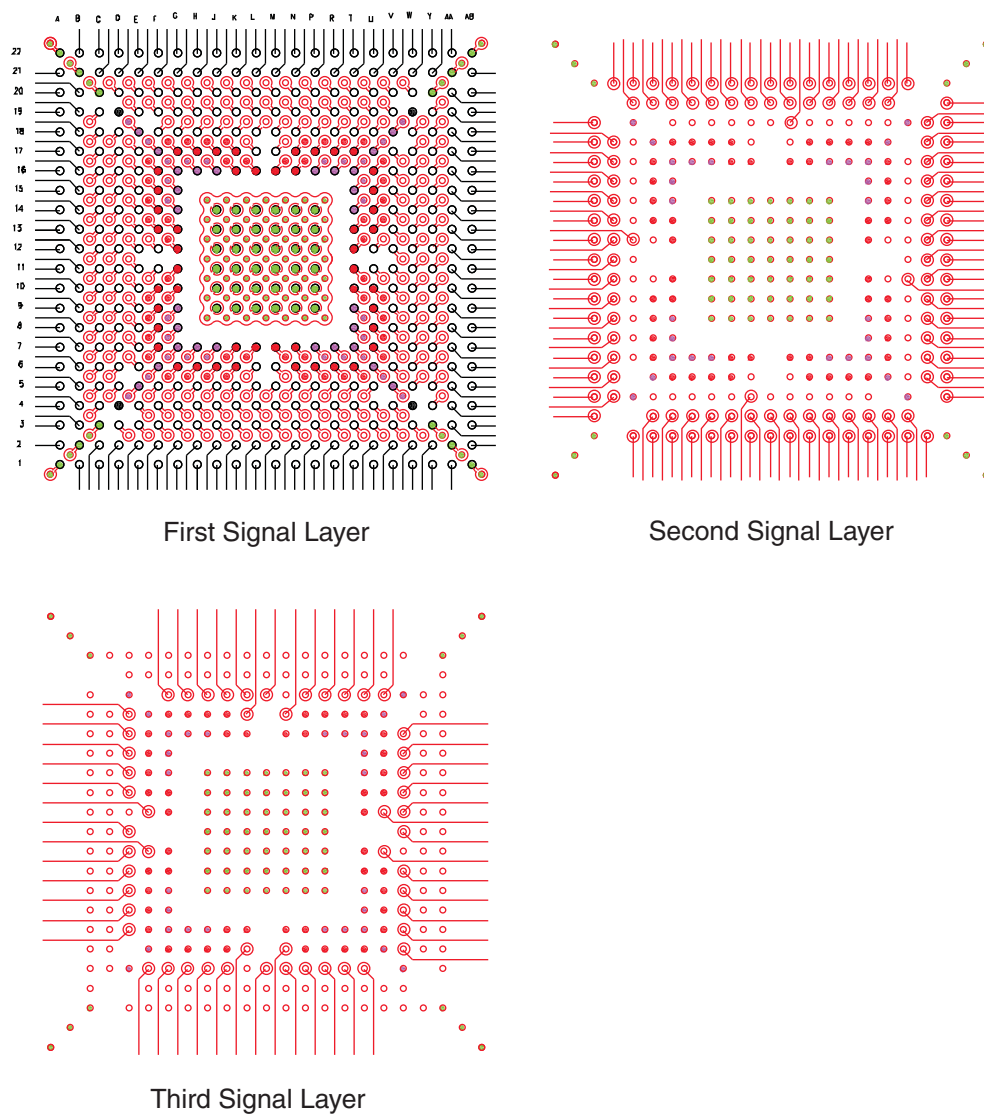


Notes:

- 1) Solder Land Diameter 0.4 mm Nonsolder Mask Defined
- 2) Solder Mask Opening Diameter 0.5 mm
- 3) Via Diameter 0.3 mm on 0.61 mm Diameter Via Land
- 4) Trace Width 0.127 mm

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Figure 5-7: XCV300E - FG256 NSMD Land Pad

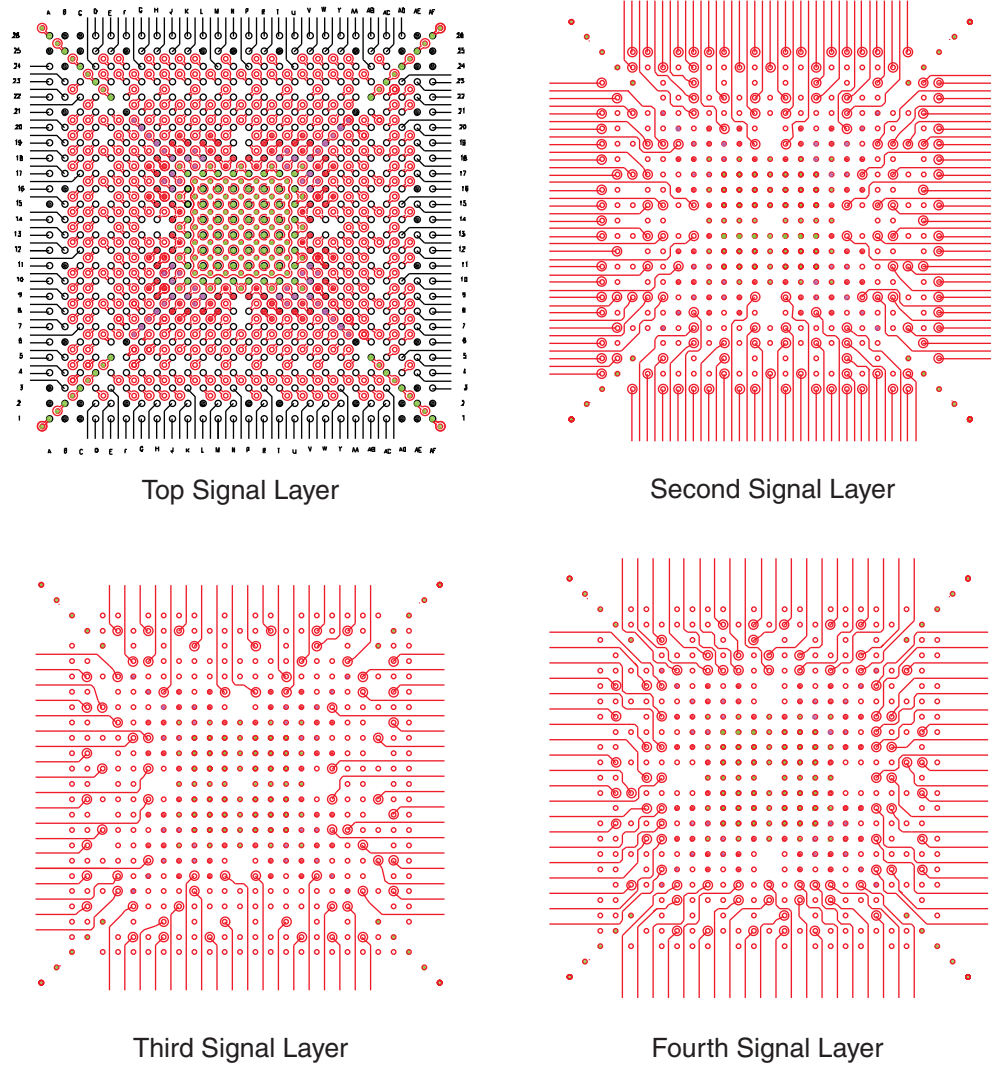


Notes:

- 1) Solder Land Diameter 0.4 mm Nonsolder Mask Defined
- 2) Solder Mask Opening 0.5 mm Diameter
- 3) Via Diameter 0.3 mm on 0.61 mm Diameter Via Land
- 4) All Layers Trace Width 0.127 mm

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Figure 5-8: XCV300E - FG456 NSMD Land Pad

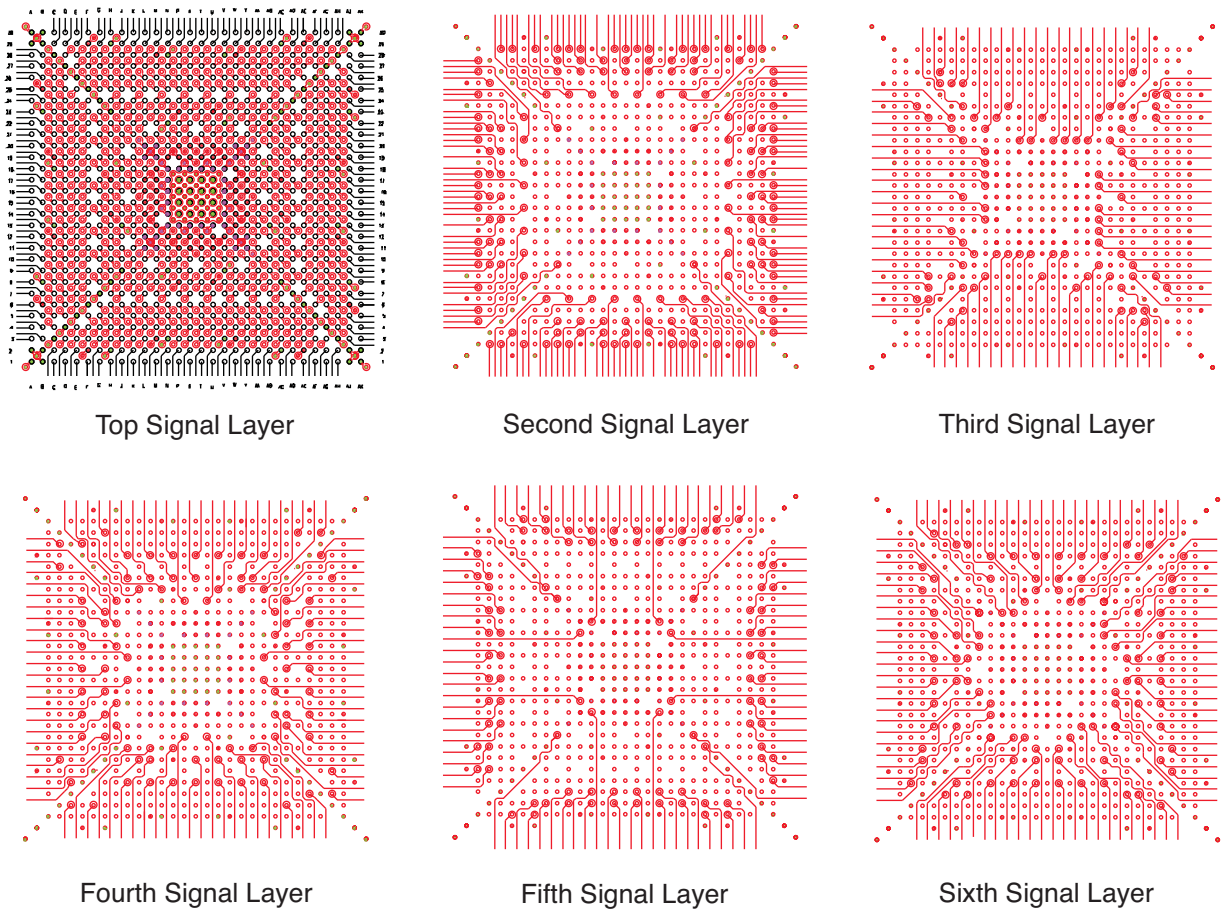


Notes:

- 1) Solder Land Diameter 0.4 mm Nonsolder Mask Defined
- 2) Solder Mask Opening Diameter 0.5 mm
- 3) Via Diameter 0.3 mm on 0.61 mm Diameter Via Land
- 4) Trace Width 0.127 mm

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Figure 5-9: XCV800 - FG676 NSMD Land Pad

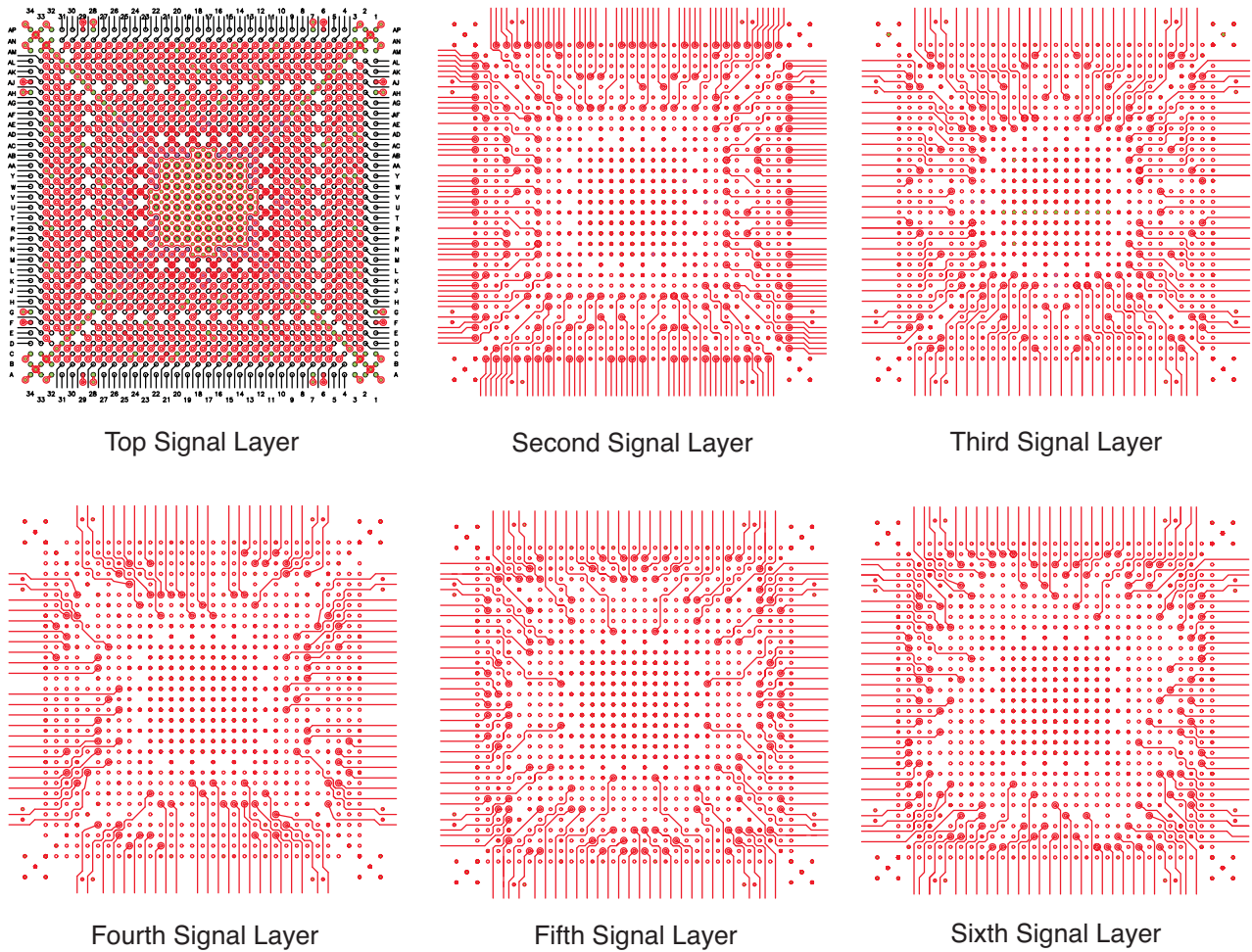


Notes:

- 1) Solder Land Diameter 0.4 mm Nonsolder Mask Defined
- 2) Solder Mask Opening Diameter 0.5 mm
- 3) Via Diameter 0.3 mm on 0.61 mm Diameter Via Land
- 4) Trace Width 0.127 mm

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Figure 5-10: XCV1600E - FG900 NSMD Solder Land Pad Layout



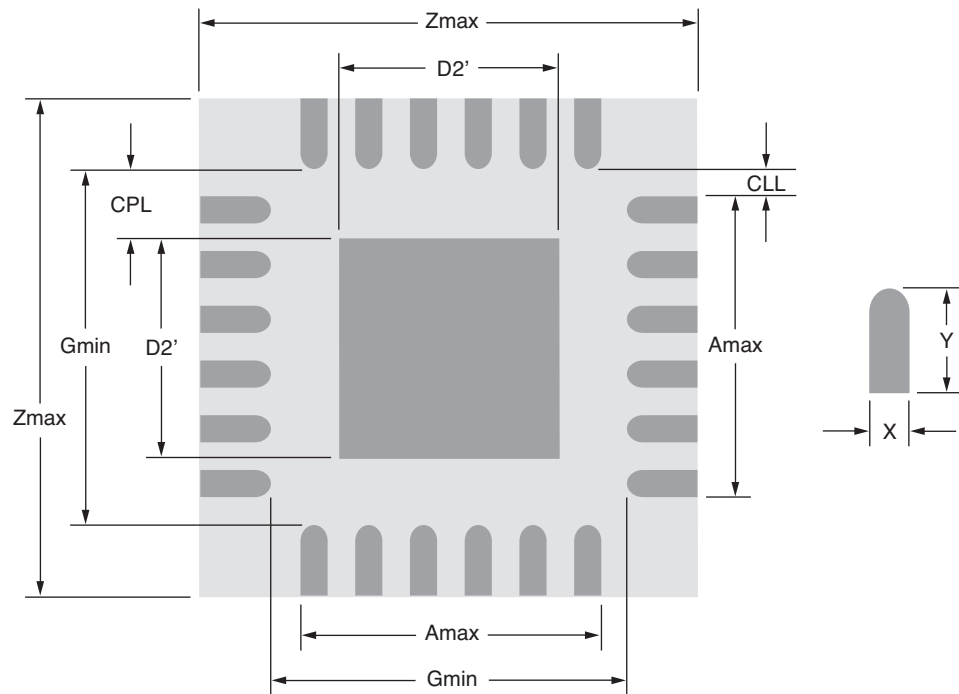
Notes:

- 1) Solder Land Diameter 0.4 mm Nonsolder Mask Defined
- 2) Solder Mask Opening Diameter 0.5 mm
- 3) Via Diameter 0.3 mm on 0.61 mm Diameter Via Land
- 4) All layers, Trace Width 0.127 mm

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Figure 5-11: XCV2000E - FG1156 NSMD Solder Land Pad Layout

Recommended PCB Design Rules for QFN Packages



UG112_C5_12_111208

Figure 5-12: IPC Standard Board Layout of Soldered Pads for QFN Packages

Table 5-6: Recommended PCB Land Pattern Dimensions (mm)

Package			PCB Land Pattern Dimensions							
Package	Body Size	Lead Pitch	Xmax	Yref	Amax	Gmin	Zmax	D2max	CLL ⁽¹⁾	CPL ⁽²⁾
QFG32	5 x 5	0.50	0.28	0.69	3.78	3.93	5.31	3.63	0.10	0.15
QFG48	7 x 7	0.50	0.28	0.69	5.78	5.93	7.31	5.63	0.10	0.15

1. CLL defines the minimum distance between land to land for the corner joints on adjacent sides.
2. CPL defines the minimum distance between the inner tip of the peripheral lands and the outer edge of the thermal pad.

PCB Pad Pattern Design and Surface-Mount Considerations for QFN Packages

Xilinx Quad Flat No-Lead (QFN) package is a robust and low profile leadframe-based plastic package that has several advantages over traditional leadframe packages. The exposed die attach paddle enables efficient thermal dissipation when directly soldered to the PCB. Additionally, this near chip scale package offers improved electrical performance, smaller package size, and an absence of external leads. Since the package has no external leads, coplanarity and bent leads are no longer a concern.

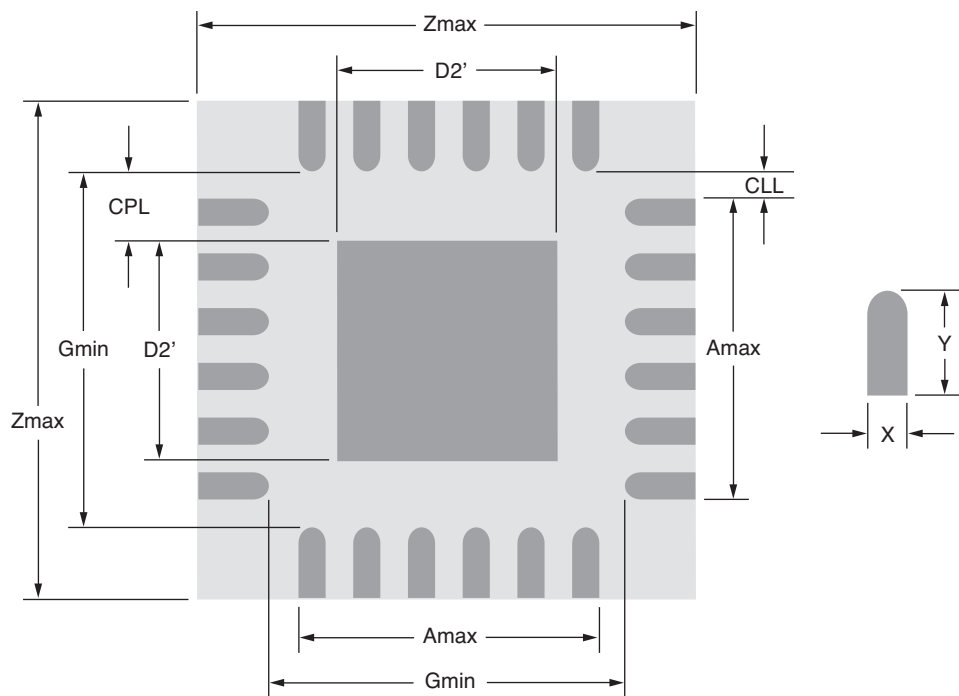
The exposed pads at the bottom of a QFN package can be used to enhance both electrical and thermal performance of the QFN component. To implement this, note that the exposed pad is a weak ground through its connection to the silicon. Under no circumstances should

the pad be connected to a positive or negative voltage. The paddle should only be left floating or connected to corresponding ground pad on the board. Ground pads incorporating thermal vias in them will significantly improve thermal performance, as shown in Figure 5-14.

The following factors have major effect on the quality and reliability of assembling QFN packages: PCB pad pattern design, amount of solder paste in thermal pad region, stencil design, type of solder paste, and reflow profile. This application note provides a good guideline on PCB pad pattern design and assembling of QFN packages for optimal reliability and quality. This is only a guideline and users are encouraged to perform actual studies to optimize the process.

PCB Pad Patterns

Figure 5-13 shows the PCB pad pattern dimensions to be determined. The dimension X and Y indicate the width and length of the pad. CLL and CPL define the clearances needed to avoid solder bridging. CLL defines the minimum distance between land to land for the corner joints on adjacent sides and CPL defines the minimum distance between the inner tip of the peripheral lands and the outer edge of the thermal pad. CLL should be 0.1 mm and CPL should be 0.15 mm.



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Figure 5-13: PCB Land Pattern Dimensions

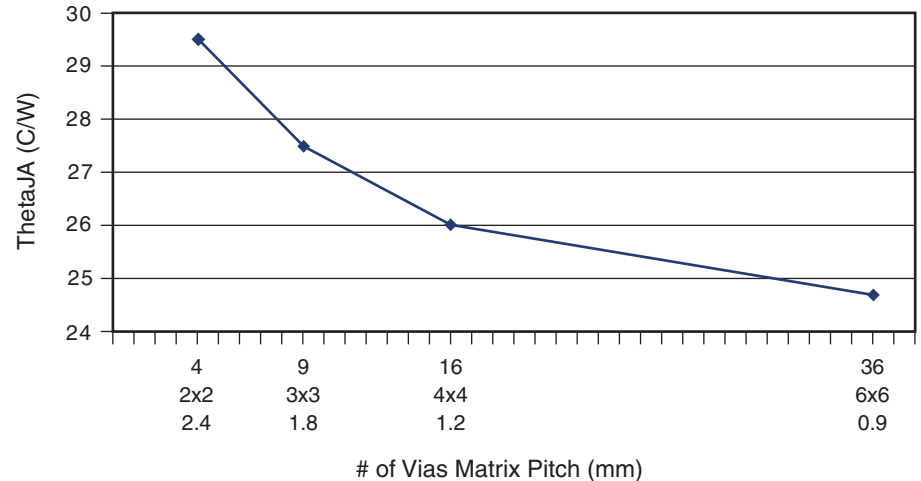
Tolerance analysis should be performed on the package and the PCB dimensions in order to design a proper pad pattern. The recommended PCB land pattern dimensions are shown in [Table 5-6](#).

Table 5-7: Recommended PCB Land Pattern Dimensions (all dimensions in mm)

Package			PCB Land Pattern Dimensions					
Package	Body Size	Lead Pitch	Xmax	Yref	Amax	Gmin	Zmax	D2max
QFG32	5 x 5	0.50	0.28	0.69	3.78	3.93	5.31	3.63
QFG48	7 x 7	0.50	0.28	0.69	5.78	5.93	7.31	5.63

Thermal Pad and Via Design

Typical deployment of a QFN package has a thermal resistance (θ_{ja}) of 35 – 45° C/watt (depending on package size). When needed, the base performance can be improved and a lower overall θ_{ja} is achieved by taking advantage of the exposed thermal pad feature. To take advantage of the exposed thermal pad under the package, the PCB should incorporate thermal pad and thermal vias. The thermal pad on the PCB acts as a solderable surface and the thermal vias provide a thermal path to the inner and/or bottom layers of the PCB to remove the heat. The number of thermal vias will depend on the following: application, power dissipation and electrical requirements. The thermal performance gets better as more thermal vias are added. However, there is a point of diminishing returns as shown in [Figure 5-14](#) where the effect of number of vias on θ_{ja} is plotted for a 7 mm, 48-lead package. A via diameter of 0.3 mm was used for this simulation.



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Figure 5-14: θ_{JA} vs. Number of Vias Graph

Based on the above and similar thermal simulations, it is recommended to incorporate an array of thermal vias that have pitch of 1.0 to 1.2 mm with via diameter of 0.3 to 0.33 mm.

Solder Masking Considerations

The PCB have pads that are either solder mask defined (SMD) or non solder mask defined (NSMD). NSMD pads are preferred over SMD pads since the copper etching process has tighter control than the solder masking process. Furthermore, NSMD pads with solder

mask opening larger than the metal pad size improves the reliability of the solder joints as solder is allowed to wrap around the sides of metal pads.

The solder mask opening should be larger than the pad size by 120 to 150 microns. This results in a clearance of 60 – 75 microns between the copper pad and the solder mask.

The thermal pad area can be solder mask defined in order to avoid any solder bridging between the thermal pad and the perimeter pads. The mask opening should be 100 microns smaller than the thermal land size on all four sides.

Stencil Design for Perimeter Pads

To achieve reliable solder joints, the solder joints on the perimeter pads should have about 50 to 75 microns standoff height and good side fillet on the outside. Good stand off can be achieved by having a stencil aperture opening that allows for maximum paste release. This is accomplished by having an area ratio that is greater than 0.66 and an aspect ratio that is greater than 1.5. Area Ratio and Aspect Ratio is defined below:

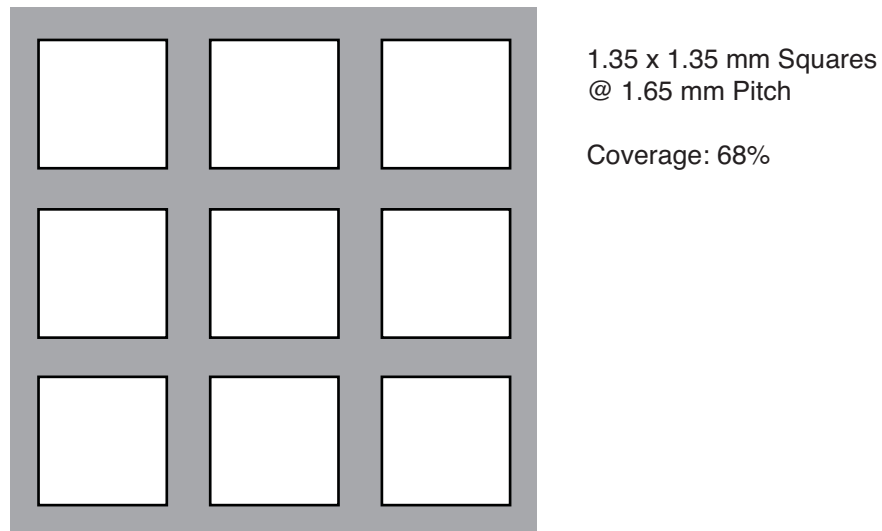
$$\text{Area Ratio} = LW / 2T(L+W)$$

$$\text{Aspect Ratio} = W/T$$

Where L and W are the aperture length and width, and T is the stencil thickness. The stencil aperture should have a 1:1 ratio with the PCB pad sizes as both area and aspect ratio targets can easily be achieved by this aperture. Also, the stencil should be laser cut and electro-polished.

Stencil Design for Thermal Pad

To enhance thermal and electrical performance, the die paddle should be soldered to the PCB thermal pad (see “[PCB Pad Pattern Design and Surface-Mount Considerations for QFN Packages](#),” page 98). Since outgassing occurs during reflow process and might cause defects such as splatter and solder balling, care must be taken to avoid large solder paste coverage. Thus, it is recommended to use smaller multiple openings in the stencil instead of one big opening for printing solder paste on the thermal pad area. By doing this, 50 to 80% solder paste coverage can be achieved. [Figure 5-15](#) below shows one way to achieve these levels of solder paste coverage.



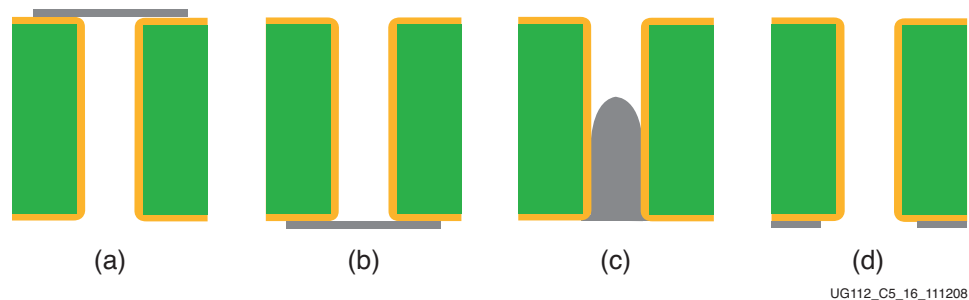
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Figure 5-15: Thermal Pad Stencil Design

Via Types and Solder Voiding

Voids in the thermal pad region are not expected to degrade thermal and electrical performance. However, large voids in the thermal pad area should be avoided. To control these voids, solder masking might be required for thermal vias to prevent solder wicking inside the via during reflow. Methods commonly used in the industry to control the voids include “via tenting” (top or bottom side) using dry film solder mask, “via plugging” with liquid photo-imageable (LPI) solder mask from the bottom side, or “via encroaching”.

[Figure 5-16](#) shows these options. For via tenting, the solder mask diameter should be 100 microns larger than the diameter of the via.



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Figure 5-16: Solder Mask Options for Thermal Vias: (a) Via Tenting from Top, (b) Via Tenting from Bottom, (c) Via Plugging from Bottom, and (d) Via Encroached from Bottom.

There are advantages/disadvantages to each of these options. Via tenting from the top side might result in smaller voids, but the presence of the solder mask on the top side of the board can hinder proper paste printing. Via tenting from the bottom and via plugging from the bottom might result in larger voids because of outgassing. Finally, encroached vias allow the solder to wick inside the vias and reduce the size of the voids. This option, however, results in lower standoff of the package.

Stencil Thickness and Solder Paste

For 0.5 mm pitch parts, a stencil thickness of 0.125 mm is recommended. Also, to improve the paste release, a stainless steel stencil with electro-polished trapezoidal walls is recommended.

For the paste, it is recommended to use “No Clean”, Type 3 paste. Since the pads on the package are plated with 100% matte Sn, the package can be soldered using either Pb-free or SnPb solder paste.

References

Application Notes for Surface Mount Assembly of Amkor’s MicroLeadFrame (MLF) Packages, Amkor Technology, www.amkor.com

Moisture Sensitivity of PSMCs

Moisture-Induced Cracking During Solder Reflow

The surface mount reflow processing step subjects the Plastic Surface Mount Components (PSMC) to high thermal exposure and chemicals from solder fluxes and cleaning fluids during board mount assembly. The plastic mold compounds used for device encapsulation are, universally, hygroscopic and absorb moisture at a level determined by storage environment and other factors. Entrapped moisture can vaporize during rapid heating in the solder reflow process generating internal hydrostatic pressure. Additional stress is added due to thermal mismatch, and the Thermal Coefficient of Expansion (TCE) of plastic, metal lead frame, and silicon die. The resultant pressure might be sufficient to cause delamination within the package, or worse, an internal or external crack in the plastic package. Cracks in the plastic package can allow high moisture penetration, inducing transport of ionic contaminants to the die surface and increasing the potential for early device failure. Cracks in the plastic package can also result in broken/lifted bond wires.

How the effects of moisture in plastic packages and the critical moisture content result in package damage or failure is a complex function of several variables. Among them are package construction details—materials, design, geometry, die size, encapsulant thickness, encapsulant properties, TCE, and the amount of moisture absorbed. The PSMC moisture sensitivity has, in addition to package cracking, been identified as a contributor to delamination-related package failure artifacts. These package failure artifacts include bond lifting and breaking, wire neckdown, bond cratering, die attach separation, and die passivation/metal breakage.

Because of the importance of the PSMC moisture sensitivity, both device suppliers and device users have ownership and responsibility. The background for present conditions, moisture sensitivity standardized test and handling procedures are published by two national organizations. Users and suppliers are urged to obtain copies of both documents (listed below) and use them rigorously. Xilinx adheres to both.

- IPC/JEDEC J-STD-020C
“Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.” Available on www.jedec.org website.
- IPC/JEDEC J-STD-033A
“Standard for Handling, Packing, Shipping, and Use of Moisture/Reflow Sensitive Surface Mount Devices.” Available on www.jedec.org website.

None of the previously stated or following recommendations apply to parts in a socketed application. For board mounted parts careful handling by the supplier and the user is vital. Each of the above publications has addressed the sensitivity issue and has established eight levels of sensitivity (based on the variables identified). A replication of those listings, including the preconditioning and test requirements, and

the factory floor life conditions for each level are outlined in Table 6-1. Xilinx devices are characterized to their proper level as listed. This information is conveyed to the user via special labeling on the Moisture Barrier Bag (MBB).

The moisture sensitivity level number, found in Table 6-1, is printed on the MBB prior to shipment. This establishes the user's factory floor life conditions as listed in the time column. The soak requirement is the test limit used by Xilinx to determine the level number. This time includes manufacturer's exposure time or the time it will take for Xilinx to bag the product after baking.

Table 6-1: Package Moisture Sensitivity Levels

Level	Floor Life		Soak Requirements ⁽¹⁾			
			Standard		Accelerated Equivalent ⁽²⁾	
	Time	Conditions	Time (hours)	Conditions	Time (hrs)	Conditions
1	Unlimited	≤30°C/85% RH	168 +5/-0	85°C/85% RH		
2	1 year	≤30°C/60% RH	168 +5/-0	85°C/60% RH		
2a	4 weeks	≤30°C/60% RH	696 ⁽³⁾ +5/-0	30°C/60% RH	120 +1/-0	60°C/60% RH
3	168 hours	≤30°C/60% RH	192 ⁽³⁾ +5/-0	30°C/60% RH	40 +1/-0	60°C/60% RH
4	72 hours	≤30°C/60% RH	96 ⁽³⁾ +2/-0	30°C/60% RH	20 +0.5/-0	60°C/60% RH
5	48 hours	≤30°C/60% RH	72 ⁽³⁾ +2/-0	30°C/60% RH	15 +0.5/-0	60°C/60% RH
5a	24 hours	≤30°C/60% RH	48 ⁽³⁾ +2/-0	30°C/60% RH	10 +0.5/-0	60°C/60% RH
6	Time on Label (TOL)	≤30°C/60% RH	TOL	30°C/60% RH		

Notes:

- Suppliers can extend the soak time at their own risk.
- CAUTION** The "accelerated equivalent" soak requirements shall not be used until correlation of damage response, including electrical, after soak and reflow is established with the "standard" soak requirements or if the known activation energy for diffusion is 0.4 - 0.48 eV. Accelerated soak times can vary depending on material properties; for example, mold compound, encapsulant, etc. JEDEC document JESD22-A120 provides a method for determining the diffusion coefficient.
- The standard soak time includes a default value of 24 hours for the semiconductor manufacturer's exposure time (MET) between bake and bag and includes the maximum time allowed out of the bag at the distributor's facility.
If the actual MET is less than 24 hours, the soak time can be reduced. For soak conditions of 30°C/60% RH, the soak time is reduced by one hour for each hour the MET is less than 24 hours. For soak conditions of 60°C/60% RH, the soak time is reduced by one hour for each five hours the MET is less than 24 hours.
If the actual MET is greater than 24 hours, the soak time must be increased. If soak conditions are 30°C/60% RH, the soak time is increased one hour for each hour that the actual MET exceeds 24 hours. If soak conditions are 60°C/60% RH, the soak time is increased one hour for each five hours that the actual MET exceeds 24 hours.

Factory Floor Life

Factory floor life conditions for Xilinx devices are clearly stated on the MBB containing moisture sensitive PSMCs. These conditions are ascertained by following test methods outlined in IPC/JEDEC J-STD-020C and are replicated in Table 6-1. If factory floor conditions are outside the stated environmental conditions (30°C/85% RH for Level 1, and 30°C/60% RH for Levels 2–6) or if time limits are exceeded, then recovery can be achieved by baking the devices before the reflow step. Identified in the next section are two acceptable bake schedules. Either can be used for recovery to the required factory floor level.

Dry Bake Recommendation and Dry Bag Policy

Xilinx recommends, as do the mentioned publications and other industry studies, that all moisture sensitive PSMCs be baked prior to use in surface mount applications, or comply strictly with requirements as specified on the MBB. Tape and Reeled parts are universally dry packed. Level 1 parts are shipped without the need for, or use of, an MBB. Note that to maintain level-1 status, the parts should be stored under conditions specified in [Table 6-1](#) ($\leq 30^{\circ}\text{C}/85\% \text{RH}$). Two bake schedules are identified as acceptable and equivalent. The first is 24 hours in air at 125°C , in shipping media capable of handling that temperature. The second bake schedule is for 192 hours in a controlled atmosphere of 40°C , equal to or less than 5% RH.

Dry Devices are sealed in special military specification Moisture Barrier Bags (MBB). Enough desiccant pouches are enclosed in the MBB to maintain contents at less than 10% RH for up to 12 months from the date of seal. A reversible Humidity Indicator Card (HIC) is enclosed to monitor the internal humidity level. The loaded bag is then sealed shut under a partial vacuum with an impulse heat sealer.

Artwork on the bags provides storage, handling and use information. There are areas to mark the seal date, quantity, and moisture sensitivity level and other information. The following paragraphs contain additional information on handling PSMCs.

Handling Parts in Sealed Bags

Inspection

Note the seal date and all other printed or hand entered notations. Review the content information against what was ordered. Thoroughly inspect for holes, tears, or punctures that might expose contents. Xilinx strongly recommends that the MBB remain closed until it reaches the actual work station where the parts will be removed from the factory shipping form.

Storage

The sealed MBB should be stored, unopened, in an environment of not more than 90% RH and 40°C . The enclosed HIC is the only verification to show if the parts are exposed to moisture. Nothing in the part's appearance can verify moisture levels.

Expiration Date

The seal date is indicated on the MBB. The expiration date for dry packed SMD packages is 12 months from the seal date. If the expiration date has been exceeded or HIC shows exposure beyond 10% upon opening the bag bake the devices per the earlier stated bake schedules. The three following options apply after baking:

Use the devices within time limits stated on the MBB.

Reseal the parts completely under a partial vacuum with an impulse sealer (hot bar sealer) in an approved MBB within 12 hours, using fresh desiccant and HIC, and label accordingly. Partial closures using staples, plastic tape, or cloth tape are unacceptable.

Store the out-of-bag devices in a controlled atmosphere at less than 10% RH. A desiccator cabinet with controlled dry air or dry nitrogen is ideal.

Other Conditions

Open the MBB when parts are to be used. Open the bag by cutting across the top as close to the seal as possible. This provides room for possible resealing and adhering to the reseal conditions outlined above. After opening, strictly adhere to factory floor life conditions to ensure that devices are maintained below critical moisture levels.

Bags opened for less than one hour (strongly dependent on environment) can be resealed with the original desiccant. If the bag is not resealed immediately, new desiccant or the old one that has been dried out can be used to reseal, if the factory floor life has not been exceeded. Note that factory floor life is cumulative. Any period of time when MBB is opened must be added to all other opened periods.

Both the desiccant pouches and the HIC are reversible. Restoration to dry condition is accomplished by baking at 125°C for 10-16 hours, depending on oven loading conditions.

Assigned Package MSL

Table 6-2 depicts the typical MSL for various classes of Xilinx packages. Moisture level information will generally follow these MSL numbers for most products. Note that specific MSL information is always printed on the Moisture Barrier Bag (MBB) in which the components are shipped. The MSL printed on the MBB takes precedence over these typical values depicted in this table for a general overview.

Table 6-2: Package MSL

Package Family	Description	Typical MSL
BF/BFG, FF/FFG, SF/SFG	Flip chip, FCBGA	4
BG/BGG	Ball Grid Array	3
CS/CSG, CP/CPG, QF/QFG, FS48/FSG48	Chipscale packages	3
FG/FGG, FT/FTG	Fine Ball Grid Array	3
HQ/HQG, HT/HTG	Heat enhanced QFPs	3
PC/PCG	PLCC packages	3
PD/PDG	Plastic Dual In Line	1
PQ/PQG, TQ/TQG, VQ/VQG	Plastic Quad Flat Packages	3
SO/SOG	SOIC packages	1
VO8, VO20/VOG20, VO24/VOG24	TSSOP	1
VOG8, VO48/VOG48	TSSOP	3
CG1156/CGG1156	Hi TEC ceramic	3

Table 6-2: Package MSL (Cont'd)

Package Family	Description	Typical MSL
CB/CBG, CC/CCG, CD/CDG, CF/CFG, CG560/CGG560, CG717/CGG717, DD8/DDG8, PG/PGG (all), WC/WCG	Ceramic Based packages - Not PSMC	Not sensitive - 1*

Notes:

* Not PSMC component, not sensitive to moisture.

Reflow Soldering Process Guidelines

Solder Reflow Process

Note: Xilinx recommends that customers qualify their custom PCB assembly processes using package samples. For more information, refer to the section on “[Package Samples](#)” in [Chapter 1](#).

The IR process is strongly dependent on equipment and loading differences. Components might overheat due to lack of thermal constraints. Unbalanced loading can lead to significant temperature variation on the board. This guideline is intended to assist users in avoiding damage to the components; the actual profile should be determined by those using these guidelines. For complete information on package moisture / reflow classification and package reflow conditions, refer to the Joint IPC/JEDEC Standard J-STD-020C.

To implement and control the production of surface-mount assemblies, the dynamics of the solder reflow process and how each element of the process is related to the end result must be thoroughly understood.

The primary phases of the reflow process are as follows:

1. Melting the particles in the solder paste
2. Wetting the surfaces to be joined
3. Solidifying the solder into a strong metallurgical bond

The sequence of five actions that occur during this process is shown in [Figure 7-1](#). The profile below reflects the soldering sequences for Sn/Pb soldering system. For the Pb-free soldering system, the sequences are the same. However, for the Pb-free soldering system, higher reflow temperature is applied.

For reflow and rework guidelines on Pb-free packages, refer to [XAPP427](#), *Implementation and Solder Reflow Guidelines for Pb-Free Packages*, and for flip-chip packages refer to [XAPP426](#), *Implementing Xilinx Flip-Chip BGA Packages*.

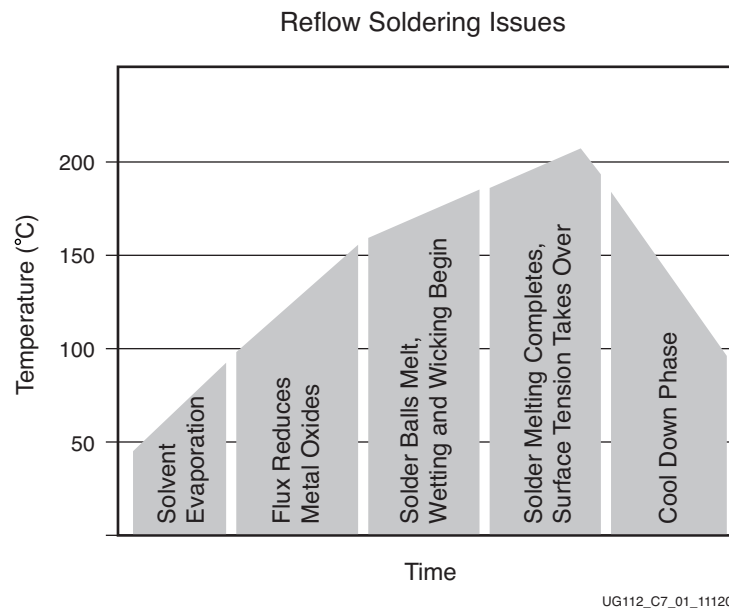


Figure 7-1: Soldering Sequence

Package Peak Reflow Temperature

The peak reflow temperature of the PSMC body should not be more than 225°C (240°C for VQ44, VQ64, VQ100) for standard packages and 245-260°C for Pb-free package (package size dependent). For multiple BGAs in a single board, it is recommended to check all BGA sites for varying temperatures because of differences in surrounding components.

Soldering Problems Summary

Each phase of a surface mount reflow profile has min/max limits that should be viewed as a process window. The process requires a careful selection and control of the materials, geometries of the mating surfaces (package footprint vs. PCB land pattern geometries) and the time/temperature of the profile. If all of the factors of the process are sufficiently optimized, there will be good solder wetting and fillet formation (between component leads and the land patterns on the substrate). If factors are not matched and optimized there can be potential problems as summarized in [Figure 7-2](#).

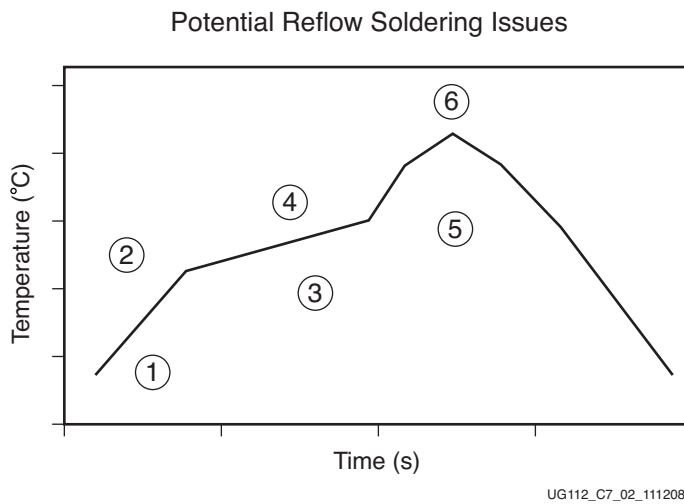


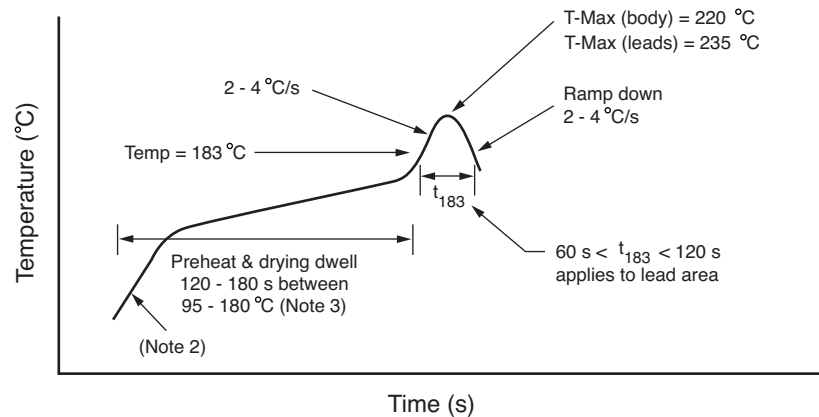
Figure 7-2: Soldering Problems Summary

Soldering problems summary notes:

1. Insufficient temperature to evaporate solvent
2. Component shock and solder splatter
3. Insufficient flux activation
4. Excessive flux activity and oxidation
5. Trapping of solvent and flux, void formation
6. Component and/or board damage

Typical Conditions for IR Reflow Soldering

[Figure 7-3](#) shows typical conditions for solder reflow processing of Sn/Pb soldering using IR/Convection. Both IR and Convection furnaces are used for BGA assembly. The moisture sensitivity of Plastic Surface-Mount Components (PSMCs) must be verified prior to surface mount flow. See the preceding sections for a more complete discussion on PSMC moisture sensitivity.



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Figure 7-3: Typical Conditions for IR Reflow Soldering of Sn/Pb Solder

Note:

1. Max temperature range = 220°C (body). Minimum temperature range before 205°C (leads/balls).
2. Preheat drying transition rate 2-4°C/seconds
3. Preheat dwell 95-180°C for 120-180 seconds
4. IR reflow shall be performed on dry packages
5. For MPM BGAs, do not reflow with lid on bottom

Implementing and Optimizing Solder Reflow Process for BGA Packages

Xilinx flip-chip BGA package is offered for Xilinx high-performance FPGA products. Unlike traditional packaging in which the die is attached to the substrate face-up and the connection is made by using wire, the solder bumped die in flip-chip BGA is flipped over and placed face-down, with the conductive bumps connecting directly to the matching metal pads on the laminate substrate.

The primary purpose of solder reflow process is to wet the surfaces to be joined to form a strong metallurgical bond between the component and the PC board.

While the fundamentals of solder reflow process is the same for most applications, careful considerations must be taken for some of the larger and heavier BGA packages.

One of the most significant variables that can affect the package warpage is the solder reflow process. This application note discusses the details of the solder reflow process and provides guidelines on profiling to achieve successful reflow of BGA components.

Reflow Ovens

Full convection ovens are preferred method for BGA assembly. Convection ovens provide more uniform heating and efficient heating across the board and the components. Convection ovens are especially recommended for applications that have a high mixture of components and densely populated boards.

Reflow Process

During the reflow process, the components undergo reflow soldering phases, as shown in [Figure 7-1](#).

As the components go through the five phases ([Figure 7-1](#)) in the oven, several actions take place to prepare a “clean” metal surface suitable for wetting and melting the solder, react with the interfaces, and solidify the solder onto the board. A typical profile with recommended settings for key parameters is shown in [Figure 7-1](#). A graphical representation of the typical profile can be found in [Figure 7-5](#).

Table 7-1: Process Window for Convection Oven

Process Steps	Process Description	Process Window
Preheat	Ramp rate Peak temperature in preheat	1–3°C/second 100°C–150°C
Preflow	Solder paste activation Soak time	120°C–170°C 60–120 seconds
Reflow	Time above 183°C Peak Reflow temperature Component body temperature	60–120 seconds 200°C–210°C 220°C Max
Cool down	Cooling rate	1–3°C/second

Methods of Measuring Profiles

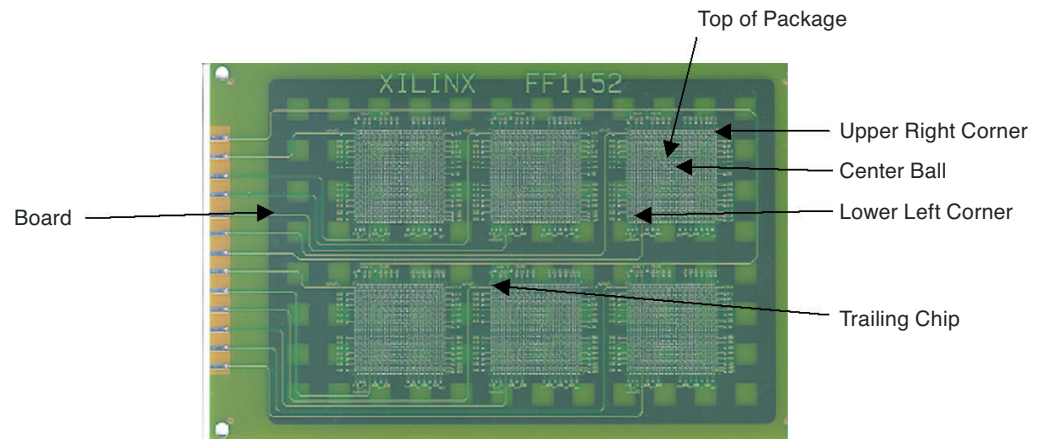
It is important to ensure that proper placement/attachment of thermocouples is carried out in order to accurately measure the desired temperatures. Thermocouples can be attached using either conductive epoxy or high temperature solders. Perhaps the easiest method to attach the thermocouple is by drilling through the pad of the PC board and attaching the thermocouple from the bottom of the PCB directly to the solder ball of the component.

Measurements should be taken at the following locations: center of the solder joint area of the component, the corner of the solder joint area of the component, the top surface of the component, and other components and locations on the PCB.

Reflow Profiling

An optimized profile is paramount in achieving successful reflow result. A good starting point is to refer to the solder paste manufacturer’s suggested reflow profile. However, solder paste manufacturers only supply the basic time/temperature duration information. To get an optimized reflow, components and board characteristics should dictate the maximum temperature and proper ramp rate.

Profiles should be established for all new board designs using thermocouples at multiple locations on the component (top, bottom, and corners-see [Figure 7-4](#)). In addition, if there are mixture of devices on the board, then the profile should be checked at different locations on the board to ensure that the minimum reflow temperature is reached to reflow the larger components and at the same time, the temperature does not exceed the threshold temperature that might damage the smaller, heat sensitive components. The minimum reflow temperature is the ideal thermal level at which the solder balls can be wetted to form the solder joints.



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Figure 7-4: Temperature Measurement Locations

This information is usually provided by the solder paste manufacturers and it is typically 15-20°C above the solder's melting point. For eutectic (Sn63Pb37) solder, it is around 205-215°C.

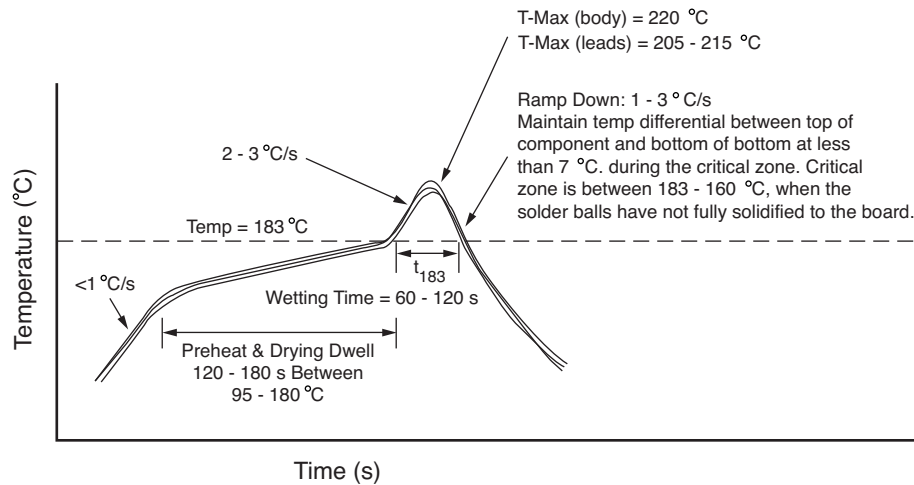
It is critical to keep the temperature gradient across the board as minimal as possible (maintain less than 10°C) to prevent warpage of the components and the board. This is accomplished by using a slower rate in the warm-up and preheating stages. A heating rate of less than 1°C/second during the initial stage, in combination with a heating rate of not more than 3°C/second throughout the rest of the profile is recommended.

Aside from the board, it is also important to minimize the temperature gradient on the component, between top surface and bottom side, especially during the cool down phase. In fact, cooling is a crucial part of the reflow process and must be optimized accordingly. While a slow cooling rate might result in high assembly yields, it could lead to formation of thick intermetallic layers with large grain size; thereby, reducing the solder joint strength.

On the other hand, faster cooling rate leads to smaller solder joint grain size and hence resulting in higher solder joint fatigue resistance. However, overly aggressive cooling on stiff packages with large thermal mass such as flip-chip BGAs can lead to cracking or package warpage, caused by the differential cooling effects between the top surface and bottom side of the component and between the component and the PCB materials.

The key is to have an optimized cooling with minimal temperature differential between the top surface of the package and the solder joint area. The temperature differential between the top surface of the component and the solder joint area should be as minimal as possible, preferably below 7°C during the critical region of the cool down phase of the reflow process. This critical region occurs at the phase in which the balls are not completely solidified to the board yet, usually between the 180°C and down to 160°C range. The best solution might be to divide the cooling section into multiple zones, with each zone operating at different temperatures to efficiently cool the parts. For a graphical representation of the typical reflow conditions for BGA, see [Figure 7-5](#).

If second pass wave solder reflow is performed on the same board as BGAs, insure that the solder wafer profile is tightly controlled and consider shielding the BGA parts. The wave solder temperature profile can warp the board and break the solder joints on the topside of the BGA component



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Figure 7-5: Typical Solder Reflow Profile for BGA

Post Reflow Washing

Most major PCB assembly subcontractors today have successfully developed the no-clean process in which post assembly washing is not required. That would be an ideal process. If cleaning is required as part of the process, then it is recommended to use a water soluble paste and then wash with deionized water in a washer, such as a Westek Triton III at 140°F - 145°F . A post-wash bake is also required to ensure the package has been completely dried from the wash.

Except for EF packages, cleaning solutions or solvents are not recommended because some cleaning solutions might contain chemicals that can attack the heatspreader adhesive, thermal compound, or components inside the package.

Reworking Flip-Chip BGAs

Since the devices packaged in a flip-chip BGA package are typically high performance and high priced devices, it is essential that proper procedures are followed to ensure successful rework of flip-chip BGAs.

Pre-Baking

As the printed circuit board and the BGA packages are quite moisture sensitive, one should always bake the PCBs and the BGA devices prior to any rework operations. The recommended temperature and duration is 125°C for at least four hours.

BGA Removal

An accurate thermal profile needs to be established for the component removal process. This will determine the exposure duration and the maximum component/board temperatures. The profile should be adapted to each board and component to be removed. Although the typical profile should provide a peak temperature between 205 to 215°C (at the solder joint) for a maximum of 75 seconds, it is best, however, to consult with equipment manufacturer for the recommended profile.

Research has also indicated that a short delta T and a short dwell time above 183°C are preferred to minimize intermetallic growth and control board warpage. Also of importance is a need to assure that the component and the board are not overheated, and that all balls are reflowed on the specific component being removed. In general, preheat the entire board to a minimum of 85°C to avoid large temperature differentials and potential board warpage.

In terms of the equipment and tools available, automatic hot gas rework systems with vacuum suction are recommended. The nozzle should be designed such that most of the heat is applied at the solder joint area and not on the package. Excess heat can cause the lid attach epoxy to soften, which can cause the lid to come off. Apply heat from the topside using the rework profile developed (ramp the temperature for 45-60 seconds with a maximum temperature between 205-215°C). When the solder balls are fully liquidus, remove the component using a vacuum tip. Do not attempt to remove partially reflowed component from a board by prying it off, as this would likely damage the component and can cause the lid to come off.

Note: To avoid package delamination, the temperature at the top of the package must not exceed 225°C (245°C, 250°C, or 260°C for Pb-free flip-chip BGA packages, depending on package size).

Site Preparation

The excess solder that remains on the board can be removed using a vacuum desoldering system or a soldering iron with a solder wick. Special care must be taken to avoid damaging the solder mask material and the solder pads. As a final step, alcohol can be used with a brush to clean the rework area. Allow the board to dry and inspect to ensure a clean solderable surface. The specific steps used here might be different from board to board and from company to company. As a minimum, the removal of the excess solder is an essential requirement.

Solder Paste Application

There are several options available to apply the solder paste to the component site. The BGA package itself can be screened with paste prior to placement. In addition, the site can receive solder paste with a dispensing method. Finally the application of flux to a prepared pre-tinned site can produce acceptable results in most situations.

BGA Placement and Reflow

The next step is to replace the component on the board. The replacement component should be baked prior to assembly if the component has been exposed to the environment for more than the allotted time. Place the component on the site, observing all the alignment precautions. Reflow the balls using hot air in a manner similar to the removal process. Again observe total board temperature to avoid any thermal gradients that can result in board warpage. It is recommended to heat the PCB from the underside to a given temperature (depending on the board size and properties), preferably in the 80°C-145°C range.

Heating the underside of the board can help to minimize the temperature gradient on the board.

Additionally, larger BGA components such as flip-chip BGAs are quite sensitive to heat; therefore, extra precautions are necessary to ensure successful result. It is critical to minimize the temperature gradient on the part. High temperature gradient will create thermal shock that leads to package warpage. The temperature delta between the following locations should be 7°C or less: the solder balls on the corners, the solder balls at

the center of the package, and the top surface side of the package. To achieve minimal temperature gradient, a slower ramp up rate (0.5°C/second) and a lower peak reflow temperature (200°C as measured at the solder balls) is recommended. Additionally, cooling should be optimized to minimize the temperature differential as described under the Reflow Profiling, page 4.

BGA Reballing

Xilinx does not recommend reballing. Xilinx parts that are reballled will not be guaranteed by Xilinx. A maximum of three reflow cycles are allowed.

Conformal Coating

Xilinx has no experience or reliability data on flip-chip BGA packages on board after exposure to conformal coating. It is recommended that the end-user should characterize the board level reliability performance of Xilinx packages before production use.

Post Assembly Handling

When assembling mechanical connectors or fixtures to the PB board, users should be careful not to create excessive bowing or flexing on the PB board as this might weaken or cause damage to the solder joints interface.

Heat Sink Removal Procedure

The heatspreader on the package provides mechanical protection for the die and serves as the primary heat dissipation path. It is attached with an epoxy adhesive to provide the necessary adhesion strength to hold the package together. For an application in which an external heatsink subjects the lid adhesion joint to continuous tension or shear, extra support might be required.

In addition, if the removal of an attached external heat sink subjects the joint to tension, torque, or shear, care should be exercised to ensure that the lid itself does not come off. In such cases, it has been found useful to use a small metal blade or metal wire to break the lid to heatsink joint from the corners and carefully pry the heatsink off. The initial cut should reach far in enough so that the blade has leverage to exert upward pressure against the heat sink. Please contact the heat sink and heat sink adhesive manufacturer for more specific recommendations on heat sink removal.

Package Pressure Handling Capacity

For mounted BGA packages, including flip chips, a direct compressive (non-varying) force applied normally to the lid or top of package with a tool head that coincides with the lid (or is slightly bigger) will not induce mechanical damage to the device including external balls, provided the force is not over 5.0 grams per external ball, and the device and board are supported to prevent any flexing or bowing.

These components are tested in sockets with loads in the 5 to 10 grams/ball range for short durations. Analysis using a 10g/ball (e.g., 10 kg for FF1148) showed little impact on short-term but some creep over time. 20 grams/ball and 45 grams/ball loads at 85°C over a six week period has shown the beginning of bridging of some outer balls; these were static load tests. The component might survive forces greater than the 5 gram limit while in short-term situations. However, sustained higher loads should be avoided (particularly if they are overlaid with thermal or power cycle loads). Within the recommended limits,

circuit board needs to be properly supported to prevent any flexing resulting from force application. Any flexing or bowing resulting from such a force can likely damage the package-to-board connections. Besides the damage that can occur from bending, the only major concern is long-term creep and bulging of the solder balls in compression to cause bridging. For the life of a part, staying below the recommended limit will ensure against that remote possibility.

References

1. Adams, Jeff, "Xilinx FF1152 Assembly Report", March 27, 2001, Samina Corporation.
2. Gilleo, Ken, "Area Array Packaging Handbook", copyrighted 2002 by McGraw-Hill Co., pages 14.14-14.16.
3. Hall, James, "Concentrating on Reflow's Cooling Zones", EP&P, 3/01/2001
4. Narrow, Phil, "Soldering", SMT Magazine, Aug. 2000
5. O'Donnell, Dennis, "BGA Rework Practices", Precision PCB Services Inc., 2001

QFN Reflow Profile

Reflow profile for QFN packages is similar to reflow profile of other SMT packages. It is recommended to follow the paste manufacturer's specification on peak reflow temperature, soak times, time above liquidus, and ramp rates. Typical profile for Sn/Pb solder paste has a peak temperature between 220-235°C with time above liquidus between 60-90 seconds.

Additional Information

Table of Socket Manufacturers

Table A-1 lists manufacturers known to offer sockets for Xilinx Package types. This summary does not imply an endorsement by Xilinx. Each user has the responsibility to evaluate and approve a particular socket manufacturer.

Table A-1: Socket Manufacturers Packages

Manufacturer	Packages					
	DIP, SO, VO	PC, WC	PQ, HQ, TQ, VQ	PG, PP	CB	BG, CG
Advanced Interconnect 5 Energy Way, P.O. Box 1019 W. Warwick, RI 02893 Toll Free: 1-800-424-9850 www.advintcorp.com	X	X	-	X	-	-
AMP Inc. 470 Friendship Road Harrisburg, PA 17105-3608 (800) 522-6752 www.amp.com	X	X	-	X	-	-
Aries Electronics P.O. Box 130 Frenchtown, NJ 08825 Phone: 908-996-6841 www.arieselec.com	X	X	-	X	-	X
Interconnect Systems, Inc. 708 Via Alondra Camarillo, CA 93012 Phone: 805-482-2870						X
Ironwood Electronics Inc. P.O. Box 21151 St. Paul, MN 55121 Phone: 651-452-8100 www.ironwoodelectronics.com	X	-	-	X	-	X

Table A-1: Socket Manufacturers Packages (Cont'd)

Manufacturer	Packages					
	DIP, SO, VO	PC, WC	PQ, HQ, TQ, VQ	PG, PP	CB	BG, CG
McKenzie Socket Division 910 Page Avenue Fremont, CA 94538 (510) 651-2700	X	X	-	X	-	-
Mill-Max MFG. Corporation 190 Pine Hollow Road P.O. Box 300 Oyster Bay, NY 11771 Phone: 516-922-6000 www.mill-max.com	X	X	-	X	-	X
3M Textool 6801 River Place Blvd. Austin, TX 78726-9000 (800) 328-0411 www.3m.com				X	X	X
Wells Electronics 1701 South Main Street South Bend, IN 46613-2299 (219) 287-5941 www.wellscti.com				X		
Yamaichi Electronics Inc. 2235 Zanker Road San Jose, CA 95131 (408) 456-0797 www.yeu.com		X	X	X	X	

Web Sites for Heatsink Sources

Below is the list manufacturers' web pages offering heatsink solutions for Xilinx Package types. This summary does not imply an endorsement by Xilinx. Each user has the responsibility to evaluate and approve a particular heatsink solution provider.

Wakefield Thermal Solutions, Inc., <http://www.wakefield.com>

Aavid Thermalloy, LLC, <http://www.aavidthermalloy.com>

Malico, Inc., <http://www.malico.com.tw>

GlobalWin, <http://www.globalwin.com.tw>

Asia Vital Components Co., Ltd., <http://www.avc.com.tw>

Alpha Company Ltd., <http://www.micforg.co.jp>

Cofan USA, Inc., <http://www.cofan-usa.com>

Web Sites for Interface Material Sources

Xilinx does not endorse these vendors nor their products. They are listed here for reference only. Any materials or services received from the vendors should be evaluated for compatibility with Xilinx components.

Loctite, <http://www.powerdevices.com>

Chomerics, <http://www.chomerics.com>

Bergquist Company, <http://www.bergquistcompany.com>

AOS Thermal Compound, <http://www.aosco.com>

Related Xilinx Web Sites and Links to Xilinx Packaging Application Notes

Package drawings and Material Declaration Data Sheets:

http://www.xilinx.com/support/documentation/package_specifications.htm

Xilinx Pb-free/RoHS Solutions:

http://www.xilinx.com/system_resources/lead_free/

[UG072](#), *Virtex-4 FPGA PCB Designer's Guide*

[UG075](#), *Virtex-4 FPGA Packaging and Pinout Specification*

[XAPP427](#), *Implementation and Solder Reflow Guidelines for Pb-Free Packages*

